# MC9S12DT128 Device User Guide V02.11

# Covers also

MC9S12DT128E, MC9S12DG128E, MC9S12DJ128E, MC9S12DG128, MC9S12DJ128, MC9S12DB128, MC9S12A128, SC515846, SC515847, SC515848, SC515849

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# **Revision History**

Version Number	Revision Date	Effective Date	Author	Description of Changes
V01.00	18 Jun 2001	18 June 2001		Initial version (parent doc v2.03 dug for dp256).
V01.01	23 July 2001	23 July 2001		Updated version after review
V01.02	23 Sep 2001	23 Sep 2001		Changed Partname, added pierce mode, updated electrical characteristics some minor corrections
V01.03	12 Oct 2001	12 Oct 2001		Replaced Star12 by HCS12
V01.04	27 Feb 2002	27 Feb 2002		Updated electrical spec after MC-Qualification (IOL/IOH), Data for Pierce, NVM reliability New document numbering. Corrected Typos
V01.05	4 Mar 2002	4 Mar 2002		Increased VDD to 2.35V, removed min. oscillator startup Removed Document order number except from Cover Sheet
V01.06	8 July 2002	22 July 2002		Added: Pull-up columns to signal table, example for PLL Filter calculation, Thermal values for junction to board and package, BGND pin pull-up Part Order Information Global Register Table Chip Configuration Summary Modified: Reduced Wait and Run IDD values Mode of Operation chapter changed leakage current for ADC inputs down to +-1uA Corrected: Interrupt vector table enable register inconsistencies PCB layout for 80QFP VREGEN position
V02.00	11 Jan 2002	11 Jan 2002		NEW MASKSET Changed part number from DTB128 to DT128 Functional Changes: ROMCTL changes in Emulation Mode 80 Pin Byteflight package Option available Flash with 2 Bit Backdoor Key Enable Additional CAN0 routing to PJ7,6 Improved BDM with sync and acknowledge capabilities New Part ID number Improvements: Significantly improved NVM reliability data Corrections: Interrupt vector Table
V02.01	01 Feb 2002	01 Feb 2002		Updated Block User Guide versions in preface Updated Appendix A Electrical Characteristics

Version Number	Revision Date	Effective Date	Author	Description of Changes
V02.02	08 Mar 2002	08 Mar 2002		Changed XCLKS to PE7 in Table 2-2 Updated device part numbers in Figure 2-1 Updated BDM clock in Figure 3-1 Removed SIM description in overview & n <sub>UPOSC</sub> spec in Table A-15 Updated electrical spec of VDD & VDDPLL (Table A-4), IOL/IOH (Table A-6), C <sub>INS</sub> (Table A-9), C <sub>IN</sub> (Table A-6 & A-15), Updated interrupt pulse timing variables in Table A-6 Updated device part numbers in Figure 2-1 Added document numbers on cover page and Table 0-2
V02.03	14 Mar 2002	14 Mar 2002		Cleaned up Fig. 1-1, 2-1 Updated Section 1.5 descriptions Corrected PE assignment in Table 2-2, Fig. 2-5,6,7. Corrected NVM sizes in Sections 16, 17 Added I <sub>REF</sub> spec for 1ATD in Table A-8 Added Blank Check in A.3.1.5 and Table A-11 Updated CRG spec in Table A-15
V02.04	16 Aug 2002	16 Aug 2002		Added: Pull-up columns to signal table, Example for PLL Filter calculation, Thermal values for junction to board and package, BGND pin pull-up Part Order Information Global Register Table Chip Configuration Summary Device specific info on CRG Modified: Reduced Wait and Run IDD values Mode of Operation chapter Changed leakage current for ADC inputs down to +-1uA Minor modification of PLL frequency/ voltage gain values Corrected: Pin names/functions on 80 pin packages Interrupt vector table enable register inconsistencies PCB layout for 80QFP VREGEN position
V02.05	12 Sep 2002	12 Sep 2002		Corrected: Register address mismatches in 1.5.1
V02.06	06 Nov 2002	06 Nov 2002		Removed document order no. from Revision History pages Renamed "Preface" section to "Derivative Differences and Document references". Added details for derivatives missing CAN0/1/4, BDLC, IIC and/or Byteflight Added 2L40K mask set in section 1.6 Added OSC User Guide in Preface, "Document References" Added oscillator clock connection to BDM in S12_CORE in fig 3-1 Corrected several register and bit names in "Local Enable" column of Table 5.1 Interrupt Vector Locations Section HCS12 Core Block Description: mentioned alternate clock of BDM to be equivalent to oscillator clock Added new section: "Oscillator (OSC) Block Description" Corrected in footnote of Table "PLL Characteristics": fOSC = 4MHz

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Version Number	Revision Date	Effective Date	Author	Description of Changes
V02.07	29 Jan 2003	29 Jan 2003		Added 3L40K mask set in section 1.6 Corrected register entries in section 1.5.1 "Detailed Memory Map" Updated description for ROMCTL in section 2.3.31 Updated section 4.3.3 "Unsecuring the Microcontroller" Corrected and updated device-specific information for OSC (section 8.1) & Byteflight (section 15.1) Updated footnote in Table A-4 "Operating Conditions" Changed reference of VDDM to VDDR in section A.1.8 Removed footnote on input leakage current in Table A-6 "5V I/O Characteristics"
V02.08	26 Feb 2003	26 Feb 2003		Added part numbers MC9S12DT128E, MC9S12DG128E, and MC9S12DJ128E in "Preface" and related part number references Removed mask sets 0L40K and 2L40K from Table 1-3
V02.09	15 Oct 2003	15 Oct 2003		Replaced references to HCS12 Core Guide by the individual HCS12 Block guides in Table 0-2, section 1.5.1, and section 6; updated Fig.3-1 "Clock Connections" to show the individual HCS12 blocks  Corrected PIM module name and document order number in Table 0-2 "Document References"  Corrected ECT pulse accumulators description in section 1.2 "Features"  Corrected KWP5 pin name in Fig 2-1 112LQFP pin assignments Corrected pull resistor CTRL/reset states for PE7 and PE4-PE0 in Table 2.1 "Signal Properties"  Mentioned "S12LRAE" bootloader in Flash section 17 Corrected footnote on clamp of TEST pin under Table A-1 "Absolute Maximum Ratings"  Corrected minimum bus frequency to 0.25MHz in Table A-4 "Operating Conditions"  Replaced "burst programming" by "row programming" in A.3 "NVM, Flash and EEPROM"  Corrected blank check time for EEPROM in Table A-11 "NVM Timing Characteristics"  Corrected operating frequency in Table A-18 "SPI Master/Slave Mode Timing Characteristics
V02.10	6 Feb 2004	6 Feb 2004		Added A128 information in "Derivative Differences", 2.1 "Device Pinout", 2.2 "Signal Properties Summary", Fig 23-2 & Fig 23-4 Added lead-free package option (PVE) in Table 0-2 "Derivative Differences for MC9S12DB128" and Fig 0-1 "Order Partnumber Example"  Added an "AEC qualified" row in the "Derivative Differences" tables 0-1 & 0-2.
V02.11	3 May 2004	3 May 2004		Added part numbers SC515846, SC515847, SC515848, and SC515849 in "Derivative Differences" tables 0-1 & 0-2, section 2, and section 23.  Corrected and added maskset 4L40K in tables 0-1 & 0-2 and section 1.6.  Corrected BDLC module availability in DB128 80QFP part in "Derivative Differences" table 0-2.



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# **Derivative Differences and Document References**

## **Derivative Differences**

**Table 0-1** and **Table 0-2** show the availability of peripheral modules on the various derivatives. For details about the compatibility within the MC9S12D-Family refer also to engineering bulletin EB386.

Table 0-1 Derivative Differences<sup>1</sup>

Modules	MC9S12DT128E <sup>3</sup> MC9S12DT128 SC515849 <sup>4</sup>	MC9S12DG128E <sup>3</sup> MC9S12DG128 SC515847 <sup>4</sup>	MC9S12DJ128E <sup>3</sup> MC9S12DJ128 SC515848 <sup>4</sup>	MC9S12A128	
# of CANs	3	2	2	0	
CAN4	✓	✓	✓	X	
CAN1	✓	X	X	X	
CAN0	✓	✓	✓	X	
J1850/BDLC	×	X	✓	X	
IIC	✓	✓	✓	X	
Byteflight	X	X	X	X	
Package	112 LQFP	112 LQFP/80 QFP <sup>2</sup>	112 LQFP/80 QFP <sup>2</sup>	112 LQFP/80 QFP <sup>2</sup>	
Package Code	PV	PV/FU	PV/FU	PV/FU	
Mask set	1L40K <sup>3</sup> , 3L40K, 4L40K <sup>4</sup>	1L40K <sup>3</sup> , 3L40K, 4L40K <sup>4</sup>	1L40K <sup>3</sup> , 3L40K, 4L40K <sup>4</sup>	3L40K	
Temp Options	M, V, C	M, V, C	M, V, C	С	
AEC qualified	Yes	Yes	Yes	No	
Notes An errata exists contact Sales Office		An errata exists contact Sales Office	An errata exists contact Sales Office	An errata exists contact Sales Office	

Table 0-2 Derivative Differences for MC9S12DB128<sup>1</sup>

Modules	MC9S12DB128 SC515846 <sup>4</sup>	MC9S12DB128 SC515846 <sup>4</sup>
# of CANs	2	0
CAN4	✓	X
CAN1	X	X
CAN0	✓	X
J1850/BDLC	X	X
IIC	X	X
Byteflight	✓	✓
Package	112 LQFP	80 QFP <sup>2</sup>
Package Code	PV/PVE	FU
Mask set	3L40K, 4L40K <sup>4</sup>	3L40K, 4L40K <sup>4</sup>
Temp Options	M, V, C/M, V	M, V, C
AEC qualified	Yes	Yes

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Modules	MC9S12DB128 SC515846 <sup>4</sup>	MC9S12DB128 SC515846 <sup>4</sup>		
Notes	An errata exists contact Sales Office	An errata exists contact Sales Office		

#### NOTE:

- 1. ✓: Available for this device, X: Not available for this device.
- 80 Pin bond-out for MC9S12DG128E, MC9S12DG128, MC9S12DJ128E, MC9S12DJ128, MC9S12A128, SC515847, and SC515848 is the same; MC9S12DB128 and SC515846 have a different bond-out.
- 3. Part numbers MC9S12DT128E, MC9S12DG128E, and MC9S12DJ128E are associated with the mask set 1L40K.
- 4. Part numbers SC515846, SC515847, SC515848, and SC515849 are associated with the mask set 4L40K.

The following figure provides an ordering number example for the MC9S12D128 devices.



Figure 0-1 Order Partnumber Example

The following items should be considered when using a derivative.

## Registers

- Do not write or read CAN0 registers (after reset: address range \$0140 \$017F), if using a derivative without CAN0 (see **Table 0-1** and **Table 0-2**).
- Do not write or read CAN1 registers (after reset: address range \$0180 \$01BF), if using a derivative without CAN1 (see **Table 0-1** and **Table 0-2**).
- Do not write or read CAN4 registers (after reset: address range \$0280 \$02BF), if using a derivative without CAN4 (see **Table 0-1** and **Table 0-2**).
- Do not write or read BDLC registers (after reset: address range \$00E8 \$00EF), if using a derivative without BDLC (see **Table 0-1** and **Table 0-2**).
- Do not write or read IIC registers (after reset: address range \$00E0 \$00E7), if using a derivative without IIC (see **Table 0-1** and **Table 0-2**).
- Do not write or read Byteflight registers (after reset: address range \$0300 \$035F), if using a derivative without Byteflight registers (see **Table 0-1** and **Table 0-2**).

#### • Interrupts

- Fill the four CAN0 interrupt vectors (\$FFB0 \$FFB7) according to your coding policies for unused interrupts, if using a derivative without CAN0 (see **Table 0-1** and **Table 0-2**).
- Fill the four CAN1 interrupt vectors (\$FFA8 \$FFAF) according to your coding policies for unused interrupts, if using a derivative without CAN1 (see **Table 0-1** and **Table 0-2**).

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- Fill the four CAN4 interrupt vectors (\$FF90 \$FF97) according to your coding policies for unused interrupts, if using a derivative without CAN4 (see **Table 0-1** and **Table 0-2**).
- Fill the BDLC interrupt vector (\$FFC2, \$FFC3) according to your coding policies for unused interrupts, if using a derivative without BDLC (see **Table 0-1** and **Table 0-2**).
- Fill the IIC interrupt vector (\$FFC0, \$FFC1) according to your coding policies for unused interrupts, if using a derivative without IIC (see **Table 0-1** and **Table 0-2**).
- Fill the four Byteflight interrupt vectors (\$FFA0 \$FFA7) according to your coding policies for unused interrupts, if using a derivative without Byteflight (see **Table 0-1** and **Table 0-2**).

#### Ports

- The CAN0 pin functionality (TXCAN0, RXCAN0) is not available on port PJ7, PJ6, PM5, PM4, PM3, PM2, PM1 and PM0, if using a derivative without CAN0 (see **Table 0-1** and **Table 0-2**).
- The CAN1 pin functionality (TXCAN1, RXCAN1) is not available on port PM3 and PM2, if using a derivative without CAN1 (see **Table 0-1** and **Table 0-2**).
- The CAN4 pin functionality (TXCAN4, RXCAN4) is not available on port PJ7, PJ6, PM7, PM6, PM5 and PM4, if using a derivative without CAN4 (see **Table 0-1** and **Table 0-2**).
- The BDLC pin functionality (TXB, RXB) is not available on port PM1 and PM0, if using a derivative without BDLC (see **Table 0-1** and **Table 0-2**).
- The IIC pin functionality (SCL, SCA) is not available on port PJ7 and PJ6, if using a derivative without IIC (see **Table 0-1** and **Table 0-2**).
- The Byteflight pin functionality (BF\_PSLM, BF\_PERR, BF\_PROK, BF\_PSYN, TX\_BF, RX\_BF) is not available on port PM7, PM6, PM5, PM4, PM3 and PM2, if using a derivative without Byteflight (see **Table 0-1** and **Table 0-2**).
- Do not write MODRR1 and MODRR0 Bit of Module Routing Register (PIM\_9DTB128 Block User Guide), if using a derivative without CAN0 (see **Table 0-1** and **Table 0-2**).
- Do not write MODRR3 and MODRR2 Bit of Module Routing Register (PIM\_9DTB128 Block User Guide), if using a derivative without CAN4 (see **Table 0-1** and **Table 0-2**).
- Pins not available in 80 pin QFP package for MC9S12DG128E, MC9S12DG128, MC9S12DJ128E, MC9S12DJ128, MC9S12A128, SC515847, and SC515848

## Port H

In order to avoid floating nodes the ports should be either configured as outputs by setting the data direction register (DDRH at Base+\$0262) to \$FF, or enabling the pull resistors by writing a \$FF to the pull enable register (PERH at Base+\$0264).

## Port J[1:0]

Port J pull-up resistors are enabled out of reset on all four pins (7:6 and 1:0). Therefore care must be taken not to disable the pull enables on PJ[1:0] by clearing the bits PERJ1 and PERJ0 at Base+\$026C.



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#### Port K

Port K pull-up resistors are enabled out of reset, i.e. Bit 7 = PUKE = 1 in the register PUCR at Base+\$000C. Therefore care must be taken not to clear this bit.

#### Port M[7:6]

PM7:6 must be configured as outputs or their pull resistors must be enabled to avoid floating inputs.

#### - Port P6

PP6 must be configured as output or its pull resistor must be enabled to avoid a floating input.

## – Port S[7:4]

PS7:4 must be configured as outputs or their pull resistors must be enabled to avoid floating inputs.

# PAD[15:8] (ATD1 channels)

Out of reset the ATD1 is disabled preventing current flows in the pins. Do not modify the ATD1 registers!

## Pins not available in 80 pin QFP package for MC9S12DB128 and SC515846

#### Port H

In order to avoid floating nodes the ports should be either configured as outputs by setting the data direction register (DDRH at Base+\$0262) to \$FF, or enabling the pull resistors by writing a \$FF to the pull enable register (PERH at Base+\$0264).

## - Port J[7:6, 1:0]

Port J pull-up resistors are enabled out of reset on all four pins (7:6 and 1:0). Therefore care must be taken not to disable the pull enables on PJ[7:6, 1:0] by clearing the bits PERJ7, PERJ6, PERJ1 and PERJ0 at Base+\$026C.

#### Port K

Port K pull-up resistors are enabled out of reset, i.e. Bit 7 = PUKE = 1 in the register PUCR at Base+\$000C. Therefore care must be taken not to clear this bit.

#### - **Port M[1:0]**

PM1:0 must be configured as outputs or their pull resistors must be enabled to avoid floating inputs.

#### Port P6

PP6 must be configured as output or its pull resistor must be enabled to avoid a floating input.

#### Port S[3:2]

PS3:2 must be configured as outputs or their pull resistors must be enabled to avoid floating inputs.

#### PAD[15:8] (ATD1 channels)

Out of reset the ATD1 is disabled preventing current flows in the pins. Do not modify the ATD1 registers!

## **Document References**

# Freescale Semiconductor, Inc. MC9S12DT128 Device User Guide — V02.11

The Device User Guide provides information about the MC9S12DT128 device made up of standard HCS12 blocks and the HCS12 processor core.

This document is part of the customer documentation. A complete set of device manuals also includes all the individual Block User Guides of the implemented modules. In a effort to reduce redundancy all module specific information is located only in the respective Block User Guide. If applicable, special implementation details of the module are given in the block description sections of this document.

See **Table 0-3** for names and versions of the referenced documents throughout the Device User Guide.

**Table 0-3 Document References** 

User Guide Version Document Order Number								
HCS12 CPU Reference Manual	V02	S12CPUV2/D						
HCS12 Module Mapping Control (MMC) Block Guide	V04	S12MMCV4/D						
HCS12 Multiplexed External Bus Interface (MEBI) Block Guide	V03	S12MEBIV3/D						
HCS12 Interrupt (INT) Block Guide	V01	S12INTV1/D						
HCS12 Background Debug Module (BDM) Block Guide	V04	S12BDMV4/D						
HCS12 Breakpoint (BKP) Block Guide	V01	S12BKPV1/D						
Clock and Reset Generator (CRG) Block User Guide	V04	S12CRGV4/D						
Oscillator (OSC) Block User Guide	V02	S12OSCV2/D						
Enhanced Capture Timer 16 Bit 8 Channel (ECT_16B8C) Block User Guide	V01	S12ECT16B8CV1/D						
Analog to Digital Converter 10 Bit 8 Channel (ATD_10B8C) Block User Guide	V02	S12ATD10B8CV2/D						
Inter IC Bus (IIC) Block User Guide	V02	S12IICV2/D						
Asynchronous Serial Interface (SCI) Block User Guide	V02	S12SCIV2/D						
Serial Peripheral Interface (SPI) Block User Guide	V02	S12SPIV2/D						
Pulse Width Modulator 8 Bit 8 Channel (PWM_8B8C) Block User Guide	V01	S12PWM8B8CV1/D						
128K Byte Flash (FTS128K) Block User Guide	V02	S12FTS128KV2/D						
2K Byte EEPROM (EETS2K) Block User Guide	V01	S12EETS2KV1/D						
Byte Level Data Link Controller -J1850 (BDLC) Block User Guide	V01	S12BDLCV1/D						
Motorola Scalable CAN (MSCAN) Block User Guide	V02	S12MSCANV2/D						
Voltage Regulator (VREG) Block User Guide	V01	S12VREGV1/D						
Port Integration Module (PIM_9DTB128) Block User Guide	V02	S12DTB128PIMV2/D						
Byteflight (BF) Block User Guide	V01	S12BFV1/D						

# **Section 1 Introduction**

# 1.1 Overview

The MC9S12DT128 microcontroller unit (MCU) is a 16-bit device composed of standard on-chip peripherals including a 16-bit central processing unit (HCS12 CPU), 128K bytes of Flash EEPROM, 8K bytes of RAM, 2K bytes of EEPROM, two asynchronous serial communications interfaces (SCI), two serial peripheral interfaces (SPI), an 8-channel IC/OC enhanced capture timer, two 8-channel, 10-bit analog-to-digital converters (ADC), an 8-channel pulse-width modulator (PWM), a digital Byte Data Link Controller (BDLC), 29 discrete digital I/O channels (Port A, Port B, Port K and Port E), 20 discrete digital I/O lines with interrupt and wakeup capability, three CAN 2.0 A, B software compatible modules (MSCAN12), a Byteflight module and an Inter-IC Bus. The MC9S12DT128 has full 16-bit data paths throughout. However, the external bus can operate in an 8-bit narrow mode so single 8-bit wide memory can be interfaced for lower cost systems. The inclusion of a PLL circuit allows power consumption and performance to be adjusted to suit operational requirements.

## 1.2 Features

- HCS12 Core
  - 16-bit HCS12 CPU
    - i. Upward compatible with M68HC11 instruction set
    - ii. Interrupt stacking and programmer's model identical to M68HC11
    - iii. 20-bit ALU
    - iv. Instruction queue
    - v. Enhanced indexed addressing
  - MEBI (Multiplexed External Bus Interface)
  - MMC (Module Mapping Control)
  - INT (Interrupt control)
  - BKP (Breakpoints)
  - BDM (Background Debug Module)
- CRG (Clock and Reset Generator)
  - Choice of low current Colpitts oscillator or standard Pierce Oscillator
  - PLL
  - COP watchdog
  - real time interrupt
  - clock monitor
- 8-bit and 4-bit ports with interrupt functionality

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- Digital filtering
- Programmable rising or falling edge trigger
- Memory
  - 128K Flash EEPROM
  - 2K byte EEPROM
  - 8K byte RAM
- Two 8-channel Analog-to-Digital Converters
  - 10-bit resolution
  - External conversion trigger capability
- Three 1M bit per second, CAN 2.0 A, B software compatible modules
  - Five receive and three transmit buffers
  - Flexible identifier filter programmable as 2 x 32 bit, 4 x 16 bit or 8 x 8 bit
  - Four separate interrupt channels for Rx, Tx, error and wake-up
  - Low-pass filter wake-up function
  - Loop-back for self test operation
- Enhanced Capture Timer
  - 16-bit main counter with 7-bit prescaler
  - 8 programmable input capture or output compare channels
  - Four 8-bit or two 16-bit pulse accumulators
- 8 PWM channels
  - Programmable period and duty cycle
  - 8-bit 8-channel or 16-bit 4-channel
  - Separate control for each pulse width and duty cycle
  - Center-aligned or left-aligned outputs
  - Programmable clock select logic with a wide range of frequencies
  - Fast emergency shutdown input
  - Usable as interrupt inputs
- Serial interfaces
  - Two asynchronous Serial Communications Interfaces (SCI)
  - Two Synchronous Serial Peripheral Interface (SPI)
  - Byteflight
- Byte Data Link Controller (BDLC)

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- SAE J1850 Class B Data Communications Network Interface
  - Compatible and ISO Compatible for Low-Speed (<125 Kbps) Serial Data Communications in Automotive Applications
- Inter-IC Bus (IIC)
  - Compatible with I2C Bus standard
  - Multi-master operation
  - Software programmable for one of 256 different serial clock frequencies
- 112-Pin LQFP and 80-Pin QFP package options
  - I/O lines with 5V input and drive capability
  - 5V A/D converter inputs
  - Operation at 50MHz equivalent to 25MHz Bus Speed
  - Development support
  - Single-wire background debug<sup>TM</sup> mode
  - On-chip hardware breakpoints

# 1.3 Modes of Operation

#### User modes

- Normal and Emulation Operating Modes
  - Normal Single-Chip Mode
  - Normal Expanded Wide Mode
  - Normal Expanded Narrow Mode
  - Emulation Expanded Wide Mode
  - Emulation Expanded Narrow Mode
- Special Operating Modes
  - Special Single-Chip Mode with active Background Debug Mode
  - Special Test Mode (Motorola use only)
  - Special Peripheral Mode (Motorola use only)

## Low power modes

- Stop Mode
- Pseudo Stop Mode
- Wait Mode



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# 1.4 Block Diagram

**Figure 1-1** shows a block diagram of the MC9S12DT128 device.

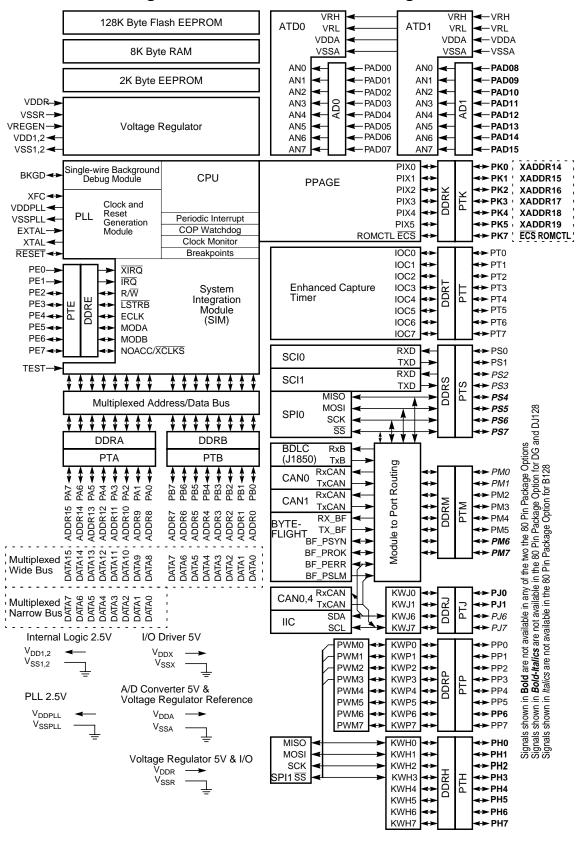


Figure 1-1 MC9S12DT128 Block Diagram

# 1.5 Device Memory Map

**Table 1-1** and **Figure 1-2** show the device memory map of the MC9S12DT128 after reset. Note that after reset the EEPROM (\$0000 – \$07FF) is hidden by the register space (\$0000 - \$03FF) and the RAM (\$0000 - \$1FFF). The bottom 1K Bytes of RAM (\$0000 - \$03FF) are hidden by the register space.

**Table 1-1 Device Memory Map** 

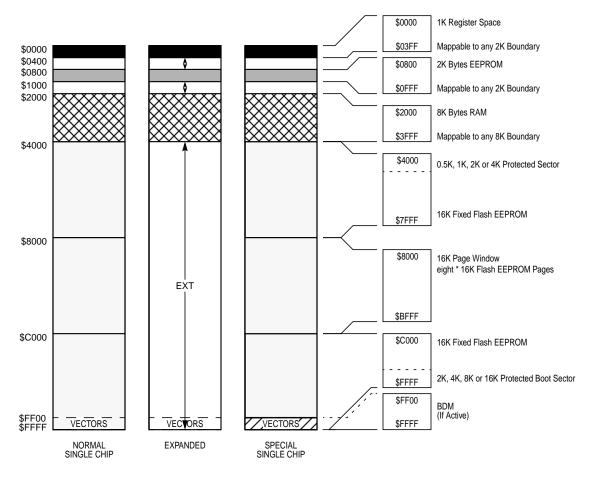
Address	ddress Module			
\$0000 - \$0017	CORE (Ports A, B, E, Modes, Inits, Test)	24		
\$0018 - \$0019	Reserved	2		
\$001A - \$001B	Device ID register (PARTID)	2		
\$001C - \$001F	CORE (MEMSIZ, IRQ, HPRIO)	4		
\$0020 - \$0027	Reserved	8		
\$0028 - \$002F	CORE (Background Debug Module)	8		
\$0030 - \$0033	CORE (PPAGE, Port K)	4		
\$0034 - \$003F	Clock and Reset Generator (PLL, RTI, COP)	12		
\$0040 - \$007F	Enhanced Capture Timer 16-bit 8 channels	64		
\$0080 - \$009F	Analog to Digital Converter 10-bit 8 channels (ATD0)	32		
\$00A0 - \$00C7	Pulse Width Modulator 8-bit 8 channels (PWM)	40		
\$00C8 - \$00CF	Serial Communications Interface (SCI0)	8		
\$00D0 - \$00D7	Serial Communications Interface (SCI1)	8		
\$00D8 - \$00DF	Serial Peripheral Interface (SPI0)	8		
\$00E0 - \$00E7	Inter IC Bus	8		
\$00E8 - \$00EF	Byte Level Data Link Controller (BDLC)	8		
\$00F0 - \$00F7	Serial Peripheral Interface (SPI1)	8		
\$00F8 - \$00FF	Reserved	8		
\$0100 - \$010F	Flash Control Register	16		
\$0110 - \$011B	EEPROM Control Register	12		
\$011C - \$011F	Reserved	4		
\$0120 - \$013F	Analog to Digital Converter 10-bit 8 channels (ATD1)	32		
\$0140 - \$017F	Motorola Scalable CAN (CAN0)	64		
\$0180 - \$01BF	Motorola Scalable CAN (CAN1)	64		
\$01C0 - \$01FF	Reserved	64		
\$0200 - \$023F	Reserved	64		
\$0240 - \$027F	Port Integration Module (PIM)	64		
\$0280 - \$02BF	Motorola Scalable CAN (CAN4)	64		
\$02C0 - \$02FF	Reserved	64		
\$0300 - \$035F	Byteflight (BF)	96		
\$0360 - \$03FF	Reserved	160		
\$0000 – \$07FF	EEPROM array	2048		
\$0000 – \$1FFF	RAM array	8192		
\$4000 – \$7FFF	Fixed Flash EEPROM array incl. 0.5K, 1K, 2K or 4K Protected Sector at start	16384		
\$8000 – \$BFFF	Flash EEPROM Page Window	16384		

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**Table 1-1 Device Memory Map** 

Address	Module	Size (Bytes)
\$C000 – \$FFFF	Fixed Flash EEPROM array incl. 0.5K, 1K, 2K or 4K Protected Sector at end and 256 bytes of Vector Space at \$FF80 – \$FFFF	16384

Figure 1-2 MC9S12DT128 Memory Map



The address does not show the map after reset, but a useful map. After reset the map is:

\$0000 – \$03FF: Register Space \$0000 – \$1FFF: 8K RAM \$0000 – \$07FF: 2K EEPROM (not visible)

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# 1.5.1 Detailed Register Map

# \$0000 - \$000F

# MEBI map 1 of 3 (HCS12 Multiplexed External Bus Interface)

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$0000	PORTA	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$0001	PORTB	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$0002	DDRA	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$0003	DDRB	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$0004	Reserved	Read: Write:	0	0	0	0	0	0	0	0
\$0005	Reserved	Read: Write:	0	0	0	0	0	0	0	0
\$0006	Reserved	Read: Write:	0	0	0	0	0	0	0	0
\$0007	Reserved	Read:	0	0	0	0	0	0	0	0
\$0008	PORTE	Write: Read: Write:	Bit 7	6	5	4	3	2	Bit 1	Bit 0
\$0009	DDRE	Read: Write:	Bit 7	6	5	4	3	Bit 2	0	0
\$000A	PEAR	Read: Write:	NOACCE	0	PIPOE	NECLK	LSTRE	RDWE	0	0
\$000B	MODE	Read: Write:	MODC	MODB	MODA	0	IVIS	0	EMK	EME
\$000C	PUCR	Read: Write:	PUPKE	0	0	PUPEE	0	0	PUPBE	PUPAE
\$000D	RDRIV	Read: Write:	RDPK	0	0	RDPE	0	0	RDPB	RDPA
\$000E	EBICTL	Read: Write:	0	0	0	0	0	0	0	ESTR
\$000F	Reserved	Read: Write:	0	0	0	0	0	0	0	0
•		vviite.								

# \$0010 - \$0014

# MMC map 1 of 4 (HCS12 Module Mapping Control)

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$0010	INITRM	Read:	RAM15	RAM14	RAM13	RAM12	RAM11	0	0	RAMHAL
φοστο	HALLIKIVI	Write:	10 (1011)	TO MVITT	10/10/10	147 (19112	T C C C C C C C C C C C C C C C C C C C			T C/ CIVII I/ C
\$0011	INITRG	Read:	0	REG14	REG13	REG12	REG11	0	0	0
φ0011	INTING	Write:		KEG14	REGIS	REGIZ	KEGII			
\$0012	INITEE	Read:	EE15	EE14	EE13	EE12	EE11	0	0	EEON
Φ0012	INITEE	Write:	EE13	CC14	EEIS		EETT			EEOIN
<b>\$0042</b>	MISC	Read:	0	0	0	0	EXSTR1	EXSTR0	ROMHM	DOMON
\$0013 MISC	MISC	Write:					EVOIKI	EXSIKU	KOMINI	ROMON
\$0014	Reserved	Read:	0	0	0	0	0	0	0	0
		Write:								

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#### \$0015 - \$0016

## INT map 1 of 2 (HCS12 Interrupt)

Address Name \$0015 **ITCR** 

\$0016 **ITEST** 

	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
Read:	0	0	0	WRINT	ADR3	ADR2	ADR1	ADR0
Write:				VVINII	ADNO	ADNZ	ADKI	ADKU
Read: Write:	INTE	INTC	INTA	INT8	INT6	INT4	INT2	INT0

## \$0017 - \$0017

# MMC map 2 of 4 (HCS12 Module Mapping Control)

Address Name MTST1 \$0017 Test Only

R W

	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
Read:	Bit 7	6	5	4	3	2	1	Bit 0
Nrite:								

Bit 4

0

Bit 3

0

Bit 2

0

Bit 1

0

## \$0018 - \$0019

#### Reserved

Address Name \$0018 -Reserved \$0019

Bit 7 Bit 6 Bit 5 0 Read: 0 0 Write:

## \$001A - \$001B

## **Device ID Register (Table 1-3)**

Address Name \$001A **PARTIDH** \$001B **PARTIDL** 

	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
Read:	ID15	ID14	ID13	ID12	ID11	ID10	ID9	ID8
Write:								
Read:	ID7	ID6	ID5	ID4	ID3	ID2	ID1	ID0
Write:								

## \$001C - \$001D

# MMC map 3 of 4 (HCS12 Module Mapping Control, Table 1-4)

Address Name \$001C MEMSIZ0 \$001D MEMSIZ1

	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
Read:	reg_sw0	0	eep_sw1	eep_sw0	0	ram_sw2	ram_sw1	ram_sw0
Write:								
Read:	rom_sw1	rom_sw0	0	0	0	0	pag_sw1	pag_sw0
Write:								

## \$001E - \$001E

# MEBI map 2 of 3 (HCS12 Multiplexed External Bus Interface)

Address Name \$001E **INTCR** 

Read: Write:

	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
:[	IDOE	IRQEN	0	0	0	0	0	0
:[	IRQE	IKQEN						

## \$001F - \$001F

# INT map 2 of 2 (HCS12 Interrupt)

Address Name \$001F **HPRIO** 

Read Write

	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
d:	PSEL7	DSELE	PSEL5	DCEI 4	DCEI 2	PSEL2	PSEL1	0
e:	FSELI	FSELO	FSELS	F SEL4	FSELS	FSELZ	FSELI	

Bit 0

0

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## \$0020 - \$0027

#### Reserved

Address	
\$0020 -	
\$0027	

Name Reserved

Read:	
Read: Write:	Į

	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
ad:	0	0	0	0	0	0	0	0
te:								

## \$0028 - \$002F

# **BKP (HCS12 Breakpoint)**

Address	Name
\$0028	ВКРСТ0
\$0029	BKPCT1
\$002A	BKP0X
\$002B	BKP0H
\$002C	BKP0L
\$002D	BKP1X
\$002E	BKP1H
\$002F	BKP1L

	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
Read:	BKEN	BKFULL	BKBDM	BKTAG	0	0	0	0
Write:	DVEN	DKFULL	DVDDINI	DNIAG				
Read:	BK0MBH	BK0MBL	BK1MBH	BK1MBL	BK0RWE	BK0RW	BK1RWE	BK1RW
Write:	DIVOIVIDITI	DIVOIVIDE	DIX HVIDI I	DIVINIDE	DIVOITABLE	DIVOITA	DIVITABLE	DIVITAV
Read:	0	0	BK0V5	BK0V4	BK0V3	BK0V2	BK0V1	BK0V0
Write:			DICOVO	DNOV4	DICOVO	DINOVZ	DIXOVI	DIGOVO
Read:	Bit 15	14	13	12	11	10	9	Bit 8
Write:	DIL 13	14	13	12	11	10	9	Dit 0
Read:	Bit 7	6	5	4	3	2	1 1	Bit 0
Write:	Dit 7			7	J		'	Dit 0
Read:	0	0	BK1V5	BK1V4	BK1V3	BK1V2	BK1V1	BK1V0
Write:			DICTVO	DICTOR	DICTVO	DICTVZ	DICTVI	DICTVO
Read:	Bit 15	14	13	12	11	10	9	Bit 8
Write:	Dit 10	17	10	12	''	10	J	DitO
Read:	Bit 7	6	5	4	3	2	1 1	Bit 0
Write:	Dit 1			т		_	'	Dit 0

## \$0030 - \$0031

# MMC map 4 of 4 (HCS12 Module Mapping Control)

Address	Name
\$0030	PPAGE

\$0031 Reserved

	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
Read:	0	0	PIX5	PIX4	PIX3	PIX2	PIX1	PIX0
Write:			LIVO	Γ1Λ <del>1</del>	LIVO	ΓΙΛΖ	ΓIXI	FIXU
Read:	0	0	0	0	0	0	0	0
Write:								

## \$0032 - \$0033

# MEBI map 3 of 3 (HCS12 Multiplexed External Bus Interface)

Address	ivame
\$0032	PORTK
\$0033	DDRK

Read:	
Write:	
Read:	
Write:	

	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
d: e:	Bit 7	6	5	4	3	2	1	Bit 0
d: e:	Bit 7	6	5	4	3	2	1	Bit 0

## \$0034 - \$003F

# **CRG (Clock and Reset Generator)**

Address Name Bit 7 Bit 6 Bit 5 Bit 4 Bit 3 Bit 2 Bit 1	Bit 0
	Dit 0
\$0034 SYNR Read: 0 0 SYN5 SYN4 SYN3 SYN2 SYN1	SYN0
Write: STNS STN4 STNS STN2 STN1	
\$0035 REFDV Read: 0 0 0 0 REFDV3 REFDV1	REFDV0
\$0035 REFDV Write: REFDV3 REFDV2 REFDV1	KELDAO
toogs CTFLG Read: 0 0 0 0 0 0 0	0
\$0036 TEST ONLY Write:	
\$0037 CRGFLG READ: RTIF PORF 0 LOCKIF LOCK TRACK SCMIF	SCM
\$0037 CRGFLG Write: RTIF PORF LOCKIF LOCKIF SCMIF	
\$0038 CRGINT READ: RTIE 0 0 LOCKIE 0 0 SCMIE	0
\$0038 CRGINT Write: RTIE LOCKIE SCMIE	
\$0039 CLKSEL Read: PLLSEL PSTP SYSWAI ROAWAI PLLWAI CWAI RTIWAI	CODMA
\$0039 CLKSEL   PLLSEL   PSTP   SYSWAI   ROAWAI   PLLWAI   CWAI   RTIWAI	COPWAI
Read: CMF BLION AUTO ACO 0 PRF PCF	SCME
\$003A PLLCTL   CME   PLLON   AUTO   ACQ   PRE   PCE	
Read: 0 PTDC PTDC PTDC PTD2 PTD2	RTR0
\$003B RTICTL Write: RTR6 RTR5 RTR4 RTR3 RTR2 RTR1	
Read: WOOD BODOL 0 0 OPO OPO	000
\$003C COPCTL Read: WCOP RSBCK CR2 CR1	CR0
FORBYP Read: 0 0 0 0 0 0	0
\$003D TEST ONLY Write:	
CTCTL Read: 0 0 0 0 0 0	0
\$003E TEST ONLY Write:	
Read: 0 0 0 0 0 0	0
\$003F ARMCOP Write: Bit 7 6 5 4 3 2 1	Bit 0

# \$0040 - \$007F

# **ECT (Enhanced Capture Timer 16 Bit 8 Channels)**

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$0040	TIOS	Read: Write:	IOS7	IOS6	IOS5	IOS4	IOS3	IOS2	IOS1	IOS0
\$0041	CFORC	Read:	0	0	0	0	0	0	0	0
φυυ <del>4</del> Ι		Write:	FOC7	FOC6	FOC5	FOC4	FOC3	FOC2	FOC1	FOC0
\$0042	OC7M	Read: Write:	ОС7М7	OC7M6	OC7M5	OC7M4	ОС7М3	OC7M2	OC7M1	ОС7М0
\$0043	OC7D	Read: Write:	OC7D7	OC7D6	OC7D5	OC7D4	OC7D3	OC7D2	OC7D1	OC7D0
\$0044	TCNT (hi)	Read:	Bit 15	14	13	12	11	10	9	Bit 8
φυυ <del>τι</del>		Write:								
\$0045	TCNT (lo)	Read:	Bit 7	6	5	4	3	2	1	Bit 0
ΨΟΟ-ΙΟ		Write:								
\$0046	TSCR1	Read:	TEN	TSWAI	TSFRZ TF	TFFCA	0	0	0	0
φουτο		Write:	1 = 1 4	1000	101112					
\$0047	TTOV	Read: Write:	TOV7	TOV6	TOV5	TOV4	TOV3	TOV2	TOV1	TOV0
\$0048	TCTL1	Read: Write:	OM7	OL7	OM6	OL6	OM5	OL5	OM4	OL4
\$0049	TCTL2	Read: Write:	ОМ3	OL3	OM2	OL2	OM1	OL1	ОМ0	OL0

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# \$0040 - \$007F

# **ECT (Enhanced Capture Timer 16 Bit 8 Channels)**

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$004A	TCTL3	Read: Write:	EDG7B	EDG7A	EDG6B	EDG6A	EDG5B	EDG5A	EDG4B	EDG4A
\$004B	TCTL4	Read: Write:	EDG3B	EDG3A	EDG2B	EDG2A	EDG1B	EDG1A	EDG0B	EDG0A
\$004C	TIE	Read: Write:	C7I	C6I	C5I	C4I	C3I	C2I	C1I	COI
\$004D	TSCR2	Read: Write:	TOI	0	0	0	TCRE	PR2	PR1	PR0
\$004E	TFLG1	Read: Write:	C7F	C6F	C5F	C4F	C3F	C2F	C1F	C0F
\$004F	TFLG2	Read: Write:	TOF	0	0	0	0	0	0	0
\$0050	TC0 (hi)	Read: Write:	Bit 15	14	13	12	11	10	9	Bit 8
\$0051	TC0 (lo)	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$0052	TC1 (hi)	Read: Write:	Bit 15	14	13	12	11	10	9	Bit 8
\$0053	TC1 (lo)	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$0054	TC2 (hi)	Read: Write:	Bit 15	14	13	12	11	10	9	Bit 8
\$0055	TC2 (lo)	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$0056	TC3 (hi)	Read: Write:	Bit 15	14	13	12	11	10	9	Bit 8
\$0057	TC3 (lo)	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$0058	TC4 (hi)	Read: Write:	Bit 15	14	13	12	11	10	9	Bit 8
\$0059	TC4 (lo)	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$005A	TC5 (hi)	Read: Write:	Bit 15	14	13	12	11	10	9	Bit 8
\$005B	TC5 (lo)	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$005C	TC6 (hi)	Read: Write:	Bit 15	14	13	12	11	10	9	Bit 8
\$005D	TC6 (lo)	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$005E	TC7 (hi)	Read: Write:	Bit 15	14	13	12	11	10	9	Bit 8
\$005F	TC7 (lo)	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$0060	PACTL	Read: Write:	0	PAEN	PAMOD	PEDGE	CLK1	CLK0	PAOVI	PAI
\$0061	PAFLG	Read: Write:	0	0	0	0	0	0	PAOVF	PAIF
\$0062	PACN3 (hi)	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0

(M) MOTOROLA

## \$0040 - \$007F

## **ECT (Enhanced Capture Timer 16 Bit 8 Channels)**

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$0063	PACN2 (lo)	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$0064	PACN1 (hi)	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$0065	PACN0 (lo)	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$0066	MCCTL	Read: Write:	MCZI	MODMC	RDMCL	0 ICLAT	0 FLMC	MCEN	MCPR1	MCPR0
\$0067	MCFLG	Read: Write:	MCZF	0	0	0	POLF3	POLF2	POLF1	POLF0
\$0068	ICPAR	Read: Write:	0	0	0	0	PA3EN	PA2EN	PA1EN	PA0EN
\$0069	DLYCT	Read: Write:	0	0	0	0	0	0	DLY1	DLY0
\$006A	ICOVW	Read: Write:	NOVW7	NOVW6	NOVW5	NOVW4	NOVW3	NOVW2	NOVW1	NOVW0
\$006B	ICSYS	Read: Write:	SH37	SH26	SH15	SH04	TFMOD	PACMX	BUFEN	LATQ
\$006C	Reserved	Read: Write:								
\$006D	TIMTST Test Only	Read: Write:	0	0	0	0	0	0	TCBYP	0
\$006E	Reserved	Read: Write:								
\$006F	Reserved	Read: Write:								
\$0070	PBCTL	Read: Write:	0	PBEN	0	0	0	0	PBOVI	0
\$0071	PBFLG	Read: Write:	0	0	0	0	0	0	PBOVF	0
\$0072	РАЗН	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$0073	PA2H	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$0074	PA1H	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$0075	PA0H	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$0076	MCCNT (hi)	Read: Write:	Bit 15	14	13	12	11	10	9	Bit 8
\$0077	MCCNT (lo)	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$0078	TC0H (hi)	Read: Write:	Bit 15	14	13	12	11	10	9	Bit 8
\$0079	TC0H (lo)	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$007A	TC1H (hi)	Read: Write:	Bit 15	14	13	12	11	10	9	Bit 8
\$007B	TC1H (lo)	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0

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#### \$0040 - \$007F

## **ECT (Enhanced Capture Timer 16 Bit 8 Channels)**

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$007C	TC2H (hi)	Read:	Bit 15	14	13	12	11	10	9	Bit 8
\$007C	TCZH (III)	Write:								
\$007D	TC2H (lo)	Read:	Bit 7	6	5	4	3	2	1	Bit 0
φυστυ	10211 (10)	Write:								
\$007E	TC3H (hi)	Read:	Bit 15	14	13	12	11	10	9	Bit 8
φ00 <i>1</i> ⊑	10311 (111)	Write:								
\$007F	TC3H (lo)	Read:	Bit 7	6	5	4	3	2	1	Bit 0
φυστη	10311 (10)	Write:								

### \$0080 - \$009F

### ATD0 (Analog to Digital Converter 10 Bit 8 Channel)

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$0080	ATD0CTL0	Read:	0	0	0	0	0	0	0	0
*		Write:								
\$0081	ATD0CTL1	Read:	0	0	0	0	0	0	0	0
		Write:								A 0.015
\$0082	ATD0CTL2	Read: Write:	ADPU	AFFC	AWAI	ETRIGLE	ETRIGP	ETRIG	ASCIE	ASCIF
\$0083	ATD0CTL3	Read: Write:	0	S8C	S4C	S2C	S1C	FIFO	FRZ1	FRZ0
\$0084	ATD0CTL4	Read: Write:	SRES8	SMP1	SMP0	PRS4	PRS3	PRS2	PRS1	PRS0
\$0085	ATD0CTL5	Read: Write:	DJM	DSGN	SCAN	MULT	0	CC	СВ	CA
\$0086	ATD0STAT0	Read: Write:	SCF	0	ETORF	FIFOR	0	CC2	CC1	CC0
<b>#</b> 0007	D	Read:	0	0	0	0	0	0	0	0
\$0087	Reserved	Write:								
\$0088	ATD0TEST0	Read:	0	0	0	0	0	0	0	0
φυυοο	AIDUIESIU	Write:								
\$0089	ATD0TEST1	Read:	0	0	0	0	0	0	0	sc
ψυσου	AIDOILOIT	Write:								
\$008A	Reserved	Read:	0	0	0	0	0	0	0	0
φοσολί	reserved	Write:								
\$008B	ATD0STAT1	Read:	CCF7	CCF6	CCF5	CCF4	CCF3	CCF2	CCF1	CCF0
*****		Write:	_	_	-	_	_	_	_	-
\$008C	Reserved	Read:	0	0	0	0	0	0	0	0
		Write:								
\$008D	ATD0DIEN	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$008E	Reserved	Read:	0	0	0	0	0	0	0	0
Ψ000L	reserved	Write:								
\$008F	PORTAD0	Read:	Bit7	6	5	4	3	2	1	BIT 0
φοσοι	. 01(1/100	Write:								
\$0090	ATD0DR0H	Read:	Bit15	14	13	12	11	10	9	Bit8
,		Write:		Di: c						
\$0091	ATD0DR0L	Read:	Bit7	Bit6	0	0	0	0	0	0
•		Write:								

## \$0080 - \$009F

## ATD0 (Analog to Digital Converter 10 Bit 8 Channel)

		_								
Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$0092	ATD0DR1H	Read:	Bit15	14	13	12	11	10	9	Bit8
φ0092	AIDODKIII	Write:								
\$0093	ATD0DR1L	Read:	Bit7	Bit6	0	0	0	0	0	0
φ0093	AIDODKIL	Write:								
\$0094	ATD0DR2H	Read:	Bit15	14	13	12	11	10	9	Bit8
ψ0034	AIDODINZII	Write:								
\$0095	ATD0DR2L	Read:	Bit7	Bit6	0	0	0	0	0	0
φυυσο	AIDODINZL	Write:								
\$0096	ATD0DR3H	Read:	Bit15	14	13	12	11	10	9	Bit8
φυυθυ	ALDODRSH	Write:								
\$0097	ATD0DR3L	Read:	Bit7	Bit6	0	0	0	0	0	0
φυυσι	AIDUDRSL	Write:								
\$0098	ATD0DR4H	Read:	Bit15	14	13	12	11	10	9	Bit8
φυυσυ	AI DODIN4I I	Write:								
\$0099	ATD0DR4L	Read:	Bit7	Bit6	0	0	0	0	0	0
φυυσσ	AIDODIN4L	Write:								
\$009A	ATD0DR5H	Read:	Bit15	14	13	12	11	10	9	Bit8
ψυυσΑ	AIDODINSII	Write:								
\$009B	ATD0DR5L	Read:	Bit7	Bit6	0	0	0	0	0	0
φυυσυ	AIDODIGE	Write:								
\$009C	ATD0DR6H	Read:	Bit15	14	13	12	11	10	9	Bit8
φυυσο	AIDODROII	Write:								
\$009D	ATD0DR6L	Read:	Bit7	Bit6	0	0	0	0	0	0
φυυθυ	AIDODROL	Write:								
\$009E	ATD0DR7H	Read:	Bit15	14	13	12	11	10	9	Bit8
ΨΟΟΘΕ	VI DODK/ LI	Write:								
\$009F	ATD0DR7L	Read:	Bit7	Bit6	0	0	0	0	0	0
φυυθΓ	AIDUDKIL	Write:								

## \$00A0 - \$00C7

## **PWM (Pulse Width Modulator 8 Bit 8 Channel)**

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$00A0	PWME	Read: Write:	PWME7	PWME6	PWME5	PWME4	PWME3	PWME2	PWME1	PWME0
\$00A1	PWMPOL	Read: Write:	PPOL7	PPOL6	PPOL5	PPOL4	PPOL3	PPOL2	PPOL1	PPOL0
\$00A2	PWMCLK	Read: Write:	PCLK7	PCLK6	PCLK5	PCLK4	PCLK3	PCLK2	PCLK1	PCLK0
\$00A3	PWMPRCLK	Read: Write:	0	PCKB2	PCKB1	PCKB0	0	PCKA2	PCKA1	PCKA0
\$00A4	PWMCAE	Read: Write:	CAE7	CAE6	CAE5	CAE4	CAE3	CAE2	CAE1	CAE0
\$00A5	PWMCTL	Read: Write:	CON67	CON45	CON23	CON01	PSWAI	PFRZ	0	0
ФОО A С	<b>PWMTST</b>	Read:	0	0	0	0	0	0	0	0
\$00A6	Test Only	Write:								
<b>#</b> 00 4 <b>7</b>	PWMPRSC	Read:	0	0	0	0	0	0	0	0
\$00A7	Test Only	Write:								
\$00A8	PWMSCLA	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0

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## \$00A0 - \$00C7

## **PWM (Pulse Width Modulator 8 Bit 8 Channel)**

Address	Name	[	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$00A9	PWMSCLB	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$00AA	PWMSCNTA Test Only	Read: Write:	0	0	0	0	0	0	0	0
\$00AB	PWMSCNTB	Read:	0	0	0	0	0	0	0	0
•	Test Only	Write:	Dit 7	6	-	4	2	2	1	Dit 0
\$00AC	PWMCNT0	Read: Write:	Bit 7 0	6 0	5 0	0	3 0	0	0	Bit 0
		Read:	Bit 7	6	5	4	3	2	1	Bit 0
\$00AD	PWMCNT1	Write:	0	0	0	0	0	0	0	0
<b>#</b> 00 4 <b>F</b>	DWMACNITO	Read:	Bit 7	6	5	4	3	2	1	Bit 0
\$00AE	PWMCNT2	Write:	0	0	0	0	0	0	0	0
\$00AF	PWMCNT3	Read:	Bit 7	6	5	4	3	2	1	Bit 0
φυυΑΓ	FWWCN13	Write:	0	0	0	0	0	0	0	0
\$00B0	PWMCNT4	Read:	Bit 7	6	5	4	3	2	1	Bit 0
ψυσου	1 WIVICINT4	Write:	0	0	0	0	0	0	0	0
\$00B1	PWMCNT5	Read:	Bit 7	6	5	4	3	2	1	Bit 0
ΨΟΟΒΙ	1 WWONTS	Write:	0	0	0	0	0	0	0	0
\$00B2	PWMCNT6	Read:	Bit 7	6	5	4	3	2	1	Bit 0
ΨΟΟΒΕ		Write:	0	0	0	0	0	0	0	0
\$00B3	PWMCNT7	Read:	Bit 7	6	5	4	3	2	1	Bit 0
****		Write:	0	0	0	0	0	0	0	0
\$00B4	PWMPER0	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$00B5	PWMPER1	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$00B6	PWMPER2	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$00B7	PWMPER3	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$00B8	PWMPER4	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$00B9	PWMPER5	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$00BA	PWMPER6	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$00BB	PWMPER7	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$00BC	PWMDTY0	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$00BD	PWMDTY1	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$00BE	PWMDTY2	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$00BF	PWMDTY3	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$00C0	PWMDTY4	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$00C1	PWMDTY5	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0

## \$00A0 - \$00C7

### **PWM (Pulse Width Modulator 8 Bit 8 Channel)**

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$00C2	PWMDTY6	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$00C3	PWMDTY7	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
¢00C4	PWMSDN	Read:	PWMIF	PWMIE	DWMDCTDT	PWMLVL	0	PWM7IN	PWM7INL	PWM7ENA
\$00C4	PWWSDN	Write:	PVVIVIIF	PVVIVIIE	PWMRSTRT	PVVIVILVL			PVVIVI/IINL	PVVIVI/EINA
<b>\$000</b>	Decembed	Read:	0	0	0	0	0	0	0	0
\$00C5	Reserved	Write:								
\$00C6	Reserved	Read:	0	0	0	0	0	0	0	0
φυυσο	Reserved	Write:								
\$00C7	Reserved	Read:	0	0	0	0	0	0	0	0
φυυυ	Keserveu	Write:								

#### \$00C8 - \$00CF

## **SCI0 (Asynchronous Serial Interface)**

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
<b>የ</b> ሰሰ <b>ር</b> የ	SCI0BDH	Read:	0	0	0	SBR12	SBR11	SBR10	SBR9	CDDo
\$00C8	ЗСІОВИП	Write:				SDR1Z	SDKII	SDKIU	SDK9	SBR8
<b>#</b> 00 <b>C</b> 0	CCIODDI	Read:	CDDZ	CDDC	CDDC	CDD4	CDDG	CDDO	CDD4	CDDA
\$00C9	SCI0BDL	Write:	SBR7	SBR6	SBR5	SBR4	SBR3	SBR2	SBR1	SBR0
<b>#</b> 00 <b>0 #</b>	0010004	Read:	1.0000	001014/41	D0D0		14/41/5	-	-	БТ
\$00CA	SCI0CR1	Write:	LOOPS	SCISWAI	RSRC	М	WAKE	ILT	PE	PT
	0010000	Read:							511111	2511
\$00CB	SCI0CR2	Write:	TIE	TCIE	RIE	ILIE	TE	RE	RWU	SBK
		Read:	TDRE	тс	RDRF	IDLE	OR	NF	FE	PF
\$00CC	SCI0SR1	Write:								
		Read:	0	0	0	0	0			RAF
\$00CD	SCI0SR2	Write:			-			BRK13	TXDIR	
		Read:	R8		0	0	0	0	0	0
\$00CE	SCI0DRH	Write:	110	T8		J		J	0	
			D=	- Do		D.1		D.0	D.4	
\$00CF	SCI0DRL	Read:	R7	R6	R5	R4	R3	R2	R1	R0
ψυσοι	GOIODINE	Write:	T7	T6	T5	T4	T3	T2	T1	T0

## \$00D0 - \$00D7

## **SCI1 (Asynchronous Serial Interface)**

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$00D0	SCI1BDH	Read:	0	0	0	SBR12	SBR11	SBR10	SBR9	SBR8
ФООРО	SCHBBH	Write:				ODICIZ	וואל	SDICTO	SDINS	SDINO
\$00D1	SCI1BDL	Read:	SBR7	SBR6	SBR5	SBR4	SBR3	SBR2	SBR1	SBR0
ΨΟΟΕΙ	OOTIBBL	Write:	ODICI	ODINO	ODINO	ODIN	ODINO	ODINZ	ODICI	ODINO
\$00D2	SCI1CR1	Read:	LOOPS	SCISWAI	RSRC	М	WAKE	ILT	PE	PT
ΨΟΟΒΣ	CONTORN	Write:		00107771	IXOIXO	171	VV/ (I \L	151	' -	
\$00D3	SCI1CR2	Read:	TIE	TCIE	RIE	ILIE	TE	RE	RWU	SBK
ΨΟΟΡΟ	OOHORZ	Write:	111	TOIL	IXIL	ILIL	_	IXL	11110	ODIX
\$00D4	SCI1SR1	Read:	TDRE	TC	RDRF	IDLE	OR	NF	FE	PF
ψ00D4	SCHSKI	Write:								

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### \$00D0 - \$00D7

## **SCI1 (Asynchronous Serial Interface)**

Address	Name	[	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$00D5	SCI1SR2	Read:	0	0	0	0	0	BRK13	TXDIR	RAF
\$00D3	SCHSKZ	Write:						DKKIS	IVDIK	
\$00D6	SCI1DRH	Read:	R8	Т8	0	0	0	0	0	0
φυυρο	SCHURH	Write:		10						
\$00D7	SCI1DRL	Read:	R7	R6	R5	R4	R3	R2	R1	R0
φυσυ	SCHURL	Write:	T7	T6	T5	T4	T3	T2	T1	T0

## \$00D8 - \$00DF

## **SPI0 (Serial Peripheral Interface)**

		_								
Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$00D8	SPI0CR1	Read: Write:	SPIE	SPE	SPTIE	MSTR	CPOL	СРНА	SSOE	LSBFE
\$00D9	SPI0CR2	Read:	0	0	0	MODFEN	BIDIROE	0	SPISWAI	SPC0
фоорэ	01 1001\Z	Write:				WODI LIV	DIDINOL		OI IOVVAI	01 00
\$00DA	SPI0BR	Read:	0	SPPR2	SPPR1	SPPR0	0	SPR2	SPR1	SPR0
ΨΟΟΡΑ	SHODIX	Write:		51 1 112	511111	31110		OF IX2	311(1	31 10
\$00DB	SPI0SR	Read:	SPIF	0	SPTEF	MODF	0	0	0	0
фОООВ	3F103K	Write:								
\$00DC	Reserved	Read:	0	0	0	0	0	0	0	0
\$00DC	Reserved	Write:								
\$00DD	SPI0DR	Read: Write:	Bit7	6	5	4	3	2	1	Bit0
\$00DE	Reserved	Read:	0	0	0	0	0	0	0	0
\$00DE	Reserved	Write:								
¢00DE	Posser and	Read:	0	0	0	0	0	0	0	0
\$00DF	Reserved	Write:								

### \$00E0 - \$00E7

## IIC (Inter IC Bus)

		_								
Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$00E0	IBAD	Read: Write:	ADR7	ADR6	ADR5	ADR4	ADR3	ADR2	ADR1	0
\$00E1	IBFD	Read: Write:	IBC7	IBC6	IBC5	IBC4	IBC3	IBC2	IBC1	IBC0
\$00E2	IBCR	Read:	IBEN	IBIE	MS/SL	TX/RX	TXAK	0	0	IBSWAI
\$00EZ	IBCK	Write:	IDEN	IDIE	IVIO/OL	IA/NA	IAAN	RSTA		IDSWAI
\$00E3	IBSR	Read:	TCF	IAAS	IBB	IBAL	0	SRW	IBIF	RXAK
Φ00Ε3	IDSK	Write:				IDAL			IDIF	
\$00E4	IBDR	Read: Write:	D7	D6	D5	D4	D3	D2	D1	D 0
\$00E5	Reserved	Read:	0	0	0	0	0	0	0	0
Φ00Ε3	Reserved	Write:								
\$00E6	Reserved	Read:	0	0	0	0	0	0	0	0
Φ00⊑0	Reserved	Write:								
\$00E7	Reserved	Read:	0	0	0	0	0	0	0	0
φυυ⊑7	Reserved	Write:								
		-			The state of the s	·	<u> </u>		·	

#### \$00E8 - \$00EF

#### **BDLC (Byte Level Data Link Controller J1850)**

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$00E8	DLCBCR1	Read:	IMSG	CLKS	0	0	0	0	IE	WCM
ΨΟΟΕΟ	DEODORT	Write:	IIVIOO	OLIKO					, L	VVOIVI
\$00E9	DLCBSVR	Read:	0	0	13	12	<b>I</b> 1	10	0	0
φυσΕθ	DECESVIC	Write:								
\$00EA	DLCBCR2	Read:	SMRST	DLOOP	RX4XE	NBFS	TEOD	TSIFR	TMIFR1	TMIFR0
ΨUULA	DEODORZ	Write:	OWING	DLOOI	IVAAVE	ס ומאו		10111	I IVIII IX I	TIVIII IXO
\$00EB	DLCBDR	Read:	D7	D6	D5	D4	D3	D2	D1	D0
<b>WOOLD</b>	DEODDIN	Write:	Di	b	2	ל	2	DZ	וט	Do
\$00EC	DLCBARD	Read:	0	RXPOL	0	0	ВО3	BO2	BO1	BO0
ΨΟΟΕΟ	DECDAND	Write:		IXI OL			3	502	БОТ	БОО
\$00ED	DLCBRSR	Read:	0	0	R5	R4	R3	R2	R1	R0
φυσΕυ	DECENSION	Write:			NΟ	N <del>4</del>	No	NΖ	I NI	NU
\$00EE	DLCSCR	Read:	0	0	0	BDLCE	0	0	0	0
ΦΟΟΕΕ	DLCGCK	Write:				BDLCL				
\$00EF	DLCBSTAT	Read:	0	0	0	0	0	0	0	IDLE
φυυ⊑Γ	DECESTAL	Write:								

#### \$00F0 - \$00F7

#### **SPI1 (Serial Peripheral Interface)**

		-								
Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$00F0	SPI1CR1	Read: Write:	SPIE	SPE	SPTIE	MSTR	CPOL	СРНА	SSOE	LSBFE
\$00F1	SPI1CR2	Read:	0	0	0	MODFEN	BIDIROE	0	SPISWAI	SPC0
φυυς ι	SPITCKZ	Write:				INIODEEN	DIDIKUE		SPISWAI	3500
\$00F2	SPI1BR	Read:	0	SPPR2	SPPR1	SPPR0	0	SPR2	SPR1	SPR0
φυυΓ2	SPIIDK	Write:		SFFRZ	SPEKI	SPPRU		SFKZ	SPKI	SPRU
<b></b> ተለሰር 2	SPI1SR	Read:	SPIF	0	SPTEF	MODF	0	0	0	0
\$00F3	SPIISK	Write:								
<b>₾</b> 00 <b>□</b> 4	Decembed	Read:	0	0	0	0	0	0	0	0
\$00F4	Reserved	Write:								
<b>₾</b>	SPI1DR	Read:	Bit7	6	5	4	3	2	1	D:+O
\$00F5	SPIIDK	Write:	DILI	О	5	4	3	2	ı	Bit0
¢ሰባርና	Reserved	Read:	0	0	0	0	0	0	0	0
\$00F6	Reserved	Write:								
<b></b>	Decembed	Read:	0	0	0	0	0	0	0	0
\$00F7	Reserved	Write:								

### \$00F8 - \$00FF

#### Reserved

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$00F8 -	Reserved	Read:	0	0	0	0	0	0	0	0
\$00FF	Reserved	Write:								

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#### \$0100 - \$010F

### Flash Control Register (fts128k2)

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$0100	FCLKDIV	Read: Write:	FDIVLD	PRDIV8	FDIV5	FDIV4	FDIV3	FDIV2	FDIV1	FDIV0
\$0101	FSEC	Read:	KEYEN1	KEYEN0	NV5	NV4	NV3	NV2	SEC1	SEC0
φυτυτ	FSEC	Write:								
\$0102	FTSTMOD	Read: Write:	0	0	0	WRALL	0	0	0	0
\$0103	FCNFG	Read:	CBEIE	CCIE	KEYACC	0	0	0	BKSEL1	BKSEL0
φυτου	101410	Write:	OBLIL	OOIL	KLIAOO				DIOLLI	DIXOLLO
\$0104	FPROT	Read: Write:	FPOPEN	NV6	FPHDIS	FPHS1	FPHS0	FPLDIS	FPLS1	FPLS0
\$0105	FSTAT	Read:	CBEIF	CCIF	PVIOL	ACCERR	0	BLANK	0	0
φυτυσ	I SIAI	Write:	CDLII		I VIOL	ACCLINIC		DLAININ		
\$0106	FCMD	Read:	0	CMDB6	CMDB5	0	0	CMDB2	0	CMDB0
*		Write:				_	_		_	
\$0107	Reserved for	Read:	0	0	0	0	0	0	0	0
<b>4</b> • • • • • • • • • • • • • • • • • • •	Factory Test	Write:								
\$0108	FADDRHI	Read: Write:	0	Bit 14	13	12	11	10	9	Bit 8
\$0109	FADDRLO	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$010A	FDATAHI	Read: Write:	Bit 15	14	13	12	11	10	9	Bit 8
\$010B	FDATALO	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$010C -	Reserved	Read:	0	0	0	0	0	0	0	0
\$010F	i vesei veu	Write:								

### \$0110 - \$011B

## **EEPROM Control Register (eets2k)**

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$0110	ECLKDIV	Read: Write:	EDIVLD	PRDIV8	EDIV5	EDIV4	EDIV3	EDIV2	EDIV1	EDIV0
\$0111	Reserved	Read:	0	0	0	0	0	0	0	0
<b>4</b>		Write:								
\$0112	Reserved for	Read:	0	0	0	0	0	0	0	0
ψΟΤΙΖ	Factory Test	Write:								
<b>CO112</b>	ECNFG	Read:	CBEIE	CCIE	0	0	0	0	0	0
\$0113	ECNEG	Write:	CDEIE	CCIE						
<b>CO111</b>	EPROT	Read:	EPOPEN	NV6	NV5	NV4	EPDIS	EP2	EP1	EP0
\$0114	EPROI	Write:	EPOPEN				EPDIS	EP2	EPI	EPU
\$0115	ESTAT	Read:	CBEIF	CCIF	PVIOL	ACCERR	0	BLANK	0	0
φυτισ	ESTAI	Write:	CDEIF		PVIOL	ACCERR		DLAINN		
\$0116	ECMD	Read:	0	CMDB6	CMDB5	0	0	CMDB2	0	CMDB0
φυτιο	ECIVID	Write:		CIVIDBO	CIVIDES			CIVIDB2		CIVIDBU
<b>CO117</b>	Reserved for	Read:	0	0	0	0	0	0	0	0
\$0117	Factory Test	Write:								
¢0110	EADDRHI	Read:	0	0	0	0	0	0	Dit 0	Dit 0
\$0118	EADDKII	Write:							Bit 9	Bit 8

## \$0110 - \$011B

### **EEPROM Control Register (eets2k)**

Address	Name	[	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$0119	EADDRLO	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0
\$011A	EDATAHI	Read: Write:	Bit 15	14	13	12	11	10	9	Bit 8
\$011B	EDATALO	Read: Write:	Bit 7	6	5	4	3	2	1	Bit 0

#### \$011C - \$011F

## **Reserved for RAM Control Register**

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$011C -	Reserved	Read:	0	0	0	0	0	0	0	0
\$011F	Reserved	Write:								

#### \$0120 - \$013F

## ATD1 (Analog to Digital Converter 10 Bit 8 Channel)

		,								
Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$0120	ATD1CTL0	Read:	0	0	0	0	0	0	0	0
ψ0120	AIDIOILO	Write:								
\$0121	ATD1CTL1	Read:	0	0	0	0	0	0	0	0
ΨΟΙΖΙ	AIDIOILI	Write:								
\$0122	ATD1CTL2	Read:	ADPU	AFFC	AWAI	ETRIGLE	ETRIGP	ETRIG	ASCIE	ASCIF
ψυτΖΖ	AIDICILZ	Write:	ADIO	ALIC	AVVAI	LINIGEL	LING	LING	AGGIL	
\$0123	ATD1CTL3	Read:	0	S8C	S4C	S2C	S1C	FIFO	FRZ1	FRZ0
φ0123	AIDICILS	Write:		360	540	320	310	FIFO	FNZI	FRZU
\$0124	ATD1CTL4	Read:	SRES8	SMP1	SMP0	PRS4	PRS3	PRS2	PRS1	PRS0
φ012 <del>4</del>	AIDICIL4	Write:	SKESO	SIVIF	SIVIFU	PK34	FRSS	FK32	FROI	PRSU
<b>CO10E</b>	ATD1CTL5	Read:	DJM	DSGN	CCAN	MULT	0	СС	CD	CA
\$0125	AIDICILS	Write:	DJIVI	DOGN	SCAN	MULI		CC	СВ	CA
<b>CO40C</b>	ATD4 CTATO	Read:	SCF	0	ETORF	FIFOR	0	CC2	CC1	CC0
\$0126	ATD1STAT0	Write:								
<b>CO407</b>	December	Read:	0	0	0	0	0	0	0	0
\$0127	Reserved	Write:								
00400	ATD 4TE 0T0	Read:	0	0	0	0	0	0	0	0
\$0128	ATD1TEST0	Write:								
00100	ATD 4TE 0T 4	Read:	0	0	0	0	0		0	
\$0129	ATD1TEST1	Write:						0		SC
		Read:	0	0	0	0	0	0	0	0
\$012A	Reserved	Write:								
		Read:	CCF7	CCF6	CCF5	CCF4	CCF3	CCF2	CCF1	CCF0
\$012B	ATD1STAT1	Write:								
	_	Read:	0	0	0	0	0	0	0	0
\$012C	Reserved	Write:								
		Read:								
\$012D	ATD1DIEN	Write:	Bit 7	6	5	4	3	2	1	Bit 0
		Read:	0	0	0	0	0	0	0	0
\$012E	Reserved	Write:						,		
		Read:	Bit7	6	5	4	3	2	1	BIT 0
\$012F	PORTAD1	Write:						_		D11 0
		vviite.								

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#### \$0120 - \$013F

## ATD1 (Analog to Digital Converter 10 Bit 8 Channel)

		_								
Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$0130	ATD1DR0H	Read:	Bit15	14	13	12	11	10	9	Bit8
ψυτου	AIDIDIOII	Write:								
\$0131	ATD1DR0L	Read:	Bit7	Bit6	0	0	0	0	0	0
ψΟΙΟΙ	AIDIDIOL	Write:								
\$0132	ATD1DR1H	Read:	Bit15	14	13	12	11	10	9	Bit8
ΨΟΤΟΣ	AIDIDICIII	Write:								
\$0133	ATD1DR1L	Read:	Bit7	Bit6	0	0	0	0	0	0
φυτου	AIDIDICIE	Write:								
\$0134	ATD1DR2H	Read:	Bit15	14	13	12	11	10	9	Bit8
ΨΟΙΟΨ	AIDIDICEII	Write:								
\$0135	ATD1DR2L	Read:	Bit7	Bit6	0	0	0	0	0	0
φυτου	MIDIDIZE	Write:								
\$0136	ATD1DR3H	Read:	Bit15	14	13	12	11	10	9	Bit8
φυτου	ALDIDION	Write:								
\$0137	ATD1DR3L	Read:	Bit7	Bit6	0	0	0	0	0	0
ψΟ137	AIDIDIGE	Write:								
\$0138	ATD1DR4H	Read:	Bit15	14	13	12	11	10	9	Bit8
φυτου	/(IDIDICTI	Write:								
\$0139	ATD1DR4L	Read:	Bit7	Bit6	0	0	0	0	0	0
ψυ100	AIDIDINAL	Write:								
\$013A	ATD1DR5H	Read:	Bit15	14	13	12	11	10	9	Bit8
ψΟΙΟΛ	AIDIDIOII	Write:								
\$013B	ATD1DR5L	Read:	Bit7	Bit6	0	0	0	0	0	0
ψΟΙΟΕ	AIDIDIGE	Write:								
\$013C	ATD1DR6H	Read:	Bit15	14	13	12	11	10	9	Bit8
ψΟ13Ο	AIDIDIOII	Write:								
\$013D	ATD1DR6L	Read:	Bit7	Bit6	0	0	0	0	0	0
φυισυ	AIDIDNOL	Write:								
\$013E	ATD1DR7H	Read:	Bit15	14	13	12	11	10	9	Bit8
ψυτο⊑	VIDIDUIU	Write:								
\$013F	ATD1DR7L	Read:	Bit7	Bit6	0	0	0	0	0	0
φυιοτ	AIDIDK/L	Write:								

#### \$0140 - \$017F

## **CANO (Motorola Scalable CAN - MSCAN)**

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
/ ladi coo	Name		Dit 1		Dit 0		Dit 0	DIL Z	Dit 1	Dit 0
\$0140	CAN0CTL0	Read:	RXFRM	RXACT	CSWAI	SYNCH	TIME	WUPE	SLPRQ	INITRQ
Ψ01-10	CANOCILO	Write:	TXXT TXIVI		COVVAI		111111	VVOI L	OLI INQ	IIIIIII
		Read:					0		SLPAK	INITAK
\$0141	CAN0CTL1	Write:	CANE	CLKSRC	LOOPB	LISTEN	-	WUPM		
\$0142	CAN0BTR0	Read:	SJW1	SJW0	BRP5	BRP4	BRP3	BRP2	BRP1	BRP0
φ0142	CANOBINO	Write:	33771	33770	BKF3	DIXE4	BKF3	DITE	DICE	BKFU
		Read:								
\$0143	CAN0BTR1	Write:	SAMP	TSEG22	TSEG21	TSEG20	TSEG13	TSEG12	TSEG11	TSEG10
\$0144	CAN0RFLG	Read:	WUPIF	CSCIF	RSTAT1	RSTAT0	TSTAT1	TSTAT0	OVRIF	RXF
<b>Ф</b> 0144	CANURELG	Write:	WUPIF	CSCIF					OVRIF	KAF
		Read:								
\$0145	CAN0RIER		WUPIE	CSCIE	RSTATE1	RSTATE0	TSTATE1	TSTATE0	OVRIE	RXFIE
		Write:				•		•		

### \$0140 - \$017F

### **CANO (Motorola Scalable CAN - MSCAN)**

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$0146	CAN0TFLG	Read:	0	0	0	0	0	TXE2	TXE1	TXE0
φοιτο	0/111011120	Write:						IXLZ	1/\_1	TALO
\$0147	CAN0TIER	Read:	0	0	0	0	0	TXEIE2	TXEIE1	TXEIE0
*****		Write:								
\$0148	CAN0TARQ	Read:	0	0	0	0	0	ABTRQ2	ABTRQ1	ABTRQ0
		Write:								
\$0149	CAN0TAAK	Read:	0	0	0	0	0	ABTAK2	ABTAK1	ABTAK0
		Write:		0	0	0	0			
\$014A	CAN0TBSEL	Read:	0	0	0	0	0	TX2	TX1	TX0
		Write:		0			0	IDHIT2	IDHIT1	IDHIT0
\$014B	<b>CANOIDAC</b>	Read: Write:	0	0	IDAM1	IDAM0	0	IDHI12	וווחטו	ווחטו
		Read:	0	0	0	0	0	0	0	0
\$014C	Reserved	Write:	0	U	U	U	U	U	U	U
		Read:	0	0	0	0	0	0	0	0
\$014D	Reserved	Write:	0	0	0	U	U	U	0	U
		Read:	RXERR7	RXERR6	RXERR5	RXERR4	RXERR3	RXERR2	RXERR1	RXERR0
\$014E	CAN0RXERR	Write:	TOTELLO	TOTELLITO	TOTELLIO	TOTELLICI	TOTELLIO	TOTELLITE	TOTELLICI	TOTELLITO
		Read:	TXERR7	TXERR6	TXERR5	TXERR4	TXERR3	TXERR2	TXERR1	TXERR0
\$014F	CAN0TXERR	Write:								
\$0150 -	CANOIDARO -	Read:								
\$0153	CAN0IDAR3	Write:	AC7	AC6	AC5	AC4	AC3	AC2	AC1	AC0
\$0154 -	CANOIDMR0 -	Read:		4440	4.1.4.5		4140	4140		4140
\$0157	CAN0IDMR3	Write:	AM7	AM6	AM5	AM4	AM3	AM2	AM1	AM0
\$0158 -	CANOIDAR4 -	Read:	۸.07	400	۸ ( ۲	AC4	400	400	A C 4	400
\$015B	CAN0IDAR7	Write:	AC7	AC6	AC5	AC4	AC3	AC2	AC1	AC0
\$015C -	CANOIDMR4 -	Read:	A N 1 7	AM6	A N 1 E	AM4	ΛMΩ	AM2	AM1	AM0
\$015F	CAN0IDMR7	Write:	AM7	Aivio	AM5	AIVI4	AM3	AIVIZ	AIVII	AIVIU
\$0160 -	CAN0RXFG	Read:		FOF	REGROUN	D RECEIV	E BUFFER	see Table	1-2	
\$016F	CANURARG	Write:								
\$0170 -	CAN0TXFG	Read:		EOP	ECDUINI	TRANSM	IT BI IEEE	Coo Table	1-2	
\$017F	CANUTATO	Write:		FOR	LGROUND	LICANON	III BUFFER	V SEE TABLE	5 1 <b>-2</b>	

Table 1-2 Detailed MSCAN Foreground Receive and Transmit Buffer Layout

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
	Extended ID	Read:	ID28	ID27	ID26	ID25	ID24	ID23	ID22	ID21
\$xxx0	Standard ID	Read:	ID10	ID9	ID8	ID7	ID6	ID5	ID4	ID3
	CANxRIDR0	Write:								
	Extended ID	Read:	ID20	ID19	ID18	SRR=1	IDE=1	ID17	ID16	ID15
\$xxx1	Standard ID	Read:	ID2	ID1	ID0	RTR	IDE=0			
	CANxRIDR1	Write:								
	Extended ID	Read:	ID14	ID13	ID12	ID11	ID10	ID9	ID8	ID7
\$xxx2	Standard ID	Read:								
	CANxRIDR2	Write:								
	Extended ID	Read:	ID6	ID5	ID4	ID3	ID2	ID1	ID0	RTR
\$xxx3	Standard ID	Read:								
	CANxRIDR3	Write:								
\$xxx4-	CANxRDSR0 -	Read:	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0
\$xxxB	CANxRDSR7	Write:								

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Table 1-2 Detailed MSCAN Foreground Receive and Transmit Buffer Layout

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$xxxC	CANRxDLR	Read: Write:					DLC3	DLC2	DLC1	DLC0
\$xxxD	Reserved	Read: Write:								
\$xxxE	CANxRTSRH	Read: Write:	TSR15	TSR14	TSR13	TSR12	TSR11	TSR10	TSR9	TSR8
\$xxxF	CANxRTSRL	Read: Write:	TSR7	TSR6	TSR5	TSR4	TSR3	TSR2	TSR1	TSR0
\$xx10	Extended ID CANxTIDR0	Read: Write:	ID28	ID27	ID26	ID25	ID24	ID23	ID22	ID21
ψλλίο	Standard ID	Read: Write:	ID10	ID9	ID8	ID7	ID6	ID5	ID4	ID3
\$xx11	Extended ID CANxTIDR1	Read: Write:	ID20	ID19	ID18	SRR=1	IDE=1	ID17	ID16	ID15
ΨΑΑΤΤ	Standard ID	Read: Write:	ID2	ID1	ID0	RTR	IDE=0			
\$xx12	Extended ID CANxTIDR2	Read: Write:	ID14	ID13	ID12	ID11	ID10	ID9	ID8	ID7
ΨΛΛΙΖ	Standard ID	Read: Write:								
¢.0.42	Extended ID CANxTIDR3	Read: Write:	ID6	ID5	ID4	ID3	ID2	ID1	ID0	RTR
\$xx13	Standard ID	Read: Write:								
\$xx14- \$xx1B	CANxTDSR0 - CANxTDSR7	Read: Write:	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0
\$xx1C	CANxTDLR	Read: Write:					DLC3	DLC2	DLC1	DLC0
\$xx1D	CONxTTBPR	Read: Write:	PRIO7	PRIO6	PRIO5	PRIO4	PRIO3	PRIO2	PRIO1	PRIO0
\$xx1E	CANxTTSRH	Read: Write:	TSR15	TSR14	TSR13	TSR12	TSR11	TSR10	TSR9	TSR8
\$xx1F	CANxTTSRL	Read: Write:	TSR7	TSR6	TSR5	TSR4	TSR3	TSR2	TSR1	TSR0

### \$0180 - \$01BF

## **CAN1 (Motorola Scalable CAN - MSCAN)**

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$0180	CAN1CTL0	Read: Write:	RXFRM	RXACT	CSWAI	SYNCH	TIME	WUPE	SLPRQ	INITRQ
\$0181	CAN1CTL1	Read: Write:	CANE	CLKSRC	LOOPB	LISTEN	0	WUPM	SLPAK	INITAK
\$0182	CAN1BTR0	Read: Write:	SJW1	SJW0	BRP5	BRP4	BRP3	BRP2	BRP1	BRP0
\$0183	CAN1BTR1	Read: Write:	SAMP	TSEG22	TSEG21	TSEG20	TSEG13	TSEG12	TSEG11	TSEG10
\$0184	CAN1RFLG	Read: Write:	WUPIF	CSCIF	RSTAT1	RSTAT0	TSTAT1	TSTAT0	OVRIF	RXF

(M) MOTOROLA

### \$0180 - \$01BF

## **CAN1 (Motorola Scalable CAN - MSCAN)**

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$0185	CAN1RIER	Read: Write:	WUPIE	CSCIE	RSTATE1	RSTATE0	TSTATE1	TSTATE0	OVRIE	RXFIE
\$0186	CAN1TFLG	Read: Write:	0	0	0	0	0	TXE2	TXE1	TXE0
\$0187	CAN1TIER	Read: Write:	0	0	0	0	0	TXEIE2	TXEIE1	TXEIE0
\$0188	CAN1TARQ	Read: Write:	0	0	0	0	0	ABTRQ2	ABTRQ1	ABTRQ0
\$0189	CAN1TAAK	Read: Write:	0	0	0	0	0	ABTAK2	ABTAK1	ABTAK0
\$018A	CAN1TBSEL	Read: Write:	0	0	0	0	0	TX2	TX1	TX0
\$018B	CAN1IDAC	Read: Write:	0	0	IDAM1	IDAM0	0	IDHIT2	IDHIT1	IDHIT0
\$018C	Reserved	Read: Write:	0	0	0	0	0	0	0	0
\$018D	Reserved	Read: Write:	0	0	0	0	0	0	0	0
\$018E	CAN1RXERR	Read: Write:	RXERR7	RXERR6	RXERR5	RXERR4	RXERR3	RXERR2	RXERR1	RXERR0
\$018F	CAN1TXERR	Read: Write:	TXERR7	TXERR6	TXERR5	TXERR4	TXERR3	TXERR2	TXERR1	TXERR0
\$0190 - \$0193	CAN1IDAR0 - CAN1IDAR3	Read: Write:	AC7	AC6	AC5	AC4	AC3	AC2	AC1	AC0
\$0194 - \$0197	CAN1IDMR0 - CAN1IDMR3	Read: Write:	AM7	AM6	AM5	AM4	АМЗ	AM2	AM1	AM0
\$0198 - \$019B	CAN1IDAR4 - CAN1IDAR7	Read: Write:	AC7	AC6	AC5	AC4	AC3	AC2	AC1	AC0
\$019C - \$019F	CAN1IDMR4 - CAN1IDMR7	Read: Write:	AM7	AM6	AM5	AM4	AM3	AM2	AM1	AM0
\$01A0 - \$01AF	CAN0RXFG	Read: Write:		FOF	REGROUN	D RECEIV	E BUFFER	see Table	1-2	
\$01B0 - \$01BF	CAN0TXFG	Read: Write:		FOR	EGROUNI	) TRANSM	IT BUFFER	R see Table	e 1-2	

#### \$01C0 - \$01FF

#### Reserved

Address Name \$01C0 -Reserved \$01FF

	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
Read:	0	0	0	0	0	0	0	0
Write:								
vviile.								

### \$0200 - \$023F

#### Reserved

Address Name \$020C -Reserved \$023F

Read:	
Write:	

	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
ad:	0	0	0	0	0	0	0	0
te:								

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# \$0240 - \$027F PIM (Port Integration Module)

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$0240	PTT	Read: Write:	PTT7	PTT6	PTT5	PTT4	PTT3	PTT2	PTT1	PTT0
\$0241	PTIT	Read:	PTIT7	PTIT6	PTIT5	PTIT4	PTIT3	PTIT2	PTIT1	PTIT0
\$0242	DDRT	Write: Read: Write:	DDRT7	DDRT7	DDRT5	DDRT4	DDRT3	DDRT2	DDRT1	DDRT0
\$0243	RDRT	Read: Write:	RDRT7	RDRT6	RDRT5	RDRT4	RDRT3	RDRT2	RDRT1	RDRT0
\$0244	PERT	Read: Write:	PERT7	PERT6	PERT5	PERT4	PERT3	PERT2	PERT1	PERT0
\$0245	PPST	Read: Write:	PPST7	PPST6	PPST5	PPST4	PPST3	PPST2	PPST1	PPST0
\$0246	Reserved	Read: Write:	0	0	0	0	0	0	0	0
\$0247	Reserved	Read:	0	0	0	0	0	0	0	0
ψ02+1 ======	Treserved	Write:								
\$0248	PTS	Read: Write:	PTS7	PTS6	PTS5	PTS4	PTS3	PTS2	PTS1	PTS0
\$0249	PTIS	Read: Write:	PTIS7	PTIS6	PTIS5	PTIS4	PTIS3	PTIS2	PTIS1	PTIS0
\$024A	DDRS	Read: Write:	DDRS7	DDRS7	DDRS5	DDRS4	DDRS3	DDRS2	DDRS1	DDRS0
\$024B	RDRS	Read: Write:	RDRS7	RDRS6	RDRS5	RDRS4	RDRS3	RDRS2	RDRS1	RDRS0
\$024C	PERS	Read: Write:	PERS7	PERS6	PERS5	PERS4	PERS3	PERS2	PERS1	PERS0
\$024D	PPSS	Read: Write:	PPSS7	PPSS6	PPSS5	PPSS4	PPSS3	PPSS2	PPSS1	PPSS0
\$024E	WOMS	Read: Write:	WOMS7	WOMS6	WOMS5	WOMS4	WOMS3	WOMS2	WOMS1	WOMS0
\$024F	Reserved	Read: Write:	0	0	0	0	0	0	0	0
\$0250	PTM	Read: Write:	PTM7	PTM6	PTM5	PTM4	PTM3	PTM2	PTM1	PTM0
\$0251	PTIM	Read:	PTIM7	PTIM6	PTIM5	PTIM4	PTIM3	PTIM2	PTIM1	PTIM0
\$0252	DDRM	Write: Read: Write:	DDRM7	DDRM7	DDRM5	DDRM4	DDRM3	DDRM2	DDRM1	DDRM0
\$0253	RDRM	Read: Write:	RDRM7	RDRM6	RDRM5	RDRM4	RDRM3	RDRM2	RDRM1	RDRM0
\$0254	PERM	Read: Write:	PERM7	PERM6	PERM5	PERM4	PERM3	PERM2	PERM1	PERM0
\$0255	PPSM	Read: Write:	PPSM7	PPSM6	PPSM5	PPSM4	PPSM3	PPSM2	PPSM1	PPSM0
\$0256	WOMM	Read: Write:	WOMM7	WOMM6	WOMM5	WOMM4	WOMM3	WOMM2	WOMM1	WOMM0
\$0257	MODRR	Read: Write:	0	0	MODRR5	MODRR4	MODRR3	MODRR2	MODRR1	MODRR0
\$0258	PTP	Read: Write:	PTP7	PTP6	PTP5	PTP4	PTP3	PTP2	PTP1	PTP0

## \$0240 - \$027F

## **PIM (Port Integration Module)**

Address	Name	Daad	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$0259	PTIP	Read:	PTIP7	PTIP6	PTIP5	PTIP4	PTIP3	PTIP2	PTIP1	PTIP0
		Write:								
\$025A	DDRP	Read: Write:	DDRP7	DDRP7	DDRP5	DDRP4	DDRP3	DDRP2	DDRP1	DDRP0
\$025B	RDRP	Read: Write:	RDRP7	RDRP6	RDRP5	RDRP4	RDRP3	RDRP2	RDRP1	RDRP0
\$025C	PERP	Read: Write:	PERP7	PERP6	PERP5	PERP4	PERP3	PERP2	PERP1	PERP0
\$025D	PPSP	Read: Write:	PPSP7	PPSP6	PPSP5	PPSP4	PPSP3	PPSP2	PPSP1	PPSS0
\$025E	PIEP	Read: Write:	PIEP7	PIEP6	PIEP5	PIEP4	PIEP3	PIEP2	PIEP1	PIEP0
\$025F	PIFP	Read: Write:	PIFP7	PIFP6	PIFP5	PIFP4	PIFP3	PIFP2	PIFP1	PIFP0
\$0260	PTH	Read: Write:	PTH7	PTH6	PTH5	PTH4	PTH3	PTH2	PTH1	PTH0
\$0261	PTIH	Read: Write:	PTIH7	PTIH6	PTIH5	PTIH4	PTIH3	PTIH2	PTIH1	PTIH0
\$0262	DDRH	Read: Write:	DDRH7	DDRH7	DDRH5	DDRH4	DDRH3	DDRH2	DDRH1	DDRH0
\$0263	RDRH	Read: Write:	RDRH7	RDRH6	RDRH5	RDRH4	RDRH3	RDRH2	RDRH1	RDRH0
\$0264	PERH	Read: Write:	PERH7	PERH6	PERH5	PERH4	PERH3	PERH2	PERH1	PERH0
\$0265	PPSH	Read: Write:	PPSH7	PPSH6	PPSH5	PPSH4	PPSH3	PPSH2	PPSH1	PPSH0
\$0266	PIEH	Read: Write:	PIEH7	PIEH6	PIEH5	PIEH4	PIEH3	PIEH2	PIEH1	PIEH0
\$0267	PIFH	Read: Write:	PIFH7	PIFH6	PIFH5	PIFH4	PIFH3	PIFH2	PIFH1	PIFH0
\$0268	PTJ	Read: Write:	PTJ7	PTJ6	0	0	0	0	PTJ1	PTJ0
\$0269	PTIJ	Read:	PTIJ7	PTIJ6	0	0	0	0	PTIJ1	PTIJ0
φ0209	FIIJ	Write:								
\$026A	DDRJ	Read: Write:	DDRJ7	DDRJ7	0	0	0	0	DDRJ1	DDRJ0
\$026B	RDRJ	Read: Write:	RDRJ7	RDRJ6	0	0	0	0	RDRJ1	RDRJ0
\$026C	PERJ	Read: Write:	PERJ7	PERJ6	0	0	0	0	PERJ1	PERJ0
\$026D	PPSJ	Read: Write:	PPSJ7	PPSJ6	0	0	0	0	PPSJ1	PPSJ0
\$026E	PIEJ	Read: Write:	PIEJ7	PIEJ6	0	0	0	0	PIEJ1	PIEJ0
\$026F	PIFJ	Read: Write:	PIFJ7	PIFJ6	0	0	0	0	PIFJ1	PIFJ0
\$0270 -	Boossiss	Read:	0	0	0	0	0	0	0	0
\$027F	Reserved	Write:								

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### \$0280 - \$02BF

### **CAN4 (Motorola Scalable CAN - MSCAN)**

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$0280	CAN4CTL0	Read: Write:	RXFRM	RXACT	CSWAI	SYNCH	TIME	WUPE	SLPRQ	INITRQ
\$0281	CAN4CTL1	Read: Write:	CANE	CLKSRC	LOOPB	LISTEN	0	WUPM	SLPAK	INITAK
\$0282	CAN4BTR0	Read: Write:	SJW1	SJW0	BRP5	BRP4	BRP3	BRP2	BRP1	BRP0
\$0283	CAN4BTR1	Read: Write:	SAMP	TSEG22	TSEG21	TSEG20	TSEG13	TSEG12	TSEG11	TSEG10
\$0284	CAN4RFLG	Read: Write:	WUPIF	CSCIF	RSTAT1	RSTAT0	TSTAT1	TSTAT0	OVRIF	RXF
\$0285	CAN4RIER	Read: Write:	WUPIE	CSCIE	RSTATE1	RSTATE0	TSTATE1	TSTATE0	OVRIE	RXFIE
\$0286	CAN4TFLG	Read: Write:	0	0	0	0	0	TXE2	TXE1	TXE0
\$0287	CAN4TIER	Read: Write:	0	0	0	0	0	TXEIE2	TXEIE1	TXEIE0
\$0288	CAN4TARQ	Read: Write:	0	0	0	0	0	ABTRQ2	ABTRQ1	ABTRQ0
\$0289	CAN4TAAK	Read:	0	0	0	0	0	ABTAK2	ABTAK1	ABTAK0
***		Write:	0	0	0	0	0			
\$028A	CAN4TBSEL	Read: Write:	0	0	0	0	0	TX2	TX1	TX0
\$028B	CAN4IDAC	Read: Write:	0	0	IDAM1	IDAM0	0	IDHIT2	IDHIT1	IDHIT0
\$028C	Reserved	Read: Write:	0	0	0	0	0	0	0	0
\$028D	Reserved	Read: Write:	0	0	0	0	0	0	0	0
\$028E	CAN4RXERR		RXERR7	RXERR6	RXERR5	RXERR4	RXERR3	RXERR2	RXERR1	RXERR0
\$028F	CAN4TXERR	Read: Write:	TXERR7	TXERR6	TXERR5	TXERR4	TXERR3	TXERR2	TXERR1	TXERR0
\$0290 - \$0293	CANOIDARO - CANOIDAR3	Read: Write:	AC7	AC6	AC5	AC4	AC3	AC2	AC1	AC0
\$0294 - \$0297	CANOIDMR0 - CANOIDMR3	Read: Write:	AM7	AM6	AM5	AM4	AM3	AM2	AM1	AM0
\$0298 - \$029B	CANOIDAR4 - CANOIDAR7	Read: Write:	AC7	AC6	AC5	AC4	AC3	AC2	AC1	AC0
\$029C - \$029F	CANOIDMR4 - CANOIDMR7	Read:	AM7	AM6	AM5	AM4	AM3	AM2	AM1	AM0
\$02A0 -	CAN4RXFG	Read:		FOI	REGROUN	D RECEIV	E BUFFER	see Table	1-2	
\$02AF \$02B0 - \$02BF	CAN4TXFG	Write: Read: Write:		FOR	EGROUNI	) TRANSM	IT BUFFE	R see Table	e 1-2	



#### \$02C0 - \$02FF Reserved

Bit 7 Bit 6 Bit 0 Address Name Bit 5 Bit 4 Bit 3 Bit 2 Bit 1 0 0 0 0 0 0 0 0 \$02C0 -Read: Reserved \$02FF Write:

# \$0300 - \$035F Byteflight

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
\$0300	BFMCR	Read: Write:	INITRQ	MASTER	ALARM	SLPAK	SLPRQ	WPULSE	SSWAI	INITAK
\$0301	BFFSIZR	Read: Write:	0	0	0	FSIZ4	FSIZ3	FSIZ2	FSIZ1	FSIZ0
\$0302	BFTCR1	Read: Write:	TWX0T7	TWX0T6	TWX0T5	TWX0T4	TWX0T3	TWX0T2	TWX0T1	TWX0T0
\$0303	BFTCR2	Read: Write:	TWX0R7	TWX0R6	TWX0R5	TWX0R4	TWX0R3	TWX0R2	TWX0R1	TWX0R0
\$0304	BFTCR3	Read: Write:	TWX0D7	TWX0D6	TWX0D5	TWX0D4	TWX0D3	TWX0D2	TWX0D1	TWX0D0
\$0305	Reserved	Read: Write:	0	0	0	0	0	0	0	0
\$0306	BFRISR	Read: Write:	RCVFIF	RXIF	SYNAIF	SYNNIF	SLMMIF	0	XSYNIF	OPTDF
\$0307	BFGISR	Read: Write:	TXIF	OVRNIF	ERRIF	SYNEIF	SYNLIF	ILLPIF	LOCKIF	WAKEIF
\$0308	BFRIER	Read: Write:	RCVFIE	RXIE	SYNAIE	SYNNIE	SLMMIE	0	XSYNIE	0
\$0309	BFGIER	Read: Write:	TXIE	OVRNIE	ERRIE	SYNEIE	SYNLIE	ILLPIE	LOCKIE	WAKEIE
\$030A	BFRIVEC	Read: Write:	0	0	0	0	RIVEC3	RIVEC2	RIVEC1	RIVEC0
\$030B	BFTIVEC	Read: Write:	0	0	0	0	TIVEC3	TIVEC2	TIVEC1	TIVEC0
\$030C	BFFIDAC	Read: Write:	FIDAC7	FIDAC6	FIDAC5	FIDAC4	FIDAC3	FIDAC2	FIDAC1	FIDAC0
\$030D	BFFIDMR	Read: Write:	FIDMR7	FIDMR6	FIDMR5	FIDMR4	FIDMR3	FIDMR2	FIDMR1	FIDMR0
\$030E	BFMVR	Read: Write:	MVR7	MVR6	MVR5	MVR4	MVR3	MVR2	MVR1	MVR0
\$030F	Reserved	Read: Write:	0	0	0	0	0	0	0	0
\$0310	BFPCTLBF	Read: Write:	PMEREN	0	PSLMEN	PERREN	PROKEN	PSYNEN	0	BFEN
\$0311	Reserved	Read: Write:	0	0	0	0	0	0	0	0
\$0312	BFBUFLOCK	Read:	0	0	0	0	0	0	TXBUFL OCK	RXBUFL OCK
\$0313	Reserved	Write: Read: Write:	0	0	0	0	0	0	0	0
\$0314	BFFIDRJ	Read: Write:	FIDRJ7	FIDRJ6	FIDRJ5	FIDRJ4	FIDRJ3	FIDRJ2	FIDRJ1	FIDRJ0

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## \$0300 - \$035F

# Byteflight

Address	Name		Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
<b>\$021</b> E	DEEIDDMD	Read:	FIDRMR 7	FIDRMR 6	FIDRMR 5	FIDRMR 5	FIDRMR 4	FIDRMR 3	FIDRMR 2	FIDRMR 1
\$0315	BFFIDRMR	Write:	,	0	3	3	4	3		'
\$0316	Reserved	Read:	0	0	0	0	0	0	0	0
φοστο	reserved	Write:	0	0	0	0	0	0	0	0
\$0317	Reserved	Read: Write:	0	0	0	0	0	0	0	0
\$0318	Reserved	Read:	0	0	0	0	0	0	0	0
φυστο	Reserved	Write:								
\$0319	Reserved	Read: Write:	0	0	0	0	0	0	0	0
	_	Read:	0	0	0	0	0	0	0	0
\$031A	Reserved	Write:	-	-	-				-	
\$031B	Reserved	Read:	0	0	0	0	0	0	0	0
•		Write: Read:	0	0	0	0	0	0	0	0
\$031C	Reserved	Write:		0	0	U	J	0	0	U
\$031D	Reserved	Read:	0	0	0	0	0	0	0	0
ψ031D	Reserved	Write:								
\$031E	Reserved	Read: Write:	0	0	0	0	0	0	0	0
<b>^</b>		Read:	0	0	0	0	0	0	0	0
\$031F	Reserved	Write:	-	-	-				-	
\$0320	BFTIDENT	Read:	ID7	ID6	ID5	ID4	ID3	ID2	ID1	ID0
·		Write: Read:								
\$0321	BFTLEN	Write:					LEN3	LEN2	LEN1	LEN0
\$0322 -	BFTDATA0-	Read:	DATA7	DATA6	DATA5	DATA4	DATA3	DATA2	DATA1	DATA0
\$032D	BFTDATA11	Write:	DAIA	DAIAU	DAIAS	DAIA	DAIAS	DAIAZ	DAIAI	DAIAU
\$032E - \$032F	Reserved	Read: Write:								
\$0330	BFRIDENT	Read:	ID7	ID6	ID5	ID4	ID3	ID2	ID1	ID0
φυσσυ	BEKIDENI	Write:	וטו	וטט	טוו	104	נטו	IDZ	וטו	IDU
\$0331	BFRLEN	Read: Write:					LEN3	LEN2	LEN1	LEN0
\$0332 -	BFRDATA0-	Read:	DATA7	DATA6	DATA5	DATA4	DATA3	DATA2	DATA1	DATA 0
\$033D	BFRDATA11	Write:		<i>D</i> /11/10	<i>D</i> /11/10	D/ (I/ ( I	<i>D</i> /11/10	Ditti	D/ (I/ (I	Brurto
\$033E- \$033F	Reserved	Read: Write:								
\$0340	BFFIDENT	Read: Write:	ID7	ID6	ID5	ID4	ID3	ID2	ID1	ID0
\$0341	BFFLEN	Read: Write:					LEN3	LEN2	LEN1	LEN0
\$0342 - \$034D	BFFDATA0- BFFDATA11	Read: Write:	DATA 7	DATA6	DATA5	DATA4	DATA3	DATA2	DATA1	DATA0
\$034E - \$034F	Reserved	Read: Write:								
\$0350 -	BFBUFCTL0 -	Read:	IFLG	IENA	LOCK	ABTAK	ABTRQ	0	0	CFG
\$035F	BFBUFCTL15	Write:	IFLG	IEINA	LOCK		ADIRU			U G

\$0360 - \$03FF

#### Reserved

Address Name \$0360 -Reserved \$03FF

	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0
Read:	0	0	0	0	0	0	0	0
Write:								

# 1.6 Part ID Assignments

The part ID is located in two 8-bit registers PARTIDH and PARTIDL (addresses \$001A and \$001B after reset). The read-only value is a unique part ID for each revision of the chip. **Table 1-3** shows the assigned part ID number.

Table 1-3 Assigned Part ID Numbers

Device	Mask Set Number	Part ID <sup>1</sup>
MC9S12DT128	1L40K	\$0111
MC9S12DT128	3L40K	\$0113
MC9S12DT128	4L40K	\$0114

#### NOTES:

1. The coding is as follows:

Bit 15-12: Major family identifier

Bit 11-8: Minor family identifier

Bit 7-4: Major mask set revision number including FAB transfers

Bit 3-0: Minor - non full - mask set revision

The device memory sizes are located in two 8-bit registers MEMSIZ0 and MEMSIZ1 (addresses \$001C and \$001D after reset). **Table 1-4** shows the read-only values of these registers. Refer to HCS12 Module Mapping Control (MMC) Block Guide for further details.

**Table 1-4 Memory size registers** 

Register name	Value
MEMSIZ0	\$13
MEMSIZ1	\$80

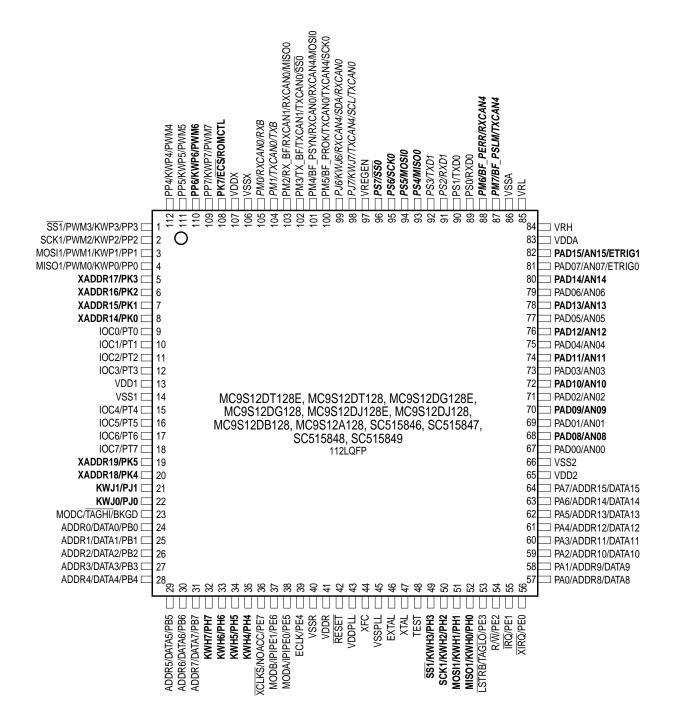
# **Section 2 Signal Description**

This section describes signals that connect off-chip. It includes a pinout diagram, a table of signal properties, and detailed discussion of signals. It is built from the signal description sections of the Block User Guides of the individual IP blocks on the device.

### 2.1 Device Pinout

The MC9S12DT128 and its derivatives are available in a 112-pin low profile quad flat pack (LQFP) and in a 80-pin quad flat pack (QFP). Most pins perform two or more functions, as described in the Signal Descriptions. **Figure 2-1**, **Figure 2-2**, and **Figure 2-3** show the pin assignments for different packages.

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Signals shown in **Bold** are not available on all the 80 pin package options
Signals shown in **Bold-Italics** are not available on the MC9S12DJ128E, MC9S12DJ128, MC9S12DG128E, MC9S12DG128E, MC9S12DG128, MC9S12DG128,

Figure 2-1 Pin assignments 112 LQFP for MC9S12DT128E, MC9S12DT128, MC9S12DG128E, MC9S12DG128, MC9S12DJ128E, MC9S12DJ128, MC9S12DB128 MC9S12A128, SC515846, SC515847, SC515848, and SC515849

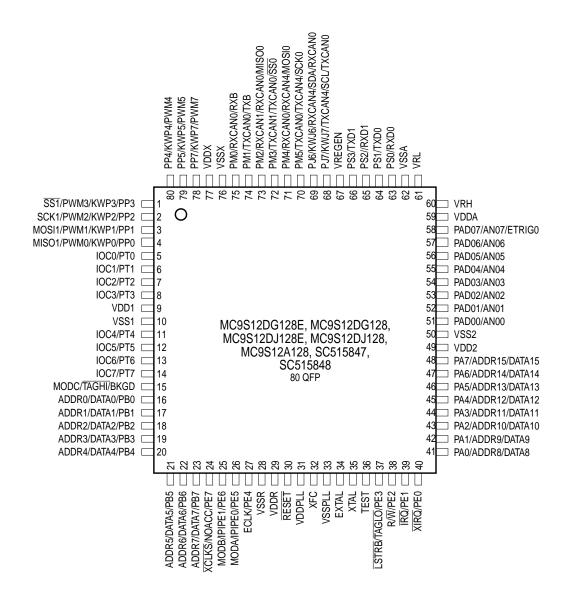


Figure 2-2 Pin Assignments in 80 QFP for MC9S12DG128E, MC9S12DG128, MC9S12DJ128E, MC9S12DJ128, MC9S12A128, SC515847, and SC515848 Bondout

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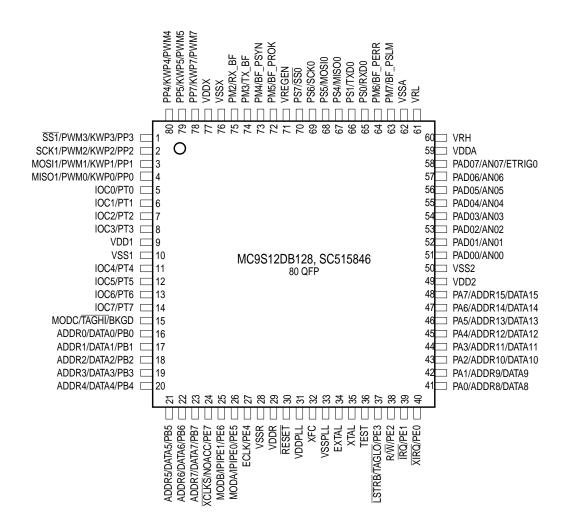


Figure 2-3 Pin Assignments in 80 QFP for MC9S12DB128 and SC515846 Bondout

# 2.2 Signal Properties Summary

**Table 2-1** summarizes the pin functionality. Signals shown in **Bold** are not available on all the 80-pin package options. Signals shown in *Bold-Italics* are not available on the MC9S12DG128E, MC9S12DG128E, MC9S12DJ128E, MC9S12DJ128, MC9S12DJ128, MC9S12DJ128, MC9S12DJ128, MC9S12DB128 and SC515848 80-pin package options. Signals shown in *Italics* are not available on MC9S12DB128 and SC515846 80-pin package options.

**Table 2-1 Signal Properties** 

Pin Name	Pin Name Function 2		Pin Name Function 4	Pin Name Function 5	Powered by	Internal Pull Resistor		- Description	
Function 1						CTRL	Reset State	Description	
EXTAL	_	_	_	_	VDDPLL	NA	NA	Oscillator Pins	
XTAL	_		_	_	VDDPLL	NA	NA		
RESET	_		_	_	VDDR	None	None	External Reset	
TEST	_	_	_	_	N.A.	None	None	Test Input	
VREGEN	_	_	_	_	VDDX	NA	NA	Voltage Regulator Enable Input	
XFC	_		_	_	VDDPLL	NA	NA	PLL Loop Filter	
BKGD	TAGHI	MODC	_	_	VDDR	Always Up	Up	Background Debug, Tag High, Mode Inpu	
PAD[15]	AN1[7]	ETRIG1	_	_	VDDA	None	None	Port AD Input, Analog Inputs, External Trigger Input (ATD1)	
PAD[14:8]	AN1[6:0]	_	_	_	VDDA	None	None	Port AD Input, Analog Inputs (ATD1)	
PAD[7]	AN0[7]	ETRIG0	_	_	VDDA	None	None	Port AD Input, Analog Inputs, External Trigger Input (ATD0)	
PAD[6:0]	AN0[6:0]	_	_	_	VDDA	None	None	Port AD Input, Analog Inputs (ATD0)	
PA[7:0]	ADDR[15:8]/ DATA[15:8]	_	_	_	VDDR	PUCR/ PUPAE	Disabled	Port A I/O, Multiplexed Address/Data	
PB[7:0]	ADDR[7:0]/ DATA[7:0]	_	_	_	VDDR	PUCR/ PUPBE	Disabled	Port B I/O, Multiplexed Address/Data	
PE7	NOACC	XCLKS	_	_	VDDR	PUCR/ PUPEE	Mode depen- dant <sup>1</sup>	Port E I/O, Access, Clock Select	
PE6	IPIPE1	MODB	_	_	VDDR		ESET pin	Port E I/O, Pipe Status, Mode Input	
PE5	IPIPE0	MODA	_	_	VDDR	low: Down		Port E I/O, Pipe Status, Mode Input	
PE4	ECLK		_		VDDR	PUCR/ PUPEE Up	Mode	Port E I/O, Bus Clock Output	
PE3	LSTRB	TAGLO	_	_	VDDR		depen-	Port E I/O, Byte Strobe, Tag Low	
PE2	R/W	_	_	_	VDDR			Port E I/O, R/W in expanded modes	
PE1	ĪRQ	_	_	_	VDDR		Port E Input, Maskable Interrupt		
PE0	XIRQ	_	_	_	VDDR	] J Op		Port E Input, Non Maskable Interrupt	
PH7	KWH7		_	_	VDDR	PERH/ PPSH	Disabled	Port H I/O, Interrupt	

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Pin Name	Pin Name			Powered	Internal Pull Resistor		- Description	
Function 1	Function 2	Function 3	Function 4	Function 5 by	CTRL	Reset State	Description	
PH6	KWH6		_	_	VDDR	PERH/ PPSH	Disabled	Port H I/O, Interrupt
PH5	KWH5		_	_	VDDR	PERH/ PPSH	Disabled	Port H I/O, Interrupt
PH4	KWH4		_	_	VDDR	PERH/ PPSH	Disabled	Port H I/O, Interrupt
PH3	KWH3	SS1	_	_	VDDR	PERH/ PPSH	Disabled	Port H I/O, Interrupt, SS of SPI1
PH2	KWH2	SCK1	_	_	VDDR	PERH/ PPSH	Disabled	Port H I/O, Interrupt, SCK of SPI1
PH1	KWH1	MOSI1	_	_	VDDR	PERH/ PPSH	Disabled	Port H I/O, Interrupt, MOSI of SPI1
PH0	KWH0	MISO1	_	_	VDDR	PERH/ PPSH	Disabled	Port H I/O, Interrupt, MISO of SPI1
PJ7	KWJ7	TXCAN4	SCL	TXCAN0	VDDX	PERJ/ PPSJ	Up	Port J I/O, Interrupt, TX of CAN4, SCL of IIC
PJ6	KWJ6	RXCAN4	SDA	RXCAN0	VDDX	PERJ/ PPSJ	Up	Port J I/O, Interrupt, RX of CAN4, SDA of IIC
PJ[1:0]	KWJ[1:0]	_	_	_	VDDX	PERJ/ PPSJ	Up	Port J I/O, Interrupts
PK7	ECS	ROMCTL	_	_	VDDX	PUCR/ PUPKE	Up	Port K I/O, Emulation Chip Select, ROM Control
PK[5:0]	XADDR[19: 14]	_	_	_	VDDX	PUCR/ PUPKE	Up	Port K I/O, Extended Addresses
PM7	BF_P\$LM	TXCAN4	_	_	VDDX	PERM/ PPSM	Disabled	Port M I/O, BF slot mismatch pulse, TX of CAN4
PM6	BF_PERR	RXCAN4	_	_	VDDX	PERM/ PPSM	Disabled	Port M I/O, BF illegal pulse/message format error pulse, RX of CAN4
PM5	BF_PROK	TXCAN0	TXCAN4	SCK0	VDDX	PERM/ PPSM	Disabled	Port M I/O, BF reception ok pulse, TX of CAN0, CAN4, SCK of SPI0
PM4	BF_PSYN	RXCAN0	RXCAN4	MOSI0	VDDX	PERM/ PPSM	Disabled	Port M I/O, BF sync pulse (Rx/Tx) OK pulse o/p, RX of CAN0, CAN4, MOSI of SPI0
PM3	TX_BF	TXCAN1	TXCAN0	<u>\$\$0</u>	VDDX	PERM/ PPSM	Disabled	Port M I/O, TX of BF, CAN1, CAN0, SS of SPI0
PM2	RX_BF	RXCAN1	RXCAN0	MISO0	VDDX	PERM/ PPSM	Disabled	Port M I/O, RX of BF, CAN1, CAN0, MISO of SPI0

Pin Name	Pin Name	Pin Name	Pin Name	Pin Name Function 5	Powered by	Internal Pull Resistor		Description
Function 1	Function 2	Function 3	Function 4			CTRL	Reset State	Description
PM1	TXCAN0	TXB	_	_	VDDX	PERM/ PPSM	Disabled	Port M I/O, TX of CANO, RX of BDLC
РМ0	RXCAN0	RXB	_	_	VDDX	PERM/ PPSM	Disabled	Port M I/O, RX of CANO, RX of BDLC
PP7	KWP7	PWM7	_	_	VDDX	PERP/ PPSP	Disabled	Port P I/O, Interrupt, Channel 7 of PWM
PP6	KWP6	PWM6	_	_	VDDX	PERP/ PPSP	Disabled	Port P I/O, Interrupt, Channel 6 of PWM
PP5	KWP5	PWM5	_	_	VDDX	PERP/ PPSP	Disabled	Port P I/O, Interrupt, Channel 5 of PWM
PP4	KWP4	PWM4	_	_	VDDX	PERP/ PPSP	Disabled	Port P I/O, Interrupt, Channel 4 of PWM
PP3	KWP3	PWM3	SS1	_	VDDX	PERP/ PPSP	Disabled	Port P I/O, Interrupt, Channel 3 of PWM, SS of SPI1
PP2	KWP2	PWM2	SCK1	_	VDDX	PERP/ PPSP	Disabled	Port P I/O, Interrupt, Channel 2 of PWM, SCK of SPI1
PP1	KWP1	PWM1	MOSI1	_	VDDX	PERP/ PPSP	Disabled	Port P I/O, Interrupt, Channel 1 of PWM, MOSI of SPI1
PP0	KWP0	PWM0	MISO1	_	VDDX	PERP/ PPSP	Disabled	Port P I/O, Interrupt, Channel 0 of PWM, MISO2 of SPI1
PS7	<u>sso</u>	_	_	_	VDDX	PERS/ PPSS	Up	Port S I/O, SS of SPI0
PS6	SCK0	_	_	_	VDDX	PERS/ PPSS	Up	Port S I/O, SCK of SPI0
PS5	MOSI0	_	_	_	VDDX	PERS/ PPSS	Up	Port S I/O, MOSI of SPI0
PS4	MISO0	_	_	_	VDDX	PERS/ PPSS	Up	Port S I/O, MISO of SPI0
PS3	TXD1	_	_	_	VDDX	PERS/ PPSS	Up	Port S I/O, TXD of SCI1
PS2	RXD1	_	_	_	VDDX	PERS/ PPSS	Up	Port S I/O, RXD of SCI1
PS1	TXD0	_	_	_	VDDX	PERS/ PPSS	Up	Port S I/O, TXD of SCI0
PS0	RXD0	_	_	_	VDDX	PERS/ PPSS	Up	Port S I/O, RXD of SCI0
PT[7:0]	IOC[7:0]	_	_	_	VDDX	PERT/ PPST	Disabled	Port T I/O, Timer channels

#### NOTES:

<sup>1.</sup> Refer to PEAR register description in HCS12 Multiplexed External Bus Interface (MEBI) Block Guide.

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# 2.3 Detailed Signal Descriptions

#### 2.3.1 EXTAL, XTAL — Oscillator Pins

EXTAL and XTAL are the crystal driver and external clock pins. On reset all the device clocks are derived from the EXTAL input frequency. XTAL is the crystal output.

#### 2.3.2 RESET — External Reset Pin

An active low bidirectional control signal, it acts as an input to initialize the MCU to a known start-up state, and an output when an internal MCU function causes a reset.

#### 2.3.3 TEST — Test Pin

This input only pin is reserved for test.

**NOTE:** The TEST pin must be tied to VSS in all applications.

#### 2.3.4 XFC — PLL Loop Filter Pin

PLL loop filter. Please ask your Motorola representative for the interactive application note to compute PLL loop filter elements. Any current leakage on this pin must be avoided.

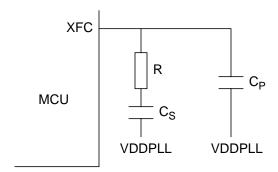


Figure 2-4 PLL Loop Filter Connections

# 2.3.5 BKGD / TAGHI / MODC — Background Debug, Tag High, and Mode Pin

The BKGD/TAGHI/MODC pin is used as a pseudo-open-drain pin for the background debug communication. In MCU expanded modes of operation when instruction tagging is on, an input low on this pin during the falling edge of E-clock tags the high half of the instruction word being read into the instruction queue. It is used as a MCU operating mode select pin during reset. The state of this pin is latched to the MODC bit at the rising edge of RESET. This pin has a permanently enabled pull-up device.

### 2.3.6 PAD[15] / AN1[7] / ETRIG1 — Port AD Input Pin [15]

PAD15 is a general purpose input pin and analog input of the analog to digital converter ATD1. It can act as an external trigger input for the ATD1.

### 2.3.7 PAD[14:8] / AN1[6:0] — Port AD Input Pins [14:8]

PAD14 - PAD8 are general purpose input pins and analog inputs of the analog to digital converter ATD1.

## 2.3.8 PAD[7] / AN0[7] / ETRIG0 — Port AD Input Pin [7]

PAD7 is a general purpose input pin and analog input of the analog to digital converter ATD0. It can act as an external trigger input for the ATD0.

## 2.3.9 PAD[6:0] / AN0[6:0] — Port AD Input Pins [6:0]

PAD6 - PAD8 are general purpose input pins and analog inputs of the analog to digital converter ATD0.

## 2.3.10 PA[7:0] / ADDR[15:8] / DATA[15:8] — Port A I/O Pins

PA7-PA0 are general purpose input or output pins. In MCU expanded modes of operation, these pins are used for the multiplexed external address and data bus.

## 2.3.11 PB[7:0] / ADDR[7:0] / DATA[7:0] — Port B I/O Pins

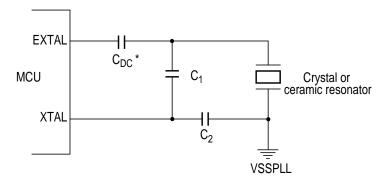
PB7-PB0 are general purpose input or output pins. In MCU expanded modes of operation, these pins are used for the multiplexed external address and data bus.

### 2.3.12 PE7 / NOACC / XCLKS — Port E I/O Pin 7

PE7 is a general purpose input or output pin. During MCU expanded modes of operation, the NOACC signal, when enabled, is used to indicate that the current bus cycle is an unused or "free" cycle. This signal will assert when the CPU is not using the bus.

The  $\overline{XCLKS}$  is an input signal which controls whether a crystal in combination with the internal Colpitts (low power) oscillator is used or whether Pierce oscillator/external clock circuitry is used. The state of this pin is latched at the rising edge of  $\overline{RESET}$ . If the input is a logic low the EXTAL pin is configured for an external clock drive. If input is a logic high an oscillator circuit is configured on EXTAL and XTAL. Since this pin is an input with a pull-up device during reset, if the pin is left floating, the default configuration is an oscillator circuit on EXTAL and XTAL.

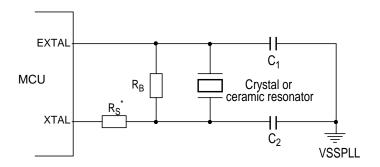
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\* Due to the nature of a translated ground Colpitts oscillator a DC voltage bias is applied to the crystal Please contact the crystal manufacturer for crystal DC

bias conditions and recommended capacitor value CDC.

Figure 2-5 Colpitts Oscillator Connections (PE7=1)



\* Rs can be zero (shorted) when used with higher frequency crystals. Refer to manufacturer's data.

Figure 2-6 Pierce Oscillator Connections (PE7=0)

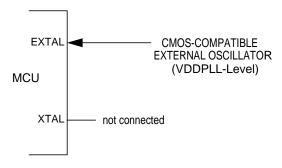


Figure 2-7 External Clock Connections (PE7=0)

#### 2.3.13 PE6 / MODB / IPIPE1 — Port E I/O Pin 6

PE6 is a general purpose input or output pin. It is used as a MCU operating mode select pin during reset. The state of this pin is latched to the MODB bit at the rising edge of  $\overline{RESET}$ . This pin is shared with the instruction queue tracking signal IPIPE1. This pin is an input with a pull-down device which is only active when  $\overline{RESET}$  is low.

#### 2.3.14 PE5 / MODA / IPIPE0 — Port E I/O Pin 5

PE5 is a general purpose input or output pin. It is used as a MCU operating mode select pin during reset. The state of this pin is latched to the MODA bit at the rising edge of  $\overline{RESET}$ . This pin is shared with the instruction queue tracking signal IPIPE0. This pin is an input with a pull-down device which is only active when  $\overline{RESET}$  is low.

#### 2.3.15 PE4 / ECLK — Port E I/O Pin 4

PE4 is a general purpose input or output pin. It can be configured to drive the internal bus clock ECLK. ECLK can be used as a timing reference.

#### 2.3.16 PE3 / LSTRB / TAGLO — Port E I/O Pin 3

PE3 is a general purpose input or output pin. In MCU expanded modes of operation,  $\overline{LSTRB}$  can be used for the low-byte strobe function to indicate the type of bus access and when instruction tagging is on,  $\overline{TAGLO}$  is used to tag the low half of the instruction word being read into the instruction queue.

#### 2.3.17 PE2 / R/W — Port E I/O Pin 2

PE2 is a general purpose input or output pin. In MCU expanded modes of operations, this pin drives the read/write output signal for the external bus. It indicates the direction of data on the external bus.

## 2.3.18 PE1 / IRQ — Port E Input Pin 1

PE1 is a general purpose input pin and the maskable interrupt request input that provides a means of applying asynchronous interrupt requests. This will wake up the MCU from STOP or WAIT mode.

# 2.3.19 PE0 / XIRQ — Port E Input Pin 0

PE0 is a general purpose input pin and the non-maskable interrupt request input that provides a means of applying asynchronous interrupt requests. This will wake up the MCU from STOP or WAIT mode.

#### 2.3.20 PH7 / KWH7 — Port H I/O Pin 7

PH7 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode.

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#### 2.3.21 PH6 / KWH6 — Port H I/O Pin 6

PH6 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode.

#### 2.3.22 PH5 / KWH5 — Port H I/O Pin 5

PH5 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode.

#### 2.3.23 PH4 / KWH4 — Port H I/O Pin 2

PH4 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode.

## 2.3.24 PH3 / KWH3 / SS1 — Port H I/O Pin 3

PH3 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode. It can be configured as slave select pin  $\overline{SS}$  of the Serial Peripheral Interface 1 (SPI1).

#### 2.3.25 PH2 / KWH2 / SCK1 — Port H I/O Pin 2

PH2 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode. It can be configured as serial clock pin SCK of the Serial Peripheral Interface 1 (SPI1).

#### 2.3.26 PH1 / KWH1 / MOSI1 — Port H I/O Pin 1

PH1 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode. It can be configured as master output (during master mode) or slave input pin (during slave mode) MOSI of the Serial Peripheral Interface 1 (SPI1).

#### 2.3.27 PH0 / KWH0 / MISO1 — Port H I/O Pin 0

PH0 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode. It can be configured as master input (during master mode) or slave output (during slave mode) pin MISO of the Serial Peripheral Interface 1 (SPI1).

#### 2.3.28 PJ7 / KWJ7 / TXCAN4 / SCL / TXCAN0 — PORT J I/O Pin 7

PJ7 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode. It can be configured as the transmit pin TXCAN for the Motorola Scalable Controller Area Network controller 0 or 4 (CAN0, CAN4) or the serial clock pin SCL of the IIC module.

#### 2.3.29 PJ6 / KWJ6 / RXCAN4 / SDA / RXCAN0 — PORT J I/O Pin 6

PJ6 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode. It can be configured as the receive pin RXCAN for the Motorola Scalable Controller Area Network controller 0 or 4 (CAN0, CAN4) or the serial data pin SDA of the IIC module.

### 2.3.30 PJ[1:0] / KWJ[1:0] — Port J I/O Pins [1:0]

PJ1 and PJ0 are general purpose input or output pins. They can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode.

#### 2.3.31 PK7 / ECS / ROMCTL — Port K I/O Pin 7

PK7 is a general purpose input or output pin. During MCU expanded modes of operation, this pin is used as the emulation chip select output (ECS). While configurating MCU expanded modes, this pin is used to enable the Flash EEPROM memory in the memory map (ROMCTL). At the rising edge of RESET, the state of this pin is latched to the ROMON bit. For a complete list of modes refer to **4.2 Chip Configuration Summary**.

## 2.3.32 PK[5:0] / XADDR[19:14] — Port K I/O Pins [5:0]

PK5-PK0 are general purpose input or output pins. In MCU expanded modes of operation, these pins provide the expanded address XADDR[19:14] for the external bus.

### 2.3.33 PM7 / BF\_PSLM / TXCAN4 — Port M I/O Pin 7

PM7 is a general purpose input or output pin. It can be configured as the slot mismatch output pulse pin of Byteflight. It can be configured as the transmit pin TXCAN of the Motorola Scalable Controller Area Network controllers 4 (CAN4).

## 2.3.34 PM6 / BF\_PERR / RXCAN4 — Port M I/O Pin 6

PM6 is a general purpose input or output pin. It can be configured as the illegal pulse or message format error output pulse pin of Byteflight. It can be configured as the receive pin RXCAN of the Motorola Scalable Controller Area Network controllers 4 (CAN4).

# 2.3.35 PM5 / BF\_PROK / TXCAN0 / TXCAN4 / SCK0 — Port M I/O Pin 5

PM5 is a general purpose input or output pin. It can be configured as the reception OK output pulse pin of Byteflight. It can be configured as the transmit pin TXCAN of the Motorola Scalable Controller Area Network controllers 0 or 4 (CAN0 or CAN4). It can be configured as the serial clock pin SCK of the Serial Peripheral Interface 0 (SPI0).

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### 2.3.36 PM4 / BF\_PSYN / RXCAN0 / RXCAN4/ MOSI0 — Port M I/O Pin 4

PM4 is a general purpose input or output pin. It can be configured as the correct synchronisation pulse reception/transmission output pulse pin of Byteflight. It can be configured as the receive pin RXCAN of the Motorola Scalable Controller Area Network controllers 0 or 4 (CAN0 or CAN4). It can be configured as the master output (during master mode) or slave input pin (during slave mode) MOSI for the Serial Peripheral Interface 0 (SPI0).

# 2.3.37 PM3 / TX\_BF / TXCAN1 / TXCAN0 / \$\overline{SS0}\$ — Port M I/O Pin 3

PM3 is a general purpose input or output pin. It can be configured as the transmit pinTX\_BF of Byteflight. It can be configured as the transmit pin TXCAN of the Motorola Scalable Controller Area Network controllers 1 or 0 (CAN1 or CAN0). It can be configured as the slave select pin  $\overline{SS}$  of the Serial Peripheral Interface 0 (SPI0).

#### 2.3.38 PM2 / RX\_BF / RXCAN1 / RXCAN0 / MISO0 — Port M I/O Pin 2

PM2 is a general purpose input or output pin. It can be configured as the receive pin RX\_BF of Byteflight. It can be configured as the receive pin RXCAN of the Motorola Scalable Controller Area Network controllers 1 or 0 (CAN1 or CAN0). It can be configured as the master input (during master mode) or slave output pin (during slave mode) MISO for the Serial Peripheral Interface 0 (SPI0).

#### 2.3.39 PM1 / TXCAN0 / TXB — Port M I/O Pin 1

PM1 is a general purpose input or output pin. It can be configured as the transmit pin TXCAN of the Motorola Scalable Controller Area Network controller 0 (CAN0). It can be configured as the transmit pin TXB of the BDLC.

#### 2.3.40 PM0 / RXCAN0 / RXB — Port M I/O Pin 0

PM0 is a general purpose input or output pin. It can be configured as the receive pin RXCAN of the Motorola Scalable Controller Area Network controller 0 (CAN0). It can be configured as the receive pin RXB of the BDLC.

#### 2.3.41 PP7 / KWP7 / PWM7 — Port P I/O Pin 7

PP7 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode. It can be configured as Pulse Width Modulator (PWM) channel 7 output.

#### 2.3.42 PP6 / KWP6 / PWM6 — Port P I/O Pin 6

PP6 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode. It can be configured as Pulse Width Modulator (PWM) channel 6 output.



### 2.3.43 PP5 / KWP5 / PWM5 — Port P I/O Pin 5

PP5 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode. It can be configured as Pulse Width Modulator (PWM) channel 5 output.

#### 2.3.44 PP4 / KWP4 / PWM4 — Port P I/O Pin 4

PP4 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode. It can be configured as Pulse Width Modulator (PWM) channel 4 output.

## 2.3.45 PP3 / KWP3 / PWM3 / SS1 — Port P I/O Pin 3

PP3 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode. It can be configured as Pulse Width Modulator (PWM) channel 3 output. It can be configured as slave select pin  $\overline{SS}$  of the Serial Peripheral Interface 1 (SPI1).

#### 2.3.46 PP2 / KWP2 / PWM2 / SCK1 — Port P I/O Pin 2

PP2 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode. It can be configured as Pulse Width Modulator (PWM) channel 2 output. It can be configured as serial clock pin SCK of the Serial Peripheral Interface 1 (SPI1).

#### 2.3.47 PP1 / KWP1 / PWM1 / MOSI1 — Port P I/O Pin 1

PP1 is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode. It can be configured as Pulse Width Modulator (PWM) channel 1 output. It can be configured as master output (during master mode) or slave input pin (during slave mode) MOSI of the Serial Peripheral Interface 1 (SPI1).

#### 2.3.48 PP0 / KWP0 / PWM0 / MISO1 — Port P I/O Pin 0

PPO is a general purpose input or output pin. It can be configured to generate an interrupt causing the MCU to exit STOP or WAIT mode. It can be configured as Pulse Width Modulator (PWM) channel 0 output. It can be configured as master input (during master mode) or slave output (during slave mode) pin MISO of the Serial Peripheral Interface 1 (SPI1).

## 2.3.49 PS7 / SS0 — Port S I/O Pin 7

PS7 is a general purpose input or output pin. It can be configured as the slave select pin  $\overline{SS}$  of the Serial Peripheral Interface 0 (SPI0).

#### 2.3.50 PS6 / SCK0 — Port S I/O Pin 6

PS6 is a general purpose input or output pin. It can be configured as the serial clock pin SCK of the Serial Peripheral Interface 0 (SPI0).



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#### 2.3.51 PS5 / MOSI0 — Port S I/O Pin 5

PS5 is a general purpose input or output pin. It can be configured as master output (during master mode) or slave input pin (during slave mode) MOSI of the Serial Peripheral Interface 0 (SPI0).

#### 2.3.52 PS4 / MISO0 — Port S I/O Pin 4

PS4 is a general purpose input or output pin. It can be configured as master input (during master mode) or slave output pin (during slave mode) MOSI of the Serial Peripheral Interface 0 (SPI0).

#### 2.3.53 PS3 / TXD1 — Port S I/O Pin 3

PS3 is a general purpose input or output pin. It can be configured as the transmit pin TXD of Serial Communication Interface 1 (SCI1).

#### 2.3.54 PS2 / RXD1 — Port S I/O Pin 2

PS2 is a general purpose input or output pin. It can be configured as the receive pin RXD of Serial Communication Interface 1 (SCI1).

#### 2.3.55 PS1 / TXD0 — Port S I/O Pin 1

PS1 is a general purpose input or output pin. It can be configured as the transmit pin TXD of Serial Communication Interface 0 (SCI0).

#### 2.3.56 PS0 / RXD0 — Port S I/O Pin 0

PS0 is a general purpose input or output pin. It can be configured as the receive pin RXD of Serial Communication Interface 0 (SCI0).

# 2.3.57 PT[7:0] / IOC[7:0] — Port T I/O Pins [7:0]

PT7-PT0 are general purpose input or output pins. They can be configured as input capture or output compare pins IOC7-IOC0 of the Enhanced Capture Timer (ECT).

# 2.4 Power Supply Pins

MC9S12DT128 power and ground pins are described below.

Table 2-2 MC9S12DT128 Power and Ground Connection Summary

Mnemonic	Pin Number 112-pin QFP	Nominal Voltage	Description						
VDD1, 2	13, 65	2.5V	Internal power and ground generated by internal regulator						
VSS1, 2	14, 66	0V	Titlernal power and ground generated by internal regulator						

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Mnemonic	Pin Number	Nominal	Description
Willellionic	112-pin QFP	Voltage	Description
VDDR	41	5.0V	External power and ground, supply to pin drivers and internal
VSSR	40	0V	voltage regulator.
VDDX	107	5.0V	External power and ground, supply to pin drivers.
VSSX	106	0V	External power and ground, supply to pill drivers.
VDDA	83	5.0V	Operating voltage and ground for the analog-to-digital
VSSA	86	0V	converters and the reference for the internal voltage regulator, allows the supply voltage to the A/D to be bypassed independently.
VRL	85	0V	Reference voltages for the analog-to-digital converter.
VRH	84	5.0V	Neierence voltages for the analog-to-digital converter.
VDDPLL	43	2.5V	Provides operating voltage and ground for the Phased-Locked
VSSPLL 45 0V		0V	Loop. This allows the supply voltage to the PLL to be bypassed independently. Internal power and ground generated by internal regulator.
VREGEN	97	5V	Internal Voltage Regulator enable/disable

**NOTE:** All VSS pins must be connected together in the application.

#### 2.4.1 VDDX, VSSX — Power & Ground Pins for I/O Drivers

External power and ground for I/O drivers. Because fast signal transitions place high, short-duration current demands on the power supply, use bypass capacitors with high-frequency characteristics and place them as close to the MCU as possible. Bypass requirements depend on how heavily the MCU pins are loaded.

# 2.4.2 VDDR, VSSR — Power & Ground Pins for I/O Drivers & for Internal Voltage Regulator

External power and ground for I/O drivers and input to the internal voltage regulator. Because fast signal transitions place high, short-duration current demands on the power supply, use bypass capacitors with high-frequency characteristics and place them as close to the MCU as possible. Bypass requirements depend on how heavily the MCU pins are loaded.

## 2.4.3 VDD1, VDD2, VSS1, VSS2 — Internal Logic Power Supply Pins

Power is supplied to the MCU through VDD and VSS. Because fast signal transitions place high, short-duration current demands on the power supply, use bypass capacitors with high-frequency characteristics and place them as close to the MCU as possible. This 2.5V supply is derived from the internal voltage regulator. There is no static load on those pins allowed. The internal voltage regulator is turned off, if VREGEN is tied to ground.

**NOTE:** No load allowed except for bypass capacitors.

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#### 2.4.4 VDDA, VSSA — Power Supply Pins for ATD and VREG

VDDA, VSSA are the power supply and ground input pins for the voltage regulator and the analog to digital converter. It also provides the reference for the internal voltage regulator. This allows the supply voltage to the ATD and the reference voltage to be bypassed independently.

#### 2.4.5 VRH, VRL — ATD Reference Voltage Input Pins

VRH and VRL are the reference voltage input pins for the analog to digital converter.

#### 2.4.6 VDDPLL, VSSPLL — Power Supply Pins for PLL

Provides operating voltage and ground for the Oscillator and the Phased-Locked Loop. This allows the supply voltage to the Oscillator and PLL to be bypassed independently. This 2.5V voltage is generated by the internal voltage regulator.

**NOTE:** No load allowed except for bypass capacitors.

#### 2.4.7 VREGEN — On Chip Voltage Regulator Enable

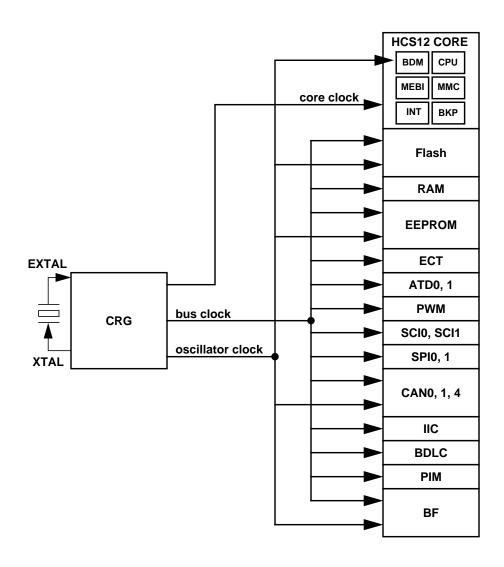
Enables the internal 5V to 2.5V voltage regulator. If this pin is tied low, VDD1,2 and VDDPLL must be supplied externally.

# **Section 3 System Clock Description**

#### 3.1 Overview

The Clock and Reset Generator provides the internal clock signals for the core and all peripheral modules. **Figure 3-1** shows the clock connections from the CRG to all modules.

Consult the CRG Block User Guide for details on clock generation.



**Figure 3-1 Clock Connections** 

## **Section 4 Modes of Operation**

#### 4.1 Overview

Eight possible modes determine the operating configuration of the MC9S12DT128. Each mode has an associated default memory map and external bus configuration controlled by a further pin.

Three low power modes exist for the device.

## 4.2 Chip Configuration Summary

The operating mode out of reset is determined by the states of the MODC, MODB, and MODA pins during reset (**Table 4-1**). The MODC, MODB, and MODA bits in the MODE register show the current operating mode and provide limited mode switching during operation. The states of the MODC, MODB, and MODA pins are latched into these bits on the rising edge of the reset signal. The ROMCTL signal allows the setting of the ROMON bit in the MISC register thus controlling whether the internal Flash is visible in the memory map. ROMON = 1 mean the Flash is visible in the memory map. The state of the ROMCTL pin is latched into the ROMON bit in the MISC register on the rising edge of the reset signal.

**Table 4-1 Mode Selection** 

BKGD = MODC	PE6 = MODB	PE5 = MODA	PK7 = ROMCTL	ROMON Bit	Mode Description
0	0	0	х	1	Special Single Chip, BDM allowed and ACTIVE. BDM is allowed in all other modes but a serial command is required to make BDM active.
0	0	1	0	1	Emulation Expanded Narrow PDM allowed
	U	'	1	0	- Emulation Expanded Narrow, BDM allowed
0	1	0	Х	0	Special Test (Expanded Wide), BDM allowed
0	1	1	0	1	Emulation Expanded Wide PDM allowed
	ı	'	1	0	- Emulation Expanded Wide, BDM allowed
1	0	0	Х	1	Normal Single Chip, BDM allowed
4	0	4	0	0	Normal Evpanded Norrow, DDM allowed
'	U	1	1	1	Normal Expanded Narrow, BDM allowed
1	1	0	Х	1	Special Peripheral; BDM allowed but bus operations would cause bus conflicts (must not be used)
1	1	1	0	0	Normal Expanded Wide, BDM allowed
		<b>!</b>	1	1	TNOTHAL Expanded Wide, DDIVI allowed

For further explanation on the modes refer to the HCS12 Multiplexed External Bus Interface Block Guide.

Table 4-2 Clock Selection Based on PE7

PE7 = XCLKS	Description
1	Colpitts Oscillator selected
0	Pierce Oscillator/external clock selected

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Table 4-3 Voltage Regulator VREGEN

VREGEN	Description			
1	Internal Voltage Regulator enabled			
0	Internal Voltage Regulator disabled, VDD1,2 and VDDPLL must be supplied externally with 2.5V			

## 4.3 Security

The device will make available a security feature preventing the unauthorized read and write of the memory contents. This feature allows:

- Protection of the contents of FLASH,
- Protection of the contents of EEPROM,
- Operation in single-chip mode, No BDM possible
- Operation from external memory with internal FLASH and EEPROM disabled.

The user must be reminded that part of the security must lie with the user's code. An extreme example would be user's code that dumps the contents of the internal program. This code would defeat the purpose of security. At the same time the user may also wish to put a back door in the user's program. An example of this is the user downloads a key through the SCI which allows access to a programming routine that updates parameters stored in EEPROM.

#### 4.3.1 Securing the Microcontroller

Once the user has programmed the FLASH and EEPROM (if desired), the part can be secured by programming the security bits located in the FLASH module. These non-volatile bits will keep the part secured through resetting the part and through powering down the part.

The security byte resides in a portion of the Flash array.

Check the Flash Block User Guide for more details on the security configuration.

## 4.3.2 Operation of the Secured Microcontroller

#### 4.3.2.1 Normal Single Chip Mode

This will be the most common usage of the secured part. Everything will appear the same as if the part was not secured with the exception of BDM operation. The BDM operation will be blocked.

#### 4.3.2.2 Executing from External Memory

The user may wish to execute from external space with a secured microcontroller. This is accomplished by resetting directly into expanded mode. The internal FLASH and EEPROM will be disabled. BDM operations will be blocked.

#### 4.3.3 Unsecuring the Microcontroller

In order to unsecure the microcontroller, the internal FLASH and EEPROM must be erased. This can be done through an external program in expanded mode or via a .sequence of BDM commands. Unsecuring is also possible via the Backdoor Key Access. Refer to Flash Block Guide for details.

Once the user has erased the FLASH and EEPROM, the part can be reset into special single chip mode. This invokes a program that verifies the erasure of the internal FLASH and EEPROM. Once this program completes, the user can erase and program the FLASH security bits to the unsecured state. This is generally done through the BDM, but the user could also change to expanded mode (by writing the mode bits through the BDM) and jumping to an external program (again through BDM commands). Note that if the part goes through a reset before the security bits are reprogrammed to the unsecure state, the part will be secured again.

#### 4.4 Low Power Modes

The microcontroller features three main low power modes. Consult the respective Block User Guide for information on the module behavior in Stop, Pseudo Stop, and Wait Mode. An important source of information about the clock system is the Clock and Reset Generator User Guide (CRG).

#### 4.4.1 Stop

Executing the CPU STOP instruction stops all clocks and the oscillator thus putting the chip in fully static mode. Wake up from this mode can be done via reset or external interrupts.

#### 4.4.2 Pseudo Stop

This mode is entered by executing the CPU STOP instruction. In this mode the oscillator is still running and the Real Time Interrupt (RTI) or Watchdog (COP) sub module can stay active. Other peripherals are turned off. This mode consumes more current than the full STOP mode, but the wake up time from this mode is significantly shorter.

#### 4.4.3 Wait

This mode is entered by executing the CPU WAI instruction. In this mode the CPU will not execute instructions. The internal CPU signals (address and databus) will be fully static. All peripherals stay active. For further power consumption the peripherals can individually turn off their local clocks.

#### 4.4.4 Run

Although this is not a low power mode, unused peripheral modules should not be enabled in order to save power.

# **Section 5 Resets and Interrupts**

#### 5.1 Overview

Consult the Exception Processing section of the CPU Reference Manual for information on resets and interrupts.

#### 5.2 Vectors

#### 5.2.1 Vector Table

**Table 5-1** lists interrupt sources and vectors in default order of priority.

**Table 5-1 Interrupt Vector Locations** 

Vector Address	Interrupt Source	CCR	Local Enable	HPRIO Value
vector Address	interrupt Source	Mask	Local Enable	to Elevate
\$FFFE, \$FFFF	Reset	None	None	_
\$FFFC, \$FFFD	Clock Monitor fail reset	None	COPCTL (CME, FCME)	-
\$FFFA, \$FFFB	COP failure reset	None	COP rate select	-
\$FFF8, \$FFF9	Unimplemented instruction trap	None	None	-
\$FFF6, \$FFF7	SWI	None	None	-
\$FFF4, \$FFF5	XIRQ / BF High Priority Sync Pulse	X-Bit	None / BFRIER (XSYNIE)	_
\$FFF2, \$FFF3	IRQ	I-Bit	INTCR (IRQEN)	\$F2
\$FFF0, \$FFF1	Real Time Interrupt	I-Bit	CRGINT (RTIE)	\$F0
\$FFEE, \$FFEF	Enhanced Capture Timer channel 0	I-Bit	TIE (C0I)	\$EE
\$FFEC, \$FFED	Enhanced Capture Timer channel 1	I-Bit	TIE (C1I)	\$EC
\$FFEA, \$FFEB	Enhanced Capture Timer channel 2	I-Bit	TIE (C2I)	\$EA
\$FFE8, \$FFE9	Enhanced Capture Timer channel 3	I-Bit	TIE (C3I)	\$E8
\$FFE6, \$FFE7	Enhanced Capture Timer channel 4	I-Bit	TIE (C4I)	\$E6
\$FFE4, \$FFE5	Enhanced Capture Timer channel 5	I-Bit	TIE (C5I)	\$E4
\$FFE2, \$FFE3	Enhanced Capture Timer channel 6	I-Bit	TIE (C6I)	\$E2
\$FFE0, \$FFE1	Enhanced Capture Timer channel 7	I-Bit	TIE (C7I)	\$E0
\$FFDE, \$FFDF	Enhanced Capture Timer overflow	I-Bit	TSCR2 (TOF)	\$DE
\$FFDC, \$FFDD	Pulse accumulator A overflow	I-Bit	PACTL (PAOVI)	\$DC
\$FFDA, \$FFDB	Pulse accumulator input edge	I-Bit	PACTL (PAI)	\$DA
\$FFD8, \$FFD9	SPI0	I-Bit	SPICR1 (SPIE, SPTIE)	\$D8
\$FFD6, \$FFD7	SCI0	I-Bit	SCICR2 (TIE, TCIE, RIE, ILIE)	\$D6
\$FFD4, \$FFD5	SCI1	I-Bit	SCICR2 (TIE, TCIE, RIE, ILIE)	\$D4
\$FFD2, \$FFD3	ATD0	I-Bit	ATDCTL2 (ASCIE)	\$D2
\$FFD0, \$FFD1	ATD1	I-Bit	ATDCTL2 (ASCIE)	\$D0
\$FFCE, \$FFCF	Port J	I-Bit	PIEJ (PIEJ7, PIEJ6, PIEJ1, PIEJ0)	\$CE
\$FFCC, \$FFCD	Port H	I-Bit	PIEH (PIEH7-0)	\$CC

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\$FFCA, \$FFCB	Modulus Down Counter underflow	I-Bit	MCCTL (MCZI)	\$CA
\$FFC8, \$FFC9	Pulse Accumulator B Overflow	I-Bit	PBCTL (PBOVI)	\$C8
\$FFC6, \$FFC7	CRG PLL lock	I-Bit	PLLCR (LOCKIE)	\$C6
\$FFC4, \$FFC5	CRG Self Clock Mode	I-Bit	PLLCR (SCMIE)	\$C4
\$FFC2, \$FFC3	BDLC	I-Bit	DLCBCR1 (IE)	\$C2
\$FFC0, \$FFC1	IIC Bus	I-Bit	IBCR (IBIE)	\$C0
\$FFBE, \$FFBF	SPI1	I-Bit	SPICR1 (SPIE, SPTIE)	\$BE
\$FFBC, \$FFBD		Rese	erved	
\$FFBA, \$FFBB	EEPROM	I-Bit	ECNFG (CCIE, CBEIE)	\$BA
\$FFB8, \$FFB9	FLASH	I-Bit	FCNFG (CCIE, CBEIE)	\$B8
\$FFB6, \$FFB7	CAN0 wake-up	I-Bit	CANRIER (WUPIE)	\$B6
\$FFB4, \$FFB5	CAN0 errors	I-Bit	CANRIER (CSCIE, OVRIE)	\$B4
\$FFB2, \$FFB3	CAN0 receive	I-Bit	CANRIER (RXFIE)	\$B2
\$FFB0, \$FFB1	CAN0 transmit	I-Bit	CANTIER (TXEIE[2:0])	\$B0
\$FFAE, \$FFAF	CAN1 wake-up	I-Bit	CANRIER (WUPIE)	\$AE
\$FFAC, \$FFAD	CAN1 errors	I-Bit	CANRIER (CSCIE, OVRIE)	\$AC
\$FFAA, \$FFAB	CAN1 receive	I-Bit	CANRIER (RXFIE)	\$AA
\$FFA8, \$FFA9	CAN1 transmit	I-Bit	CANTIER (TXEIE[2:0])	\$A8
\$FFA6, \$FFA7	BF Receive FIFO not empty	I-Bit	BFRIER (RCVFIE)	\$A6
\$FFA4, \$FFA5	BF receive	I-Bit	BFBUFCTL[15:0] (IENA)	\$A4
\$FFA2, \$FFA3	BF Synchronization	I-Bit	BFRIER (SYNAIE, SYNNIE)	\$A2
\$FFA0, \$FFA1	BF general	I-Bit	BFBUFCTL[15:0] (IENA), BFGIER (OVRNIE, ERRIE, SYNEIE, SYNLIE, ILLPIE, LOCKIE, WAKEIE) BFRIER (SLMMIE)	\$A0
\$FF98, \$FF9F		Rese	erved	
\$FF96, \$FF97	CAN4 wake-up	I-Bit	CANRIER (WUPIE)	\$96
\$FF94, \$FF95	CAN4 errors	I-Bit	CANRIER (CSCIE, OVRIE)	\$94
\$FF92, \$FF93	CAN4 receive	I-Bit	CANRIER (RXFIE)	\$92
\$FF90, \$FF91	CAN4 transmit	I-Bit	CANTIER (TXEIE[2:0])	\$90
\$FF8E, \$FF8F	Port P Interrupt	I-Bit	PIEP (PIEP7-0)	\$8E
\$FF8C, \$FF8D	PWM Emergency Shutdown	I-Bit	PWMSDN (PWMIE)	\$8C
\$FF80 to \$FF8B		Rese	erved	

#### 5.3 Effects of Reset

When a reset occurs, MCU registers and control bits are changed to known start-up states. Refer to the respective module Block User Guides for register reset states.

#### 5.3.1 I/O pins

Refer to the HCS12 Multiplexed External Bus Interface (MEBI) Block Guide for mode dependent pin configuration of port A, B, E and K out of reset.

Refer to the PIM Block User Guide for reset configurations of all peripheral module ports.



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**NOTE:** 

For devices assembled in 80-pin QFP packages all non-bonded out pins should be configured as outputs after reset in order to avoid current drawn from floating inputs. Refer to **Table 2-1** for affected pins.

#### **5.3.2 Memory**

Refer to **Table 1-1** for locations of the memories depending on the operating mode after reset.

The RAM array is not automatically initialized out of reset.

## **Section 6 HCS12 Core Block Description**

## 6.1 CPU Block Description

Consult the CPU Reference Manual for information on the CPU.

#### 6.1.1 Device-specific information

When the CPU Reference Manual refers to cycles this is equivalent to Bus Clock periods. So 1 cycle is equivalent to 1 Bus Clock period.

## 6.2 HCS12 Module Mapping Control (MMC) Block Description

Consult the MMC Block Guide for information on the HCS12 Module Mapping Control module.

#### 6.2.1 Device-specific information

- INITEE
  - Reset state: \$01
  - Bits EE11-EE15 are "Write once in Normal and Emulation modes and write anytime in Special modes".
- PPAGE
  - Reset state: \$00
  - Register is "Write anytime in all modes".
- MEMSIZ0
  - Reset state: \$13
- MEMSIZ1
  - Reset state: \$80

# 6.3 HCS12 Multiplexed External Bus Interface (MEBI) Block Description

Consult the MEBI Block Guide for information on HCS12 Multiplexed External Bus Interface module.

## 6.3.1 Device-specific information

- PUCR
  - Reset state: \$90

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## 6.4 HCS12 Interrupt (INT) Block Description

Consult the INT Block Guide for information on the HCS12 Interrupt module.

## 6.5 HCS12 Background Debug Module (BDM) Block Description

Consult the BDM Block Guide for information on the HCS12 Background Debug module.

#### 6.5.1 Device-specific information

When the BDM Block Guide refers to *alternate clock* this is equivalent to *oscillator clock*.

## 6.6 HCS12 Breakpoint (BKP) Block Description

Consult the BKP Block Guide for information on the HCS12 Breakpoint module.

# Section 7 Clock and Reset Generator (CRG) Block Description

Consult the CRG Block User Guide for information about the Clock and Reset Generator module.

## 7.1 Device-specific information

The Low Voltage Reset feature of the CRG is not available on this device.

# Section 8 Oscillator (OSC) Block Description

Consult the OSC Block User Guide for information about the Oscillator module.

## 8.1 Device-specific information

The  $\overline{XCLKS}$  input signal is active low (see 2.3.12 PE / NOACC /  $\overline{XCLKS}$  — Port E I/O Pin 7).

# **Section 9 Enhanced Capture Timer (ECT) Block Description**

Consult the ECT\_16B8C Block User Guide for information about the Enhanced Capture Timer module. When the ECT\_16B8C Block User Guide refers to *freeze mode* this is equivalent to *active BDM mode*.

# Section 10 Analog to Digital Converter (ATD) Block Description

There are two Analog to Digital Converters (ATD1 and ATD0) implemented on the MC9S12DT128. Consult the ATD\_10B8C Block User Guide for information about each Analog to Digital Converter module. When the ATD\_10B8C Block User Guide refers to *freeze mode* this is equivalent to *active BDM mode*.

## Section 11 Inter-IC Bus (IIC) Block Description

Consult the IIC Block User Guide for information about the Inter-IC Bus module.

# Section 12 Serial Communications Interface (SCI) Block Description

There are two Serial Communications Interfaces (SCI1 and SCI0) implemented on the MC9S12DT128 device. Consult the SCI Block User Guide for information about each Serial Communications Interface module.

# Section 13 Serial Peripheral Interface (SPI) Block Description

There are two Serial Peripheral Interfaces (SPI1 and SPI0) implemented on MC9S12DT128. Consult the SPI Block User Guide for information about each Serial Peripheral Interface module.

# Section 14 J1850 (BDLC) Block Description

Consult the BDLC Block User Guide for information about the J1850 module.

# Section 15 Byteflight (BF) Block Description

Consult the BF Block User Guide for information about the 10 Mbps Byteflight module.

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## 15.1 Device-specific information

The read-only Module Version Register (BFMVR) contains the current version number of \$80.

# Section 16 Pulse Width Modulator (PWM) Block Description

Consult the PWM\_8B8C Block User Guide for information about the Pulse Width Modulator module. When the PWM\_8B8C Block User Guide refers to *freeze mode* this is equivalent to *active BDM mode*.

# Section 17 Flash EEPROM 128K Block Description

Consult the FTS128K Block User Guide for information about the flash module.

The "S12 LRAE" is a generic Load RAM and Execute (LRAE) program which will be programmed into the flash memory of this device during manufacture. This LRAE program will provide greater programming flexibility to the end users by allowing the device to be programmed directly using CAN or SCI after it is assembled on the PCB. Use of the LRAE program is at the discretion of the end user and, if not required, it must simply be erased prior to flash programming. For more details of the S12 LRAE and its implementation, please see the S12 LREA Application Note (AN2546/D).

It is planned that most HC9S12 devices manufactured after Q1 of 2004 will be shipped with the S12 LRAE programmed in the Flash . Exact details of the changeover (ie blank to programmed) for each product will be communicated in advance via GPCN and will be traceable by the customer via datecode marking on the device.

Please contact Motorola SPS Sales if you have any additional questions.

## **Section 18 EEPROM 2K Block Description**

Consult the EETS2K Block User Guide for information about the EEPROM module.

# **Section 19 RAM Block Description**

This module supports single-cycle misaligned word accesses without wait states.

## **Section 20 MSCAN Block Description**

There are three MSCAN modules (CAN4, CAN1 and CAN0) implemented on the MC9S12DT128. Consult the MSCAN Block User Guide for information about the Motorola Scalable CAN Module.



# Section 21 Port Integration Module (PIM) Block Description

Consult the PIM\_9DTB128 Block User Guide for information about the Port Integration Module.

# Section 22 Voltage Regulator (VREG) Block Description

Consult the VREG Block User Guide for information about the dual output linear voltage regulator.

## Section 23 Printed Circuit Board Layout Proposal

**Table 23-1 Suggested External Component Values** 

Component	Purpose	Туре	Value	
C1	VDD1 filter cap	ceramic X7R	100 220nF	
C2	VDD2 filter cap	ceramic X7R	100 220nF	
СЗ	VDDA filter cap	ceramic X7R	100nF	
C4	VDDR filter cap	X7R/tantalum	>= 100nF	
C5	VDDPLL filter cap	ceramic X7R	100nF	
C6	VDDX filter cap	X7R/tantalum	>= 100nF	
C7	OSC load cap			
C8	OSC load cap			
C9 / C <sub>S</sub>	PLL loop filter cap	Soo DLL angai	fination chapter	
C10 / C <sub>P</sub>	PLL loop filter cap	See FLL speci	fication chapter	
C11 / C <sub>DC</sub>	DC cutoff cap		if recommended by nufacturer	
R1 / R	PLL loop filter res	See PLL Speci	fication chapter	
R2 / R <sub>B</sub>		· · · · · · · · · · · · · · · · · · ·		
R3 / R <sub>S</sub>		Pierce mode only		
Q1	Quartz			

The PCB must be carefully laid out to ensure proper operation of the voltage regulator as well as of the MCU itself. The following rules must be observed:

- Every supply pair must be decoupled by a ceramic capacitor connected as near as possible to the corresponding pins (C1 C6).
- Central point of the ground star should be the VSSR pin.

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- Use low ohmic low inductance connections between VSS1, VSS2 and VSSR.
- VSSPLL must be directly connected to VSSR.
- Keep traces of VSSPLL, EXTAL and XTAL as short as possible and occupied board area for C7, C8, C11 and Q1 as small as possible.
- Do not place other signals or supplies underneath area occupied by C7, C8, C10 and Q1 and the connection area to the MCU.
- Central power input should be fed in at the VDDA/VSSA pins.

Figure 23-1 Recommended PCB Layout for 112LQFP Colpitts Oscillator

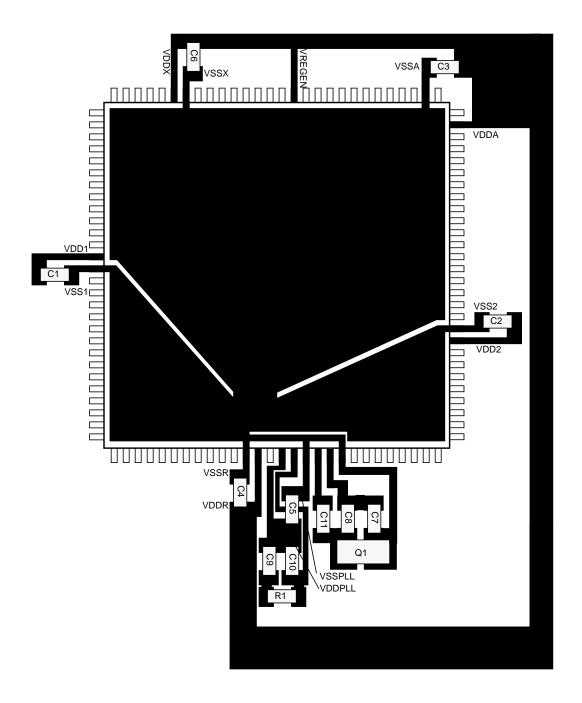
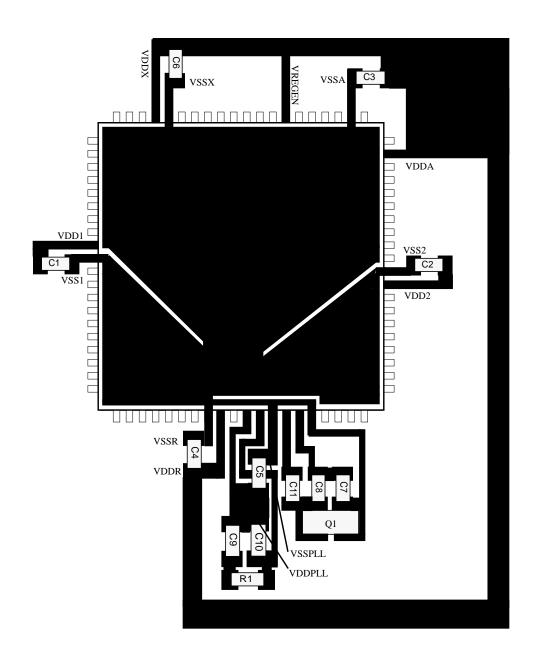


Figure 23-2 Recommended PCB Layout for 80QFP (MC9S12DG128E, MC9S12DG128, MC9S12DJ128E, MC9S12DJ128, MC9S12A128, SC515847, and SC515848) Colpitts
Oscillator



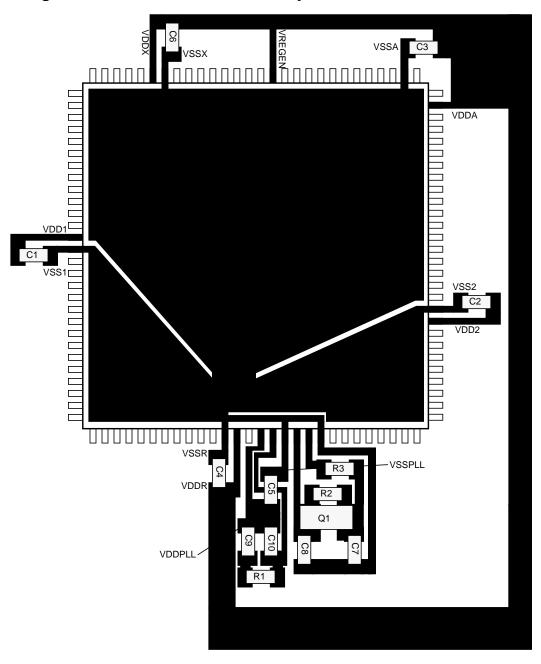


Figure 23-3 Recommended PCB Layout for 112LQFP Pierce Oscillator

Figure 23-4 Recommended PCB Layout for 80QFP (MC9S12DG128E, MC9S12DG128, MC9S12DJ128E, MC9S12DJ128, MC9S12A128, SC515847, and SC515848) Pierce Oscillator

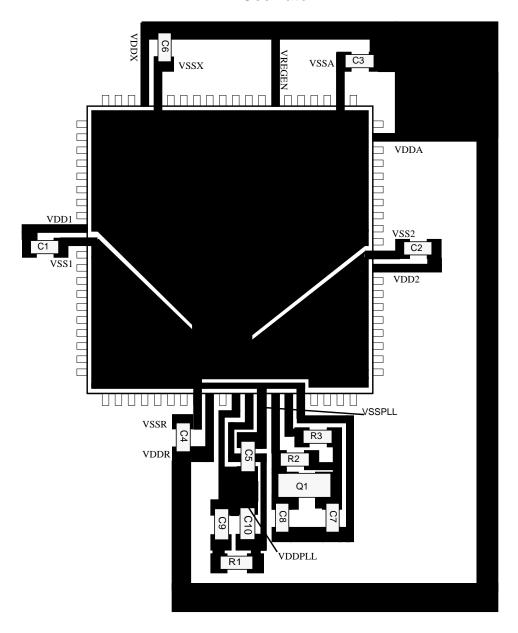
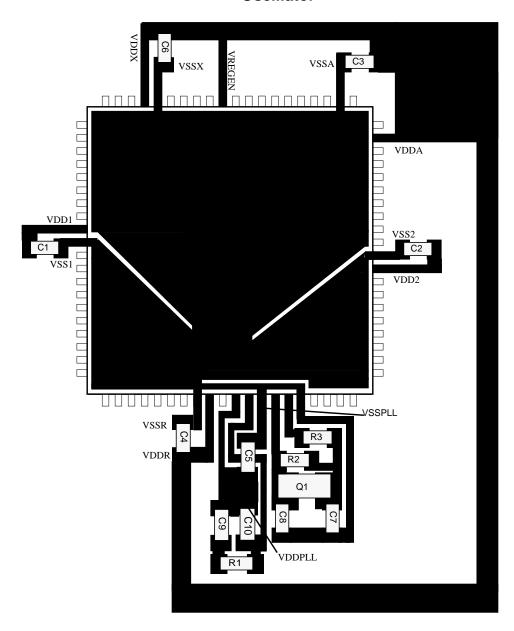


Figure 23-5 Recommended PCB Layout for 80QFP (MC9S12DB128 and SC515846) Pierce Oscillator



## **Appendix A Electrical Characteristics**

#### A.1 General

This introduction is intended to give an overview on several common topics like power supply, current injection etc.

#### A.1.1 Parameter Classification

The electrical parameters shown in this supplement are guaranteed by various methods. To give the customer a better understanding the following classification is used and the parameters are tagged accordingly in the tables where appropriate.

P:

Those parameters are guaranteed during production testing on each individual device.

C:

Those parameters are achieved by the design characterization by measuring a statistically relevant sample size across process variations. They are regularly verified by production monitors.

T:

Those parameters are achieved by design characterization on a small sample size from typical devices. All values shown in the typical column are within this category.

D:

Those parameters are derived mainly from simulations.

## A.1.2 Power Supply

The MC9S12DT128 utilizes several pins to supply power to the I/O ports, A/D converter, oscillator, PLL and internal logic.

The VDDA, VSSA pair supplies the A/D converter and the resistor ladder of the internal voltage regulator.

The VDDX, VSSX, VDDR and VSSR pairs supply the I/O pins, VDDR supplies also the internal voltage regulator.

VDD1, VSS1, VDD2 and VSS2 are the supply pins for the digital logic, VDDPLL, VSSPLL supply the oscillator and the PLL.

VSS1 and VSS2 are internally connected by metal.

VDDA, VDDX, VDDR as well as VSSA, VSSX, VSSR are connected by anti-parallel diodes for ESD protection.

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**NOTE:** 

In the following context VDD5 is used for either VDDA, VDDR and VDDX; VSS5 is used for either VSSA, VSSR and VSSX unless otherwise noted.

IDD5 denotes the sum of the currents flowing into the VDDA, VDDX and VDDR

pins.

VDD is used for VDD1, VDD2 and VDDPLL, VSS is used for VSS1, VSS2 and

VSSPLL.

IDD is used for the sum of the currents flowing into VDD1 and VDD2.

#### A.1.3 Pins

There are four groups of functional pins.

#### A.1.3.1 5V I/O pins

Those I/O pins have a nominal level of 5V. This class of pins is comprised of all port I/O pins, the analog inputs, BKGD pin and the RESET inputs. The internal structure of all those pins is identical, however some of the functionality may be disabled. E.g. for the analog inputs the output drivers, pull-up and pull-down resistors are disabled permanently.

#### A.1.3.2 Analog Reference

This class is made up by the two VRH and VRL pins.

#### A.1.3.3 Oscillator

The pins XFC, EXTAL, XTAL dedicated to the oscillator have a nominal 2.5V level. They are supplied by VDDPLL.

#### A.1.3.4 TEST

This pin is used for production testing only.

#### **A.1.3.5 VREGEN**

This pin is used to enable the on chip voltage regulator.

## A.1.4 Current Injection

Power supply must maintain regulation within operating  $V_{DD5}$  or  $V_{DD}$  range during instantaneous and operating maximum current conditions. If positive injection current ( $V_{in} > V_{DD5}$ ) is greater than  $I_{DD5}$ , the injection current may flow out of VDD5 and could result in external power supply going out of regulation. Insure external VDD5 load will shunt current greater than maximum injection current. This will be the greatest risk when the MCU is not consuming power; e.g. if no system clock is present, or if clock rate is very low which would reduce overall power consumption.

#### A.1.5 Absolute Maximum Ratings

Absolute maximum ratings are stress ratings only. A functional operation under or outside those maxima is not guaranteed. Stress beyond those limits may affect the reliability or cause permanent damage of the device.

This device contains circuitry protecting against damage due to high static voltage or electrical fields; however, it is advised that normal precautions be taken to avoid application of any voltages higher than maximum-rated voltages to this high-impedance circuit. Reliability of operation is enhanced if unused inputs are tied to an appropriate logic voltage level (e.g., either V<sub>SS5</sub> or V<sub>DD5</sub>).

Table A-1 Absolute Maximum Ratings<sup>1</sup>

Num	Rating	Symbol	Min	Max	Unit
1	I/O, Regulator and Analog Supply Voltage	V <sub>DD5</sub>	-0.3	6.0	V
2	Digital Logic Supply Voltage <sup>2</sup>	V <sub>DD</sub>	-0.3	3.0	V
3	PLL Supply Voltage <sup>2</sup>	V <sub>DDPLL</sub>	-0.3	3.0	V
4	Voltage difference VDDX to VDDR and VDDA	$\Delta_{VDDX}$	-0.3	0.3	V
5	Voltage difference VSSX to VSSR and VSSA	$\Delta_{VSSX}$	-0.3	0.3	V
6	Digital I/O Input Voltage	V <sub>IN</sub>	-0.3	6.0	V
7	Analog Reference	$V_{RH,}V_{RL}$	-0.3	6.0	V
8	XFC, EXTAL, XTAL inputs	V <sub>ILV</sub>	-0.3	3.0	V
9	TEST input	V <sub>TEST</sub>	-0.3	10.0	V
10	Instantaneous Maximum Current Single pin limit for all digital I/O pins <sup>3</sup>	I <sub>D</sub>	-25	+25	mA
11	Instantaneous Maximum Current Single pin limit for XFC, EXTAL, XTAL <sup>4</sup>	I <sub>DL</sub>	-25	+25	mA
12	Instantaneous Maximum Current Single pin limit for TEST <sup>5</sup>	I <sub>DT</sub>	-0.25	0	mA
13	Storage Temperature Range	T <sub>stg</sub>	<b>– 65</b>	155	°C

- 1. Beyond absolute maximum ratings device might be damaged.
- 2. The device contains an internal voltage regulator to generate the logic and PLL supply out of the I/O supply. The absolute maximum ratings apply when the device is powered from an external source.
- 3. All digital I/O pins are internally clamped to  $V_{SSX}$  and  $V_{DDX}$ ,  $V_{SSR}$  and  $V_{DDR}$  or  $V_{SSA}$  and  $V_{DDA}$ .
- 4. Those pins are internally clamped to V<sub>SSPLL</sub> and V<sub>DDPLL</sub>.
  5. This pin is clamped low to V<sub>SSX</sub>, but not clamped high. This pin must be tied low in applications.

## A.1.6 ESD Protection and Latch-up Immunity

All ESD testing is in conformity with CDF-AEC-Q100 Stress test qualification for Automotive Grade Integrated Circuits. During the device qualification ESD stresses were performed for the Human Body Model (HBM), the Machine Model (MM) and the Charge Device Model.



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A device will be defined as a failure if after exposure to ESD pulses the device no longer meets the device specification. Complete DC parametric and functional testing is performed per the applicable device specification at room temperature followed by hot temperature, unless specified otherwise in the device specification.

Table A-2 ESD and Latch-up Test Conditions

Model	Description	Symbol	Value	Unit
	Series Resistance	R1	1500	Ohm
l	Storage Capacitance	Resistance       R1       1500       Ohm         e Capacitance       C       100       pF         r of Pulse per pin       -       -       3         e       Resistance       R1       0       Ohm         e Capacitance       C       200       pF         r of Pulse per pin       -       -       3         e       3       -       3         m input voltage limit       -2.5       V	pF	
Human Body	Number of Pulse per pin positive negative	_		
	Series Resistance	R1	0	Ohm
	Storage Capacitance	С	200	pF
Machine	Number of Pulse per pin positive negative	_	_	
Latab up	Minimum input voltage limit		-2.5	V
Latch-up	Maximum input voltage limit		7.5	V

Table A-3 ESD and Latch-Up Protection Characteristics

Num	С	Rating	Symbol	Min	Max	Unit
1	С	Human Body Model (HBM)	V <sub>HBM</sub>	2000	-	V
2	С	Machine Model (MM)	V <sub>MM</sub>	200	_	V
3	С	Charge Device Model (CDM)	V <sub>CDM</sub>	500	_	V
4	С	Latch-up Current at 125°C positive negative	I <sub>LAT</sub>	+100 -100	-	mA
5	С	Latch-up Current at 27°C positive negative	I <sub>LAT</sub>	+200 -200	_	mA

## A.1.7 Operating Conditions

This chapter describes the operating conditions of the device. Unless otherwise noted those conditions apply to all the following data.

**NOTE:** Please refer to the temperature rating of the device (C, V, M) with regards to the ambient temperature  $T_A$  and the junction temperature  $T_J$ . For power dissipation

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calculations refer to Section A.1.8 Power Dissipation and Thermal Characteristics.

**Table A-4 Operating Conditions** 

Rating	Symbol	Min	Тур	Max	Unit
I/O, Regulator and Analog Supply Voltage	$V_{DD5}$	4.5	5	5.25	V
Digital Logic Supply Voltage <sup>1</sup>	$V_{DD}$	2.35	2.5	2.75	V
PLL Supply Voltage <sup>1</sup>	V <sub>DDPLL</sub>	2.25	2.5	2.75	V
Voltage Difference VDDX to VDDR and VDDA	$\Delta_{VDDX}$	-0.1	0	0.1	V
Voltage Difference VSSX to VSSR and VSSA	$\Delta_{VSSX}$	-0.1	0	0.1	V
Oscillator	f <sub>osc</sub>	0.5	-	16	MHz
Bus Frequency	f <sub>bus</sub>	0.25 <sup>2</sup>	-	25	MHz
MC9S12DT128 <b>C</b>					
Operating Junction Temperature Range	$T_J$	-40	-	100	°C
Operating Ambient Temperature Range <sup>3</sup>	T <sub>A</sub>	-40	27	85	°C
MC9S12DT128 <b>V</b>					
Operating Junction Temperature Range	$T_J$	-40	-	120	°C
Operating Ambient Temperature Range <sup>3</sup>	T <sub>A</sub>	-40	27	105	°C
MC9S12DT128 <b>M</b>					
Operating Junction Temperature Range	$T_J$	-40	-	140	°C
Operating Ambient Temperature Range <sup>3</sup>	T <sub>A</sub>	-40	27	125	°C

#### NOTES:

- 1. The device contains an internal voltage regulator to generate the logic and PLL supply out of the I/O supply. The given operating range applies when this regulator is disabled and the device is powered from an external source.
- Some blocks e.g. ATD (conversion) and NVMs (program/erase) require higher bus frequencies for proper operation.
- 3. Please refer to **Section A.1.8 Power Dissipation and Thermal Characteristics** for more details about the relation between ambient temperature  $T_A$  and device junction temperature  $T_J$ .

## A.1.8 Power Dissipation and Thermal Characteristics

Power dissipation and thermal characteristics are closely related. The user must assure that the maximum operating junction temperature is not exceeded. The average chip-junction temperature ( $T_J$ ) in  ${}^{\circ}C$  can be obtained from:

$$\mathsf{T}_\mathsf{J} = \mathsf{T}_\mathsf{A} + (\mathsf{P}_\mathsf{D} \bullet \Theta_\mathsf{JA})$$

 $T_{,I}$  = Junction Temperature, [°C]

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 $T_{\Delta}$  = Ambient Temperature, [°C]

P<sub>D</sub> = Total Chip Power Dissipation, [W]

 $\Theta_{JA}$  = Package Thermal Resistance, [°C/W]

The total power dissipation can be calculated from:

$$P_D = P_{INT} + P_{IO}$$

P<sub>INIT</sub> = Chip Internal Power Dissipation, [W]

Two cases with internal voltage regulator enabled and disabled must be considered:

1. Internal Voltage Regulator disabled

$$P_{INT} = I_{DD} \cdot V_{DD} + I_{DDPLL} \cdot V_{DDPLL} + I_{DDA} \cdot V_{DDA}$$

$$P_{IO} = \sum_{i} R_{DSON} \cdot I_{IO_{i}}^{2}$$

Which is the sum of all output currents on I/O ports associated with VDDX and VDDR.

For R<sub>DSON</sub> is valid:

$$R_{DSON} = \frac{V_{OL}}{I_{OL}}$$
; for outputs driven low

respectively

$$R_{DSON} = \frac{V_{DD5} - V_{OH}}{I_{OH}}$$
; for outputs driven high

2. Internal voltage regulator enabled

I<sub>DDR</sub> is the current shown in **Table A-7** and not the overall current flowing into VDDR, which additionally contains the current flowing into the external loads with output high.

$$P_{IO} = \sum_{i} R_{DSON} \cdot I_{IO_i}^2$$

Which is the sum of all output currents on I/O ports associated with VDDX and VDDR.

Table A-5 Thermal Package Characteristics<sup>1</sup>

Num	С	Rating	Symbol	Min	Тур	Max	Unit
1	Т	Thermal Resistance LQFP112, single sided PCB <sup>2</sup>	$\theta_{JA}$	_	_	54	°C/W
2	Т	Thermal Resistance LQFP112, double sided PCB with 2 internal planes <sup>3</sup>	$\theta_{\sf JA}$	-	_	41	°C/W
3	Т	Junction to Board LQFP112	$\theta_{\sf JB}$	_	_	31	°C/W
4	Т	Junction to Case LQFP112	$\theta_{\sf JC}$	_	_	11	°C/W
5	Т	Junction to Package Top LQFP112	$\Psi_{JT}$	_	_	2	°C/W
6	Т	Thermal Resistance QFP 80, single sided PCB	$\theta_{JA}$	_	_	51	°C/W
7	Т	Thermal Resistance QFP 80, double sided PCB with 2 internal planes	$\theta_{JA}$	-	-	41	°C/W
8	Т	Junction to Board QFP80	$\theta_{JB}$	_	_	27	°C/W
9	Т	Junction to Case QFP80	$\theta_{\sf JC}$	-	_	14	°C/W
10	Т	Junction to Package Top QFP80	$\Psi_{JT}$	_	_	3	°C/W

#### NOTES:

- 1. The values for thermal resistance are achieved by package simulations
- 2. PC Board according to EIA/JEDEC Standard 51-3
- 3. PC Board according to EIA/JEDEC Standard 51-7

#### A.1.9 I/O Characteristics

This section describes the characteristics of all 5V I/O pins. All parameters are not always applicable, e.g. not all pins feature pull up/down resistances.

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Table A-6 5V I/O Characteristics

Num	С	Rating	Symbol	Min	Тур	Max	Unit
1	Р	Input High Voltage	V <sub>IH</sub>	0.65*V <sub>DD5</sub>	_		V
	Т	Input High Voltage	V <sub>IH</sub>	-	-	V <sub>DD5</sub> + 0.3	
2	Р	Input Low Voltage	V <sub>IL</sub>	-	-	0.35*V <sub>DD5</sub>	V
	Т	Input Low Voltage	V <sub>IL</sub>	V <sub>SS5</sub> - 0.3	-	_	V
3	С	Input Hysteresis	V <sub>HYS</sub>		250		mV
4	Р	Input Leakage Current (pins in high ohmic input mode) $V_{in} = V_{DD5} \text{ or } V_{SS5}$	I <sub>in</sub>	-1.0	-	1.0	μΑ
5	СР	Output High Voltage (pins in output mode) Partial Drive $I_{OH} = -2.0 \text{mA}$ Full Drive $I_{OH} = -10.0 \text{mA}$	V <sub>OH</sub>	V <sub>DD5</sub> – 0.8	-	-	V
6	СР	Output Low Voltage (pins in output mode) Partial Drive $I_{OL} = +2.0mA$ Full Drive $I_{OL} = +10.0mA$	V <sub>OL</sub>	-	-	0.8	V
7	Р	Internal Pull Up Device Current, tested at V <sub>IL</sub> Max.	I <sub>PUL</sub>	-	_	-130	μΑ
8	С	Internal Pull Up Device Current, tested at V <sub>IH</sub> Min.	I <sub>PUH</sub>	-10	-	_	μА
9	Р	Internal Pull Down Device Current, tested at V <sub>IH</sub> Min.	I <sub>PDH</sub>	-	-	130	μА
10	С	Internal Pull Down Device Current, tested at V <sub>IL</sub> Max.	I <sub>PDL</sub>	10	-	_	μΑ
11	D	Input Capacitance	C <sub>in</sub>		6	_	pF
12	Т	Injection current <sup>1</sup> Single Pin limit Total Device Limit. Sum of all injected currents	I <sub>ICS</sub>	-2.5 -25	-	2.5 25	mA
13	Р	Port H, J, P Interrupt Input Pulse filtered <sup>2</sup>	t <sub>PULSE</sub>			3	μs
14	Р	Port H, J, P Interrupt Input Pulse passed <sup>2</sup>	t <sub>PULSE</sub>	10			μs

#### NOTES:

- 1. Refer to Section A.1.4 Current Injection, for more details
- 2. Parameter only applies in STOP or Pseudo STOP mode.

# A.1.10 Supply Currents

This section describes the current consumption characteristics of the device as well as the conditions for the measurements.

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#### A.1.10.1 Measurement Conditions

All measurements are without output loads. Unless otherwise noted the currents are measured in single chip mode, internal voltage regulator enabled and at 25MHz bus frequency using a 4MHz oscillator in Colpitts mode. Production testing is performed using a square wave signal at the EXTAL input.

#### A.1.10.2 Additional Remarks

In expanded modes the currents flowing in the system are highly dependent on the load at the address, data and control signals as well as on the duty cycle of those signals. No generally applicable numbers can be given. A very good estimate is to take the single chip currents and add the currents due to the external loads.

**Table A-7 Supply Current Characteristics** 

Condit	ions	s are shown in <b>Table A-4</b> unless otherwise noted					
Num	С	Rating	Symbol	Min	Тур	Max	Unit
1	Р	Run supply currents Single Chip, Internal regulator enabled	I <sub>DD5</sub>			55	mA
2	P P	Wait Supply current  All modules enabled, PLL on only RTI enabled <sup>1</sup>	I <sub>DDW</sub>			30 5	mA
3	CPCCPCPCP	Pseudo Stop Current (RTI and COP disabled) 1, 2 -40°C 27°C 70°C 85°C "C" Temp Option 100°C 105°C "V" Temp Option 120°C 125°C "M" Temp Option 140°C	I <sub>DDPS</sub>		370 400 450 550 600 650 800 850 1200	500 1600 2100 5000	μА
4	0000000	Pseudo Stop Current (RTI and COP enabled) 1, 2 -40°C 27°C 70°C 85°C 105°C 125°C 140°C	I <sub>DDPS</sub>		570 600 650 750 850 1200 1500		μА
5	CPCCPCPCP	Stop Current <sup>2</sup> -40°C  27°C  70°C  85°C  "C" Temp Option 100°C  105°C  "V" Temp Option 120°C  125°C  "M" Temp Option 140°C	I <sub>DDS</sub>		12 25 100 130 160 200 350 400 600	100 1200 1700 5000	μА

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#### NOTES:

- 1. PLL off, Oscillator in Colpitts Mode 2. At those low power dissipation levels  $T_{\rm J}$  =  $T_{\rm A}$  can be assumed

#### A.2 ATD Characteristics

This section describes the characteristics of the analog to digital converter.

#### A.2.1 ATD Operating Characteristics

The **Table A-8** shows conditions under which the ATD operates.

The following constraints exist to obtain full-scale, full range results:

 $V_{SSA} \le V_{RL} \le V_{IN} \le V_{RH} \le V_{DDA}$ . This constraint exists since the sample buffer amplifier can not drive beyond the power supply levels that it ties to. If the input level goes outside of this range it will effectively be clipped.

#### **Table A-8 ATD Operating Characteristics**

Condit	Conditions are shown in Table A-4 unless otherwise noted							
Num	С	Rating	Symbol	Min	Тур	Max	Unit	
1	D	Reference Potential Low High	V <sub>RL</sub> V <sub>RH</sub>	V <sub>SSA</sub> V <sub>DDA</sub> /2		V <sub>DDA</sub> /2 V <sub>DDA</sub>	V	
2	С	Differential Reference Voltage <sup>1</sup>	$V_{RH}-V_{RL}$	4.50	5.00	5.25	V	
3	D	ATD Clock Frequency	f <sub>ATDCLK</sub>	0.5		2.0	MHz	
4	D	ATD 10-Bit Conversion Period  Clock Cycles <sup>2</sup> Conv, Time at 2.0MHz ATD Clock f <sub>ATDCLK</sub>		14 7		28 14	Cycles μs	
5	D	ATD 8-Bit Conversion Period  Clock Cycles <sup>(2)</sup> Conv, Time at 2.0MHz ATD Clock f <sub>ATDCLK</sub>	N <sub>CONV8</sub> T <sub>CONV8</sub>	12 6		26 13	Cycles μs	
6	D	Stop Recovery Time (V <sub>DDA</sub> =5.0 Volts)	t <sub>SR</sub>			20	μs	
7	Р	Reference Supply current (Both ATD modules on)	I <sub>REF</sub>			0.75	mA	
8	Р	Reference Supply current (Only one ATD module on)	I <sub>REF</sub>			0.375	mA	

#### NOTES:

- 1. Full accuracy is not guaranteed when differential voltage is less than 4.50V
- The minimum time assumes a final sample period of 2 ATD clocks cycles while the maximum time assumes a final sample period of 16 ATD clocks.

## A.2.2 Factors influencing accuracy

Three factors – source resistance, source capacitance and current injection – have an influence on the accuracy of the ATD.

#### A.2.2.1 Source Resistance:

Due to the input pin leakage current as specified in **Table A-6** in conjunction with the source resistance there will be a voltage drop from the signal source to the ATD input. The maximum source resistance  $R_S$ 

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specifies results in an error of less than 1/2 LSB (2.5mV) at the maximum leakage current. If device or operating conditions are less than worst case or leakage-induced error is acceptable, larger values of source resistance is allowed.

#### A.2.2.2 Source capacitance

When sampling an additional internal capacitor is switched to the input. This can cause a voltage drop due to charge sharing with the external and the pin capacitance. For a maximum sampling error of the input voltage  $\leq$  1LSB, then the external filter capacitor,  $C_f \geq 1024 * (C_{INS} - C_{INN})$ .

#### A.2.2.3 Current injection

There are two cases to consider.

- 1. A current is injected into the channel being converted. The channel being stressed has conversion values of \$3FF (\$FF in 8-bit mode) for analog inputs greater than  $V_{RH}$  and \$000 for values less than  $V_{RL}$  unless the current is higher than specified as disruptive conditions.
- 2. Current is injected into pins in the neighborhood of the channel being converted. A portion of this current is picked up by the channel (coupling ratio K), This additional current impacts the accuracy of the conversion depending on the source resistance.
  The additional input voltage error on the converted channel can be calculated as V<sub>ERR</sub> = K \* R<sub>S</sub> \* I<sub>INJ</sub>, with I<sub>INJ</sub> being the sum of the currents injected into the two pins adjacent to the converted channel.

Table A-9 ATD Electrical Characteristics

Condit	Conditions are shown in <b>Table A-4</b> unless otherwise noted						
Num	С	Rating	Symbol	Min	Тур	Max	Unit
1	С	Max input Source Resistance	R <sub>S</sub>	-	-	1	ΚΩ
2	Т	Total Input Capacitance Non Sampling Sampling	C <sub>INN</sub> C <sub>INS</sub>			10 22	pF
3	С	Disruptive Analog Input Current	I <sub>NA</sub>	-2.5		2.5	mA
4	С	Coupling Ratio positive current injection	K <sub>p</sub>			10 <sup>-4</sup>	A/A
5	С	Coupling Ratio negative current injection	K <sub>n</sub>			10 <sup>-2</sup>	A/A

## A.2.3 ATD accuracy

**Table A-10** specifies the ATD conversion performance excluding any errors due to current injection, input capacitance and source resistance.

### **Table A-10 ATD Conversion Performance**

Conditions are shown in Table A-4 unless otherwise noted

V<sub>REF</sub> = V<sub>RH</sub> - V<sub>RL</sub> = 5.12V. Resulting to one 8 bit count = 20mV and one 10 bit count = 5mV

 $f_{ATDCIK} = 2.0MHz$ 

Num	С	Rating	Symbol	Min	Тур	Max	Unit
1	Р	10-Bit Resolution	LSB		5		mV
2	Р	10-Bit Differential Nonlinearity	DNL	-1		1	Counts
3	Р	10-Bit Integral Nonlinearity	INL	-2.5	±1.5	2.5	Counts
4	Р	10-Bit Absolute Error <sup>1</sup>	AE	-3	±2.0	3	Counts
5	Р	8-Bit Resolution	LSB		20		mV
6	Р	8-Bit Differential Nonlinearity	DNL	-0.5		0.5	Counts
7	Р	8-Bit Integral Nonlinearity	INL	-1.0	±0.5	1.0	Counts
8	Р	8-Bit Absolute Error <sup>(1)</sup>	AE	-1.5	±1.0	1.5	Counts

#### NOTES:

For the following definitions see also **Figure A-1**.

Differential Non-Linearity (DNL) is defined as the difference between two adjacent switching steps.

$$DNL(i) = \frac{V_i - V_{i-1}}{1LSB} - 1$$

The Integral Non-Linearity (INL) is defined as the sum of all DNLs:

$$INL(n) \, = \, \sum_{i \, = \, 1}^n DNL(i) \, = \, \frac{V_n - V_0}{1LSB} - n$$

<sup>1.</sup> These values include the quantization error which is inherently 1/2 count for any A/D converter.

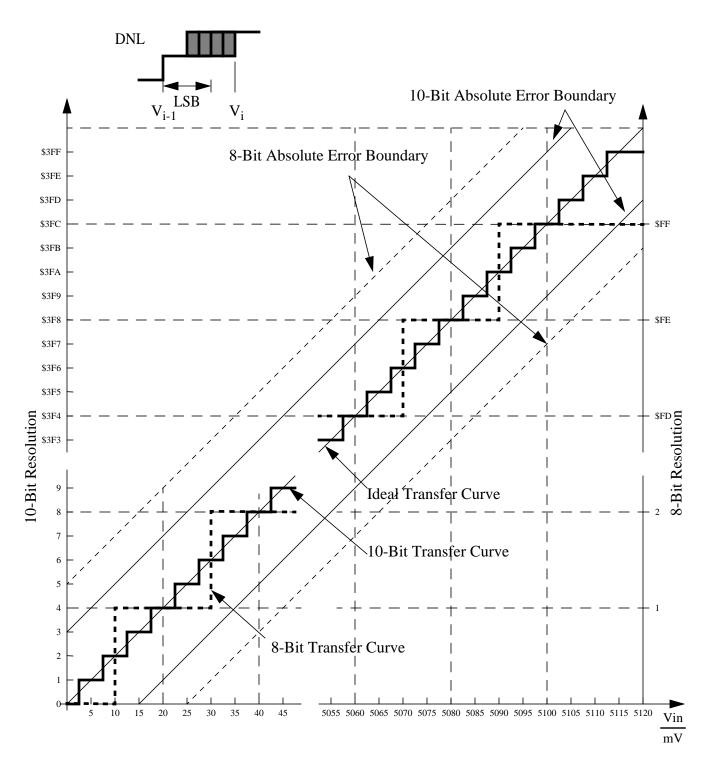


Figure A-1 ATD Accuracy Definitions

**NOTE:** Figure A-1 shows only definitions, for specification values refer to Table A-10.

## A.3 NVM, Flash and EEPROM

**NOTE:** Unless otherwise noted the abbreviation NVM (Non Volatile Memory) is used for both Flash and EEPROM.

## A.3.1 NVM timing

The time base for all NVM program or erase operations is derived from the oscillator. A minimum oscillator frequency f<sub>NVMOSC</sub> is required for performing program or erase operations. The NVM modules do not have any means to monitor the frequency and will not prevent program or erase operation at frequencies above or below the specified minimum. Attempting to program or erase the NVM modules at a lower frequency a full program or erase transition is not assured.

The Flash and EEPROM program and erase operations are timed using a clock derived from the oscillator using the FCLKDIV and ECLKDIV registers respectively. The frequency of this clock must be set within the limits specified as  $f_{NVMOP}$ .

The minimum program and erase times shown in **Table A-11** are calculated for maximum  $f_{NVMOP}$  and maximum  $f_{bus}$ . The maximum times are calculated for minimum  $f_{NVMOP}$  and a  $f_{bus}$  of 2MHz.

### A.3.1.1 Single Word Programming

The programming time for single word programming is dependant on the bus frequency as a well as on the frequency  $f_{NVMOP}$  and can be calculated according to the following formula.

$$t_{swpgm} = 9 \cdot \frac{1}{f_{NVMOP}} + 25 \cdot \frac{1}{f_{bus}}$$

## A.3.1.2 Row Programming

This applies only to the Flash where up to 32 words in a row can be programmed consecutively by keeping the command pipeline filled. The time to program a consecutive word can be calculated as:

$$t_{bwpgm} = 4 \cdot \frac{1}{f_{NVMOP}} + 9 \cdot \frac{1}{f_{bus}}$$

The time to program a whole row is:

$$t_{brpam} = t_{swpam} + 31 \cdot t_{bwpam}$$

Row programming is more than 2 times faster than single word programming.

### A.3.1.3 Sector Erase

Erasing a 512 byte Flash sector or a 4 byte EEPROM sector takes:

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$$t_{era} \approx 4000 \cdot \frac{1}{f_{NVMOP}}$$

The setup time can be ignored for this operation.

### A.3.1.4 Mass Erase

Erasing a NVM block takes:

$$t_{\text{mass}} \approx 20000 \cdot \frac{1}{f_{\text{NVMOP}}}$$

The setup time can be ignored for this operation.

#### A.3.1.5 Blank Check

The time it takes to perform a blank check on the Flash or EEPROM is dependant on the location of the first non-blank word starting at relative address zero. It takes one bus cycle per word to verify plus a setup of the command.

$$t_{check} \approx location \cdot t_{cyc} + 10 \cdot t_{cyc}$$

**Table A-11 NVM Timing Characteristics** 

Condit	ions	s are shown in <b>Table A-4</b> unless otherwise noted					
Num	С	Rating	Symbol	Min	Тур	Max	Unit
1	D	External Oscillator Clock	f <sub>NVMOSC</sub>	0.5		50 <sup>1</sup>	MHz
2	D	Bus frequency for Programming or Erase Operations	f <sub>NVMBUS</sub>	1			MHz
3	D	Operating Frequency	f <sub>NVMOP</sub>	150		200	kHz
4	Р	Single Word Programming Time	t <sub>swpgm</sub>	46 <sup>2</sup>		74.5 <sup>3</sup>	μs
5	D	Flash Row Programming consecutive word <sup>4</sup>	t <sub>bwpgm</sub>	20.4 <sup>2</sup>		31 <sup>3</sup>	μs
6	D	Flash Row Programming Time for 32 Words <sup>4</sup>	t <sub>brpgm</sub>	678.4 <sup>2</sup>		1035.5 <sup>3</sup>	μs
7	Р	Sector Erase Time	t <sub>era</sub>	20 <sup>5</sup>		26.7 <sup>3</sup>	ms
8	Р	Mass Erase Time	t <sub>mass</sub>	100 <sup>5</sup>		133 <sup>3</sup>	ms
9	D	Blank Check Time Flash per block	t <sub>check</sub>	11 <sup>6</sup>		32778 <sup>7</sup>	t <sub>cyc</sub>
10	D	Blank Check Time EEPROM per block	t <sub>check</sub>	11 <sup>6</sup>		1034 <sup>7</sup>	t <sub>cyc</sub>

#### NOTES:

- 1. Restrictions for oscillator in crystal mode apply!
- 2. Minimum Programming times are achieved under maximum NVM operating frequency f<sub>NVMOP</sub> and maximum bus frequency f<sub>bus</sub>.
- 3. Maximum Erase and Programming times are achieved under particular combinations of f<sub>NVMOP</sub> and bus frequency f<sub>bus</sub>. Refer to formulae in Sections **A.3.1.1 A.3.1.4** for guidance.
- 4. Row Programming operations are not applicable to EEPROM
- 5. Minimum Erase times are achieved under maximum NVM operating frequency f<sub>NVMOP</sub>.
- 6. Minimum time, if first word in the array is not blank
- 7. Maximum time to complete check on an erased block



## A.3.2 NVM Reliability

The reliability of the NVM blocks is guaranteed by stress test during qualification, constant process monitors and burn-in to screen early life failures.

The failure rates for data retention and program/erase cycling are specified at the operating conditions noted.

The program/erase cycle count on the sector is incremented every time a sector or mass erase event is executed.

Table A-12 NVM Reliability Characteristics

Condit	ions	s are shown in Table A-4 unless otherwise noted					
Num	С	Rating	Symbol	Min	Тур	Max	Unit
1	С	Data Retention at an average junction temperature of $T_{Javg} = 70^{\circ}C$	t <sub>NVMRET</sub>	15			Years
2	С	Flash number of Program/Erase cycles	n <sub>FLPE</sub>	10,000			Cycles
3	С	EEPROM number of Program/Erase cycles (–40°C $\leq$ T <sub>J</sub> $\leq$ 0°C)	n <sub>EEPE</sub>	10,000			Cycles
4	С	EEPROM number of Program/Erase cycles $(0^{\circ}\text{C} < \text{T}_{\text{J}} \le 140^{\circ}\text{C})$	n <sub>EEPE</sub>	100,000			Cycles

## A.4 Voltage Regulator

The on-chip voltage regulator is intended to supply the internal logic and oscillator circuits. No external DC load is allowed.

**Table A-13 Voltage Regulator Recommended Load Capacitances** 

Rating	Symbol	Min	Тур	Max	Unit
Load Capacitance on VDD1, 2	C <sub>LVDD</sub>		220		nF
Load Capacitance on VDDPLL	C <sub>LVDDfcPLL</sub>		220		nF

## A.5 Reset, Oscillator and PLL

This section summarizes the electrical characteristics of the various startup scenarios for Oscillator and Phase-Locked-Loop (PLL).

### A.5.1 Startup

**Table A-14** summarizes several startup characteristics explained in this section. Detailed description of the startup behavior can be found in the Clock and Reset Generator (CRG) Block User Guide.

**Table A-14 Startup Characteristics** 

Condit	ions	s are shown in Table A-4 unless otherwise noted					
Num	С	Rating	Symbol	Min	Тур	Max	Unit
1	Т	POR release level	V <sub>PORR</sub>			2.07	V
2	Т	POR assert level	V <sub>PORA</sub>	0.97			V
3	D	Reset input pulse width, minimum input time	PW <sub>RSTL</sub>	2			t <sub>osc</sub>
4	D	Startup from Reset	n <sub>RST</sub>	192		196	n <sub>osc</sub>
5	D	Interrupt pulse width, IRQ edge-sensitive mode	PW <sub>IRQ</sub>	20			ns
6	D	Wait recovery startup time	t <sub>WRS</sub>			14	t <sub>cyc</sub>

### A.5.1.1 POR

The release level  $V_{PORR}$  and the assert level  $V_{PORA}$  are derived from the  $V_{DD}$  Supply. They are also valid if the device is powered externally. After releasing the POR reset the oscillator and the clock quality check are started. If after a time  $t_{CQOUT}$  no valid oscillation is detected, the MCU will start using the internal self clock. The fastest startup time possible is given by  $n_{uposc}$ .

#### A.5.1.2 SRAM Data Retention

Provided an appropriate external reset signal is applied to the MCU, preventing the CPU from executing code when VDD5 is out of specification limits, the SRAM contents integrity is guaranteed if after the reset the PORF bit in the CRG Flags Register has not been set.

### A.5.1.3 External Reset

When external reset is asserted for a time greater than PW<sub>RSTL</sub> the CRG module generates an internal reset, and the CPU starts fetching the reset vector without doing a clock quality check, if there was an oscillation before reset.

### A.5.1.4 Stop Recovery

Out of STOP the controller can be woken up by an external interrupt. A clock quality check as after POR is performed before releasing the clocks to the system.

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### A.5.1.5 Pseudo Stop and Wait Recovery

The recovery from Pseudo STOP and Wait are essentially the same since the oscillator was not stopped in both modes. The controller can be woken up by internal or external interrupts. After t<sub>wrs</sub> the CPU starts fetching the interrupt vector.

### A.5.2 Oscillator

The device features an internal Colpitts and Pierce oscillator. The selection of Colpitts oscillator or Pierce oscillator/external clock depends on the XCLKS signal which is sampled during reset. By asserting the  $\overline{\text{XCLKS}}$  input during reset this oscillator can be bypassed allowing the input of a square wave. Before asserting the oscillator to the internal system clocks the quality of the oscillation is checked for each start from either power-on, STOP or oscillator fail.  $t_{CQOUT}$  specifies the maximum time before switching to the internal self clock mode after POR or STOP if a proper oscillation is not detected. The quality check also determines the minimum oscillator start-up time  $t_{UPOSC}$ . The device also features a clock monitor. A Clock Monitor Failure is asserted if the frequency of the incoming clock signal is below the Assert Frequency  $f_{CMFA}$ .

Table A-15 Oscillator Characteristics

Condit	ions	s are shown in <b>Table A-4</b> unless otherwise noted					
Num	С	Rating	Symbol	Min	Тур	Max	Unit
1a	С	Crystal oscillator range (Colpitts)	fosc	0.5		16	MHz
1b	С	Crystal oscillator range (Pierce) <sup>1</sup>	fosc	0.5		40	MHz
2	Р	Startup Current	iosc	100			μА
3	С	Oscillator start-up time (Colpitts)	t <sub>UPOSC</sub>		8 <sup>2</sup>	100 <sup>3</sup>	ms
4	D	Clock Quality check time-out	t <sub>CQOUT</sub>	0.45		2.5	S
5	Р	Clock Monitor Failure Assert Frequency	f <sub>CMFA</sub>	50	100	200	KHz
6	Р	External square wave input frequency <sup>4</sup>	f <sub>EXT</sub>	0.5		50	MHz
7	D	External square wave pulse width low	t <sub>EXTL</sub>	9.5			ns
8	D	External square wave pulse width high	t <sub>EXTH</sub>	9.5			ns
9	D	External square wave rise time	t <sub>EXTR</sub>			1	ns
10	D	External square wave fall time	t <sub>EXTF</sub>			1	ns
11	D	Input Capacitance (EXTAL, XTAL pins)	C <sub>IN</sub>		7		pF
12	С	DC Operating Bias in Colpitts Configuration on EXTAL Pin	V <sub>DCBIAS</sub>		1.1		V

#### NOTES:

- 1. Depending on the crystal a damping series resistor might be necessary
- 2.  $f_{osc} = 4MHz$ , C = 22pF.
- 3. Maximum value is for extreme cases using high Q, low frequency crystals
- 4. XCLKS =0 during reset



### A.5.3 Phase Locked Loop

The oscillator provides the reference clock for the PLL. The PLL's Voltage Controlled Oscillator (VCO) is also the system clock source in self clock mode.

### A.5.3.1 XFC Component Selection

This section describes the selection of the XFC components to achieve a good filter characteristics.

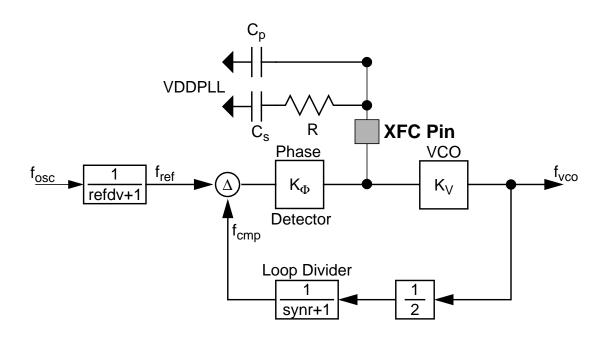


Figure A-2 Basic PLL functional diagram

The following procedure can be used to calculate the resistance and capacitance values using typical values for  $K_1$ ,  $f_1$  and  $i_{ch}$  from **Table A-16**.

The grey boxes show the calculation for  $f_{VCO} = 50 MHz$  and  $f_{ref} = 1 MHz$ . E.g., these frequencies are used for  $f_{OSC} = 4 MHz$  and a 25MHz bus clock.

The VCO Gain at the desired VCO frequency is approximated by:

$$K_V = K_1 \cdot e^{\frac{(f_1 - f_{vco})}{K_1 \cdot 1V}} -100 \cdot e^{\frac{(60 - 50)}{-100}} = -90.48MHz/V$$

The phase detector relationship is given by:

$$K_{\Phi} = -|i_{ch}| \cdot K_{V}$$
 = 316.7Hz/ $\Omega$ 

i<sub>ch</sub> is the current in tracking mode.

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The loop bandwidth  $f_C$  should be chosen to fulfill the Gardner's stability criteria by <u>at least</u> a factor of 10, typical values are 50.  $\zeta = 0.9$  ensures a good transient response.

$$f_{C} < \frac{2 \cdot \zeta \cdot f_{ref}}{\pi \cdot \left(\zeta + \sqrt{1 + \zeta^{2}}\right)} \frac{1}{10} \rightarrow f_{C} < \frac{f_{ref}}{4 \cdot 10}; (\zeta = 0.9)$$

$$f_{C} < 25kHz$$

And finally the frequency relationship is defined as

$$n = \frac{f_{VCO}}{f_{ref}} = 2 \cdot (synr + 1) = 50$$

With the above values the resistance can be calculated. The example is shown for a loop bandwidth  $f_C=10KHz$ :

$$R = \frac{2 \cdot \pi \cdot n \cdot f_C}{K_{\Phi}} = 2^* \pi^* 50^* 10 \text{kHz} / (316.7 \text{Hz}/\Omega) = 9.9 \text{k}\Omega = \sim 10 \text{k}\Omega$$

The capacitance  $C_s$  can now be calculated as:

$$C_s = \frac{2 \cdot \zeta^2}{\pi \cdot f_C \cdot R} \approx \frac{0.516}{f_C \cdot R}; (\zeta = 0.9)$$
 = 5.19nF =~ 4.7nF

The capacitance C<sub>p</sub> should be chosen in the range of:

$$C_{s}/20 \le C_{p} \le C_{s}/10$$
  $C_{p} = 470pF$ 

#### A.5.3.2 Jitter Information

The basic functionality of the PLL is shown in **Figure A-2**. With each transition of the clock  $f_{cmp}$ , the deviation from the reference clock  $f_{ref}$  is measured and input voltage to the VCO is adjusted accordingly. The adjustment is done continuously with no abrupt changes in the clock output frequency. Noise, voltage, temperature and other factors cause slight variations in the control loop resulting in a clock jitter. This jitter affects the real minimum and maximum clock periods as illustrated in **Figure A-3**.

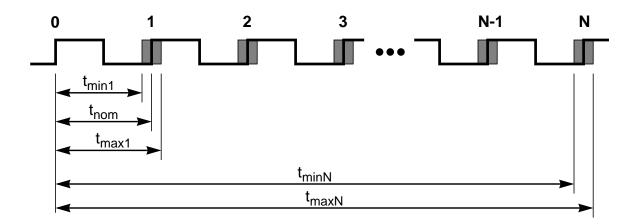


Figure A-3 Jitter Definitions

The relative deviation of  $t_{nom}$  is at its maximum for one clock period, and decreases towards zero for larger number of clock periods (N).

Defining the jitter as:

$$J(N) = \max \left( \left| 1 - \frac{t_{max}(N)}{N \cdot t_{nom}} \right|, \left| 1 - \frac{t_{min}(N)}{N \cdot t_{nom}} \right| \right)$$

For N < 100, the following equation is a good fit for the maximum jitter:

$$J(N) = \frac{j_1}{\sqrt{N}} + j_2$$

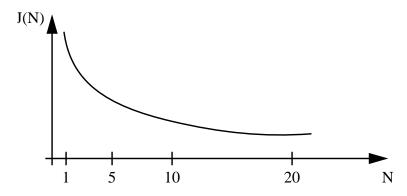


Figure A-4 Maximum bus clock jitter approximation

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This is very important to notice with respect to timers, serial modules where a pre-scaler will eliminate the effect of the jitter to a large extent.

**Table A-16 PLL Characteristics** 

Condit	ions	s are shown in <b>Table A-4</b> unless otherwise noted					
Num	С	Rating	Symbol	Min	Тур	Max	Unit
1	Р	Self Clock Mode frequency	f <sub>SCM</sub>	1		5.5	MHz
2	D	VCO locking range	f <sub>VCO</sub>	8		50	MHz
3	D	Lock Detector transition from Acquisition to Tracking mode	Δ <sub>trk</sub>	3		4	% <sup>1</sup>
4	D	Lock Detection	Δ <sub>Lock</sub>	0		1.5	% <sup>(1)</sup>
5	D	Un-Lock Detection	$ \Delta_{unl} $	0.5		2.5	% <sup>(1)</sup>
6	D	Lock Detector transition from Tracking to Acquisition mode	Δ <sub>unt</sub>	6		8	%(1)
7	С	PLLON Total Stabilization delay (Auto Mode) <sup>2</sup>	t <sub>stab</sub>		0.5		ms
8	D	PLLON Acquisition mode stabilization delay (2)	t <sub>acq</sub>		0.3		ms
9	D	PLLON Tracking mode stabilization delay (2)	t <sub>al</sub>		0.2		ms
10	D	Fitting parameter VCO loop gain	K <sub>1</sub>		-100		MHz/V
11	D	Fitting parameter VCO loop frequency	f <sub>1</sub>		60		MHz
12	D	Charge pump current acquisition mode	i <sub>ch</sub>		38.5		μА
13	D	Charge pump current tracking mode	i <sub>ch</sub>		3.5		μА
14	С	Jitter fit parameter 1 <sup>(2)</sup>	j <sub>1</sub>			1.1	%
15	С	Jitter fit parameter 2 <sup>(2)</sup>	j <sub>2</sub>			0.13	%

#### NOTES:

- 1. % deviation from target frequency
- 2.  $f_{OSC}$  = 4MHz,  $f_{BUS}$  = 25MHz equivalent  $f_{VCO}$  = 50MHz: REFDV = #\$03, SYNR = #\$018, Cs = 4.7nF, Cp = 470pF, Rs = 10K $\Omega$ .

## A.6 MSCAN

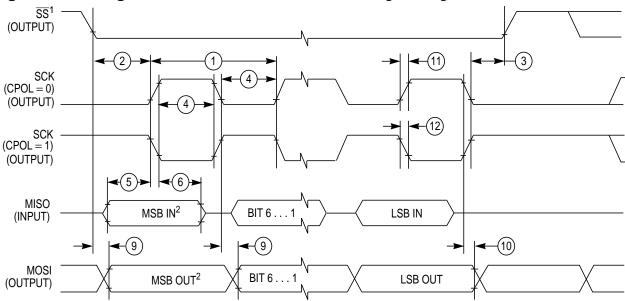
### **Table A-17 MSCAN Wake-up Pulse Characteristics**

Condit	Conditions are shown in <b>Table A-4</b> unless otherwise noted									
Num	С	Rating	Symbol	Min	Тур	Max	Unit			
1	Р	MSCAN Wake-up dominant pulse filtered	t <sub>WUP</sub>			2	μs			
2	Р	MSCAN Wake-up dominant pulse pass	t <sub>WUP</sub>	5			μs			

### A.7 SPI

### A.7.1 Master Mode

Figure A-5 and Figure A-6 illustrate the master mode timing. Timing values are shown in Table A-18.

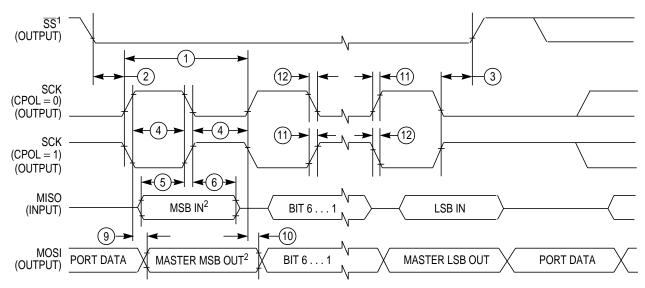


<sup>1.</sup>if configured as an output.

Figure A-5 SPI Master Timing (CPHA = 0)

<sup>2.</sup> LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

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- 1.If configured as output
- 2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

Figure A-6 SPI Master Timing (CPHA =1)

## Table A-18 SPI Master Mode Timing Characteristics<sup>1</sup>

Condit	ions	s are shown in <b>Table A-4</b> unless otherwise noted, $C_{LO}$	<sub>AD</sub> = 200pF o	n all outputs			
Num	С	Rating	Symbol	Min	Тур	Max	Unit
1	Р	Operating Frequency	f <sub>op</sub>	DC		1/2	f <sub>bus</sub>
1	Р	SCK Period t <sub>SCk</sub> = 1./f <sub>op</sub>	t <sub>sck</sub>	4		2048	t <sub>bus</sub>
2	D	Enable Lead Time	t <sub>lead</sub>	1/2		_	t <sub>sck</sub>
3	D	Enable Lag Time	t <sub>lag</sub>	1/2			t <sub>sck</sub>
4	D	Clock (SCK) High or Low Time	t <sub>wsck</sub>	t <sub>bus</sub> – 30		1024 t <sub>bus</sub>	ns
5	D	Data Setup Time (Inputs)	t <sub>su</sub>	25			ns
6	D	Data Hold Time (Inputs)	t <sub>hi</sub>	0			ns
9	D	Data Valid (after SCK Edge)	t <sub>v</sub>			25	ns
10	D	Data Hold Time (Outputs)	t <sub>ho</sub>	0			ns
11	D	Rise Time Inputs and Outputs	t <sub>r</sub>			25	ns
12	D	Fall Time Inputs and Outputs	t <sub>f</sub>			25	ns

### NOTES:

1. The numbers 7, 8 in the column labeled "Num" are missing. This has been done on purpose to be consistent between the Master and the Slave timing shown in **Table A-19**.

### A.7.2 Slave Mode

Figure A-7 and Figure A-8 illustrate the slave mode timing. Timing values are shown in Table A-19.

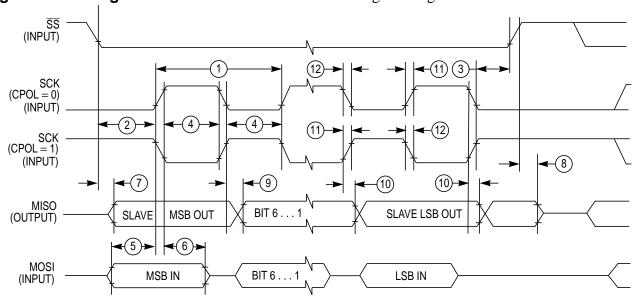


Figure A-7 SPI Slave Timing (CPHA = 0)

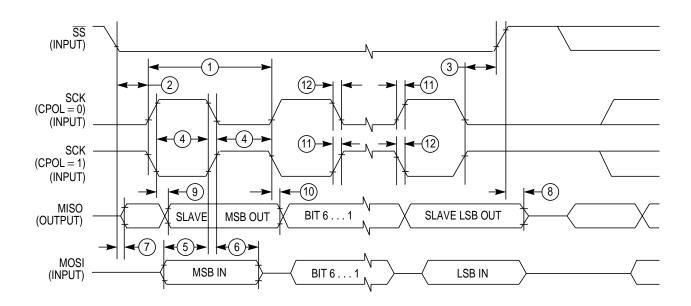


Figure A-8 SPI Slave Timing (CPHA =1)

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Table A-19 SPI Slave Mode Timing Characteristics

Condit	ions	s are shown in Table A-4 unless otherwise noted, CLO	AD = 200pF	on all outputs			
Num	С	Rating	Symbol	Min	Тур	Max	Unit
1	Р	Operating Frequency	f <sub>op</sub>	DC		1/4	f <sub>bus</sub>
1	Р	SCK Period t <sub>sck</sub> = 1./f <sub>op</sub>	t <sub>sck</sub>	4		2048	t <sub>bus</sub>
2	D	Enable Lead Time	t <sub>lead</sub>	1			t <sub>cyc</sub>
3	D	Enable Lag Time	t <sub>lag</sub>	1			t <sub>cyc</sub>
4	D	Clock (SCK) High or Low Time	t <sub>wsck</sub>	t <sub>cyc</sub> - 30			ns
5	D	Data Setup Time (Inputs)	t <sub>su</sub>	25			ns
6	D	Data Hold Time (Inputs)	t <sub>hi</sub>	25			ns
7	D	Slave Access Time	t <sub>a</sub>			1	t <sub>cyc</sub>
8	D	Slave MISO Disable Time	t <sub>dis</sub>			1	t <sub>cyc</sub>
9	D	Data Valid (after SCK Edge)	t <sub>v</sub>			25	ns
10	D	Data Hold Time (Outputs)	t <sub>ho</sub>	0			ns
11	D	Rise Time Inputs and Outputs	t <sub>r</sub>			25	ns
12	D	Fall Time Inputs and Outputs	t <sub>f</sub>			25	ns

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## A.8 External Bus Timing

A timing diagram of the external multiplexed-bus is illustrated in **Figure A-9** with the actual timing values shown on table **Table A-20**. All major bus signals are included in the diagram. While both a data write and data read cycle are shown, only one or the other would occur on a particular bus cycle.

### A.8.1 General Multiplexed Bus Timing

The expanded bus timings are highly dependent on the load conditions. The timing parameters shown assume a balanced load across all outputs.

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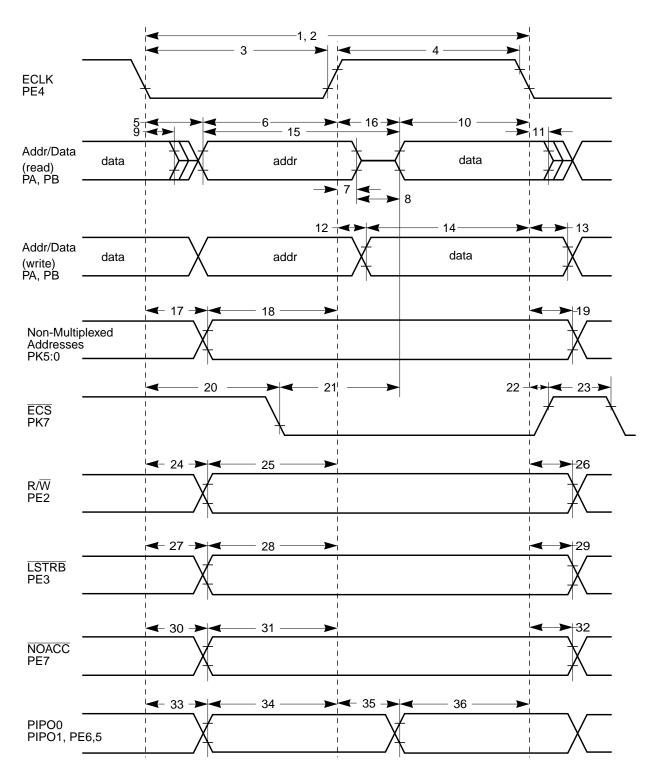


Figure A-9 General External Bus Timing

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## **Table A-20 Expanded Bus Timing Characteristics**

Num	С	Rating	Symbol	Min	Тур	Max	Unit
1	Р	Frequency of operation (E-clock)	f <sub>o</sub>	0		25.0	MHz
2	Р	Cycle time	t <sub>cyc</sub>	40			ns
3	D	Pulse width, E low	PW <sub>EL</sub>	19			ns
4	D	Pulse width, E high <sup>1</sup>	PW <sub>EH</sub>	19			ns
5	D	Address delay time	t <sub>AD</sub>			8	ns
6	D	Address valid time to E rise (PW <sub>EL</sub> -t <sub>AD</sub> )	t <sub>AV</sub>	11			ns
7	D	Muxed address hold time	t <sub>MAH</sub>	2			ns
8	D	Address hold to data valid	t <sub>AHDS</sub>	7			ns
9	D	Data hold to address	t <sub>DHA</sub>	2			ns
10	D	Read data setup time	t <sub>DSR</sub>	13			ns
11	D	Read data hold time	t <sub>DHR</sub>	0			ns
12	D	Write data delay time	t <sub>DDW</sub>			7	ns
13	D	Write data hold time	t <sub>DHW</sub>	2			ns
14	D	Write data setup time <sup>(1)</sup> (PW <sub>EH</sub> -t <sub>DDW</sub> )	t <sub>DSW</sub>	12			ns
15	D	Address access time <sup>(1)</sup> (t <sub>cyc</sub> -t <sub>AD</sub> -t <sub>DSR</sub> )	t <sub>ACCA</sub>	19			ns
16	D	E high access time <sup>(1)</sup> (PW <sub>EH</sub> -t <sub>DSR</sub> )	t <sub>ACCE</sub>	6			ns
17	D	Non-multiplexed address delay time	t <sub>NAD</sub>			6	ns
18	D	Non-muxed address valid to E rise (PW <sub>EL</sub> -t <sub>NAD</sub> )	t <sub>NAV</sub>	15			ns
19	D	Non-multiplexed address hold time	t <sub>NAH</sub>	2			ns
20	D	Chip select delay time	t <sub>CSD</sub>			16	ns
21	D	Chip select access time <sup>(1)</sup> (t <sub>cyc</sub> –t <sub>CSD</sub> –t <sub>DSR</sub> )	t <sub>ACCS</sub>	11			ns
22	D	Chip select hold time	t <sub>CSH</sub>	2			ns
23	D	Chip select negated time	t <sub>CSN</sub>	8			ns
24	D	Read/write delay time	t <sub>RWD</sub>			7	ns
25	D	Read/write valid time to E rise (PW <sub>EL</sub> -t <sub>RWD</sub> )	t <sub>RWV</sub>	14			ns
26	D	Read/write hold time	t <sub>RWH</sub>	2			ns
27	D	Low strobe delay time	t <sub>LSD</sub>			7	ns
28	D	Low strobe valid time to E rise (PW <sub>EL</sub> -t <sub>LSD</sub> )	t <sub>LSV</sub>	14			ns
29	D	Low strobe hold time	t <sub>LSH</sub>	2			ns
30	D	NOACC strobe delay time	t <sub>NOD</sub>			7	ns
31	D	NOACC valid time to E rise (PW <sub>EL</sub> -t <sub>NOD</sub> )	t <sub>NOV</sub>	14			ns

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## **Table A-20 Expanded Bus Timing Characteristics**

Condit	Conditions are shown in <b>Table A-4</b> unless otherwise noted, C <sub>LOAD</sub> = 50pF											
Num	С	Rating	Symbol	Min	Тур	Max	Unit					
32	D	NOACC hold time	t <sub>NOH</sub>	2			ns					
33	D	IPIPO[1:0] delay time	t <sub>P0D</sub>	2		7	ns					
34	D	IPIPO[1:0] valid time to E rise (PW <sub>EL</sub> -t <sub>P0D</sub> )	t <sub>P0V</sub>	11			ns					
35	D	IPIPO[1:0] delay time <sup>(1)</sup> (PW <sub>EH</sub> -t <sub>P1V</sub> )	t <sub>P1D</sub>	2		25	ns					
36	D	IPIPO[1:0] valid time to E fall	t <sub>P1V</sub>	11			ns					

#### NOTES:

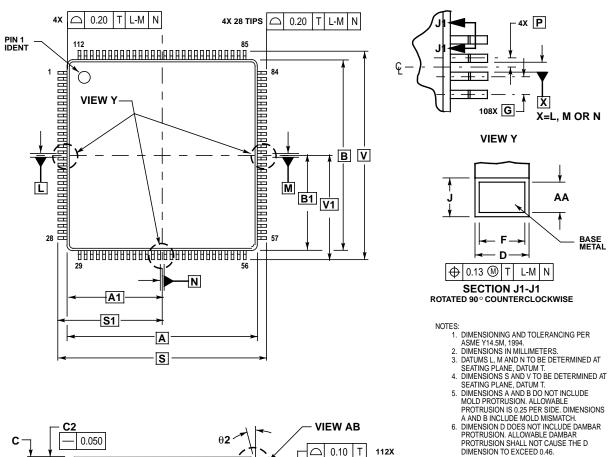
<sup>1.</sup> Affected by clock stretch: add N x  $t_{cyc}$  where N=0,1,2 or 3, depending on the number of clock stretches.

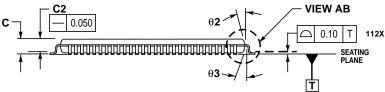
## **Appendix B Package Information**

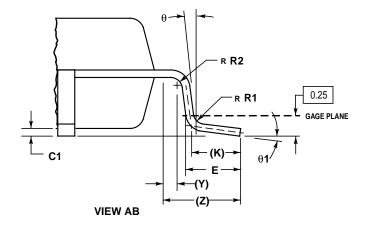
## **B.1** General

This section provides the physical dimensions of the MC9S12DT128 packages.

## B.2 112-pin LQFP package







MILLIMETERS DIM MIN MAX A1 10.000 BSC В 20.000 BSC 10.000 BSC 1.600 C1 C2 0.050 0.150 1.350 1.450 D 0.270 0.370 0.450 0.750 0.270 0.330 G 0.650 BSC 0.090 0.170 0.500 REF 0.325 BSC R1 0.100 0.200 R2 0.100 0.200 S S1 22,000 BSC 11.000 BSC V1 11 000 BSC 0.250 REF 1.000 REF θ1

AA

BASE METAL

Figure 23-6 112-pin LQFP mechanical dimensions (case no. 987)

## B.3 80-pin QFP package

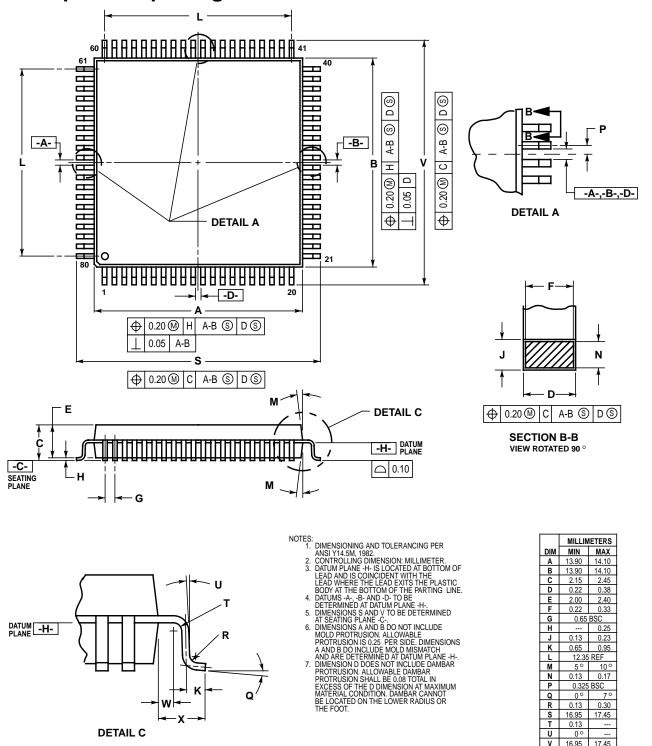


Figure 1 80-pin QFP Mechanical Dimensions (case no. 841B)

0.35 0.45

## **User Guide End Sheet**

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